

MSP430FR2422 混合信号微控制器

1 器件概述

1.1 特性

- 嵌入式微控制器
 - 16 位 RISC 架构
 - 支持的时钟频率最高可达 16MHz
 - 3.6V 至 1.8V 的宽电源电压范围（最低电源电压受限于 SVS 电平，请参阅 [SVS 规格](#)）
- 优化的超低功耗模式
 - 激活模式：120 μ A/MHz（典型值）
 - 待机模式：LPM3.5，采用 32768Hz 晶振的实时时钟 (RTC) 计数器：710nA（典型值）
 - 关断模式 (LPM4.5)：36nA，无 SVS
- 低功耗铁电 RAM (FRAM)
 - 非易失性存储器容量高达 7.5KB
 - 内置错误修正码 (ECC)
 - 可配置的写保护
 - 对程序、常量和存储的统一存储
 - 耐写次数达 10^{15} 次
 - 抗辐射和非磁性
 - FRAM 与 SRAM 之比高达 4: 1
- 高性能模拟
 - 高达 8 通道 10 位模数转换器 (ADC)
 - 1.5V 的内部基准电压
 - 采样与保持 200kps
- 智能数字外设
 - 两个 16 位计时器，每个计时器有三个捕捉/比较寄存器 (Timer_A3)
 - 一个仅用作计数器的 16 位 RTC
 - 16 位循环冗余校验 (CRC)
- 增强型串行通信，支持引脚重映射功能（请参阅 [器件比较](#)）
 - 一个 eUSCI_A 接口，支持 UART、IrDA 和 SPI
 - 一个 eUSCI_B 接口，支持 SPI 和 I²C
- 时钟系统 (CS)
 - 片上 32kHz RC 振荡器 (REFO)
 - 带有锁频环 (FLL) 的片上 16MHz 数控振荡器 (DCO)
 - 室温下的精度为 $\pm 1\%$ （具有片上基准）
 - 片上超低频 10kHz 振荡器 (VLO)
 - 片上高频调制振荡器 (MODOSC)
 - 外部 32kHz 晶振 (LFXT)
 - 可编程 MCLK 预分频器（1 至 128）
 - 通过可编程预分频器（1、2、4 或 8）从 MCLK 获得的 SMCLK
- 通用输入/输出和引脚功能
 - 共计 15 个 I/O（采用 VQFN-20 封装）
 - 15 个中断引脚（P1 和 P2）可以将 MCU 从低功耗模式下唤醒
- 开发工具和软件
 - 开发工具
 - 目标开发板 [MSP-TS430RHL20](#)
- 系列成员（另请参阅 [器件特性](#)）
 - MSP430FR2422：7.25KB 程序 FRAM、256B 信息 FRAM、2KB RAM
- 封装选项
 - 20 引脚：VQFN (RHL)
 - 16 引脚：TSSOP (PW)

1.2 应用

- 工业传感器
- 电池组
- 便携式电器
- 电动牙刷
- 低功耗医疗、健康和健身器材

1.3 说明

MSP430FR2422 是 MSP430™ 超值系列微控制器 (MCU) 产品组合的其中一个器件，该超值系列微控制器是 TI 成本最低的 MCU 系列，适用于检测和测量应用中的数字输入 D 类音频放大器。MSP430FR2422 MCU 可提供 8KB 非易失性存储器并配备 8 通道 10 位 ADC。该架构、FRAM 和集成外设与多种低功耗模式相结合，针对在便携式和电池供电传感应用中实现延长电池寿命进行了优化应用中的数字输入 D 类音频放大器。采用 16 引脚 TSSOP 或 20 引脚 VQFN 封装。

TI 的 MSP430 超低功耗 FRAM 微控制器平台将独特的嵌入式 FRAM 和全面的超低功耗系统架构相结合，从而使系统设计人员能够在降低能耗的同时提升性能。FRAM 技术兼有 RAM 的低功耗快速写入、灵活性、耐用性和闪存非易失性等特性。



MSP430FR2422 MCU 由广泛的硬件和软件生态系统进行支持，提供参考设计和代码示例，协助用户快速开展设计。开发套件包括 [MSP-TS430RHL20](#) 20 引脚目标开发板。TI 还提供免费的 [MSP430Ware™](#) 软件，该软件以 [Code Composer Studio™](#) IDE 台式机和云版本组件的形式提供（[位于 TI Resource Explorer](#)）。[E2E™ 支持论坛](#) 还为 MSP430 MCU 提供广泛的在线配套资料、培训和在线支持。

有关完整的模块说明，请参阅 [《MSP430FR4xx 和 MSP430FR2xx 系列器件用户指南》](#)。

器件信息⁽¹⁾

器件型号	封装	封装尺寸 ⁽²⁾
MSP430FR2422IPW16	TSSOP (16)	5mm x 4.4mm
MSP430FR2422IRHL	VQFN (20)	4.5mm x 3.5mm

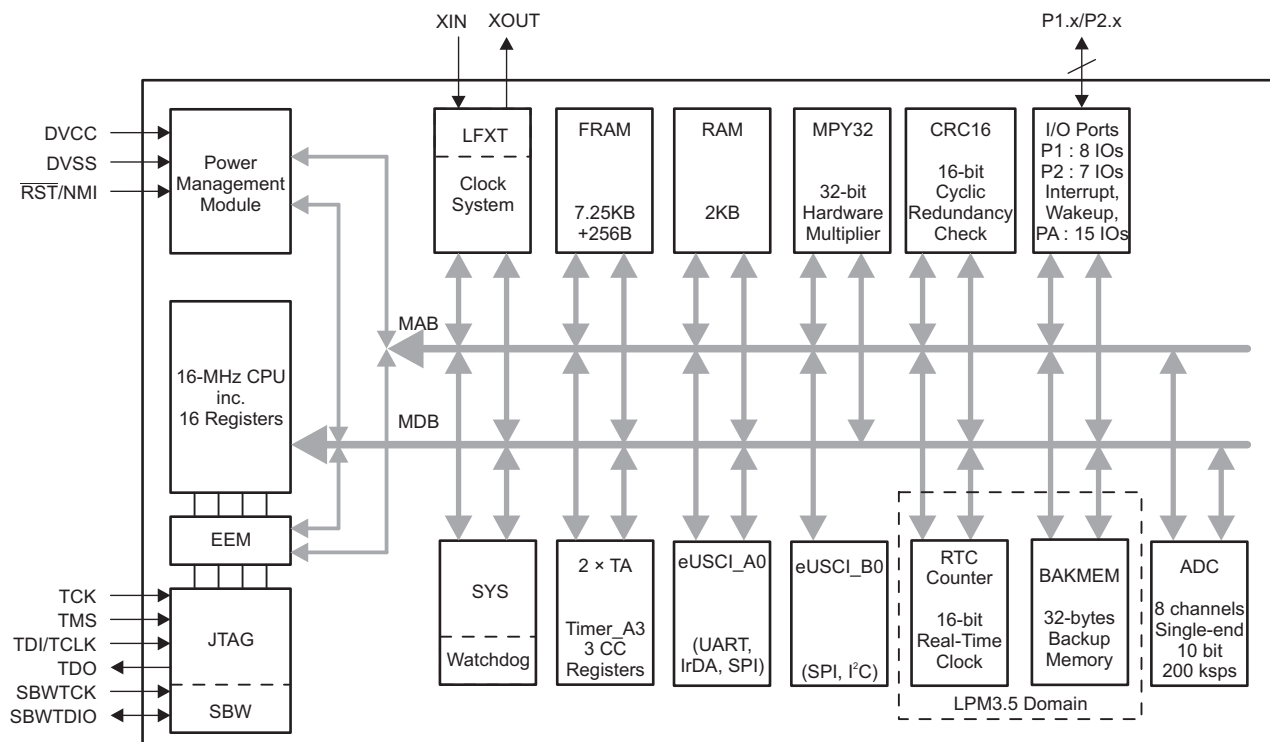
- (1) 要获得最新的产品、封装和订购信息，请参见封装选项附录（[节 9](#)），或者访问德州仪器 (TI) 网站 www.ti.com.cn。
- (2) 这里显示的尺寸为近似值。要获得包含误差值的封装尺寸，请参见机械数据（[节 9](#)中）。

CAUTION

系统级静电放电 (ESD) 保护必须符合器件级 ESD 规范，以防发生电气过载或对数据或代码存储器造成干扰。有关更多信息，请参阅 [《MSP430 系统级 ESD 注意事项》](#)。

1.4 功能方框图

图 1-1 给出了功能框图。



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图 1-1. 功能框图

- MCU 的主电源对 DVCC 和 DVSS 分别为数字模块和模拟模块供电。推荐的旁路电容和去耦电容分别为 4.7μF 至 10μF 和 0.1μF，精度为 ±5%。
- P1 和 P2 特有引脚中断功能，可将 MCU 从所有 LPM 唤醒（包括 LPM3.5 和 LPM4）。
- 每个 Timer_A3 具有 3 个捕捉/比较寄存器，不过仅 CCR1 和 CCR2 从外部连接。CCR0 寄存器仅用于内部周期时序和生成中断。
- 在 LPM3.5 模式下，RTC 模块可在其他外设停止工作的情况下继续工作。

内容

1	器件概述	1	6	Detailed Description	38
1.1	特性	1	6.1	Overview	38
1.2	应用	1	6.2	CPU	38
1.3	说明	1	6.3	Operating Modes	38
1.4	功能方框图	3	6.4	Interrupt Vector Addresses	39
2	修订历史记录	5	6.5	Bootloader (BSL)	41
3	Device Comparison	6	6.6	JTAG Standard Interface	41
3.1	Related Products	6	6.7	Spy-Bi-Wire Interface (SBW)	42
4	Terminal Configuration and Functions	7	6.8	FRAM	42
4.1	Pin Diagrams	7	6.9	Memory Protection	42
4.2	Pin Attributes	8	6.10	Peripherals	42
4.3	Signal Descriptions	10	6.11	Input/Output Diagrams	51
4.4	Pin Multiplexing	12	6.12	Device Descriptors	55
4.5	Buffer Types	12	6.13	Memory	56
4.6	Connection of Unused Pins	12	6.14	Identification	64
5	Specifications	13	7	Applications, Implementation, and Layout	65
5.1	Absolute Maximum Ratings	13	7.1	Device Connection and Layout Fundamentals	65
5.2	ESD Ratings	13	7.2	Peripheral- and Interface-Specific Design Information	68
5.3	Recommended Operating Conditions	13	8	器件和文档支持	70
5.4	Active Mode Supply Current Into V_{CC} Excluding External Current	14	8.1	入门和后续步骤	70
5.5	Active Mode Supply Current Per MHz	14	8.2	器件命名规则	70
5.6	Low-Power Mode (LPM0) Supply Currents Into V_{CC} Excluding External Current	14	8.3	工具和软件	71
5.7	Low-Power Mode (LPM3, LPM4) Supply Currents (Into V_{CC}) Excluding External Current	15	8.4	文档支持	73
5.8	Low-Power Mode (LPMx.5) Supply Currents (Into V_{CC}) Excluding External Current	16	8.5	社区资源	74
5.9	Typical Characteristics - Low-Power Mode Supply Currents	17	8.6	商标	74
5.10	Thermal Resistance Characteristics	18	8.7	静电放电警告	75
5.11	Timing and Switching Characteristics	18	8.8	Export Control Notice	75
			8.9	Glossary	75
			9	机械、封装和可订购信息	76

2 修订历史记录

注：之前版本的页码可能与当前版本有所不同。

从修订版本 B 更改为修订版本 C

Changes from August 20, 2019 to December 10, 2019	Page
- Changed the note that begins "Supply voltage changes faster than 0.2 V/μs can trigger a BOR reset..." in Section 5.3, Recommended Operating Conditions 13 - Added the note that begins "TI recommends that power to the DVCC pin must not exceed the limits..." in Section 5.3, Recommended Operating Conditions 13 - Changed the note that begins "A capacitor tolerance of $\pm 20\%$ or better is required..." in Section 5.3, Recommended Operating Conditions 13 - Added the note "See MSP430 32-kHz Crystal Oscillators for details on crystal section, layout, and testing" to Table 5-4, XT1 Crystal Oscillator (Low Frequency) 20 - Changed the note that begins "Requires external capacitors at both terminals..." in Table 5-4, XT1 Crystal Oscillator (Low Frequency) 20 - Added the $t_{TA, cap}$ parameter in Table 5-13, Timer_A 26 - Corrected the test conditions for the R_1 parameter in Table 5-20, ADC, Power Supply and Input Range Conditions. 33 - Added the note that begins "$t_{sample} = \ln(2^{n+1}) \times \tau$..." in Table 5-21, ADC, 10-Bit Timing Parameters 33 - Changed the CRC covered end address to 0x1AF5 in note (1) in Table 6-18, Device Descriptors 55 - Added "1.5-V reference factor" in Table 6-18, Device Descriptors 56	

从修订版本 A 更改为修订版本 B

Changes from November 8, 2018 to August 19, 2019	Page
- 更新了 节 1.1 特性..... 1 - Added the $t_{TA, cap}$ parameter in Table 5-13, Timer_A 26 - 更新了 节 8.2, 器件命名规则..... 70	

从初始发行版更改为修订版本 A

Changes from January 12, 2018 to November 7, 2018	Page
- 更改了 节 1.1, 特性 中的列表项"3.6V 至 1.8V 的宽电源电压范围..." 1 - Updated Section 3.1, Related Products 6 - Changed HBM limit to ± 1000 V and CDM limit to ± 250 V in Section 5.2, ESD Ratings 13 - Changed the MIN value of the V_{CC} parameter from 2 V to 1.8 V in Section 5.3, Recommended Operating Conditions 13 - Changed the crystal in the footnote that begins "Characterized with a Seiko Crystal SC-32S crystal..." in Section 5.7, Low-Power Mode (LPM3, LPM4) Supply Currents (Into V_{CC}) Excluding External Current 15 - Changed the crystal in the footnote that begins "Characterized with a Seiko Crystal SC-32S crystal..." in Section 5.8, Low-Power Mode (LPMx.5) Supply Currents (Into V_{CC}) Excluding External Current 16 - Added note on V_{SVSH-} and V_{SVSH+} parameters to Table 5-2, PMM, SVS and BOR 18 - Changed the minimum V_{CC} from 2.0 V to 1.8 V in the test conditions for the f_{REF0}, df_{REF0}/dV_{CC}, and f_{DC} parameters and in note (2) in Table 5-7, REFO 22 - Changed the minimum V_{CC} from 2.0 V to 1.8 V in the test conditions for the df_{VLO}/dV_{CC} parameter and in note (2) in Table 5-8, Internal Very-Low-Power Low-Frequency Oscillator (VLO) 23 - Changed the minimum V_{CC} from 2.0 V to 1.8 V in the test conditions for the f_{MODOSC}/dV_{CC} parameter in Table 5-9, Module Oscillator (MODOSC) 23 - Added the $t_{TA, cap}$ parameter in Table 5-13, Timer_A 26 - Corrected bitfield from RTCCLK to RTCCKSEL in table note that starts "Controlled by ..." in Table 6-8, Clock Distribution 43 - Corrected bitfield from IRDSEL to IRDSSEL in Section 6.10.8, Timers (Timer0_A3, Timer1_A3), in the description that starts "The interconnection of Timer0_A3 and ..." 48 - Corrected ADCINCHx column heading in Table 6-13, ADC Channel Connections 49	

• Corrected ADCINCHx column heading in Table 6-13, ADC Channel Connections	50
• Added P1SELC information in Table 6-28, Port P1, P2 Registers (Base Address: 0200h)	59
• Added P2SELC information in Table 6-28, Port P1, P2 Registers (Base Address: 0200h)	59

3 Device Comparison

Table 3-1 summarizes the features of the available family members.

Table 3-1. Device Comparison⁽¹⁾⁽²⁾

DEVICE	PROGRAM FRAM + INFORMATION FRAM (bytes)	SRAM (bytes)	TA0,TA1	eUSCI_A	eUSCI_B	10-BIT ADC CHANNELS	GPIOs	PACKAGE
MSP430FR2422IRHL	7424 + 256	2048	2, 3 × CCR ⁽³⁾	1	1	8	15	20 RHL (VQFN)
MSP430FR2422IPW16	7424 + 256	2048	2, 3 × CCR ⁽³⁾	1	1	5	11	16 PW (TSSOP)

- (1) For the most current package and ordering information, see the *Package Option Addendum* in [§ 9](#), or see the TI website at www.ti.com.
- (2) Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/packaging.
- (3) A CCR register is a configurable register that provides internal and external capture or compare inputs, or internal and external PWM outputs.

3.1 Related Products

For information about other devices in this family of products or related products, see the following links.

[TI 16-bit and 32-bit microcontrollers](#)

High-performance, low-power solutions to enable the autonomous future

[Products for MSP430 ultra-low-power sensing and measurement microcontrollers](#)

One platform. One ecosystem. Endless possibilities.

[Companion Products for MSP430FR2422](#)

Review products that are frequently purchased or used in conjunction with this product.

[Reference Designs](#)

Find reference designs leveraging the best in TI technology to solve your system-level challenges

4 Terminal Configuration and Functions

4.1 Pin Diagrams

Figure 4-1 shows the pinout of the 20-pin RHL package.

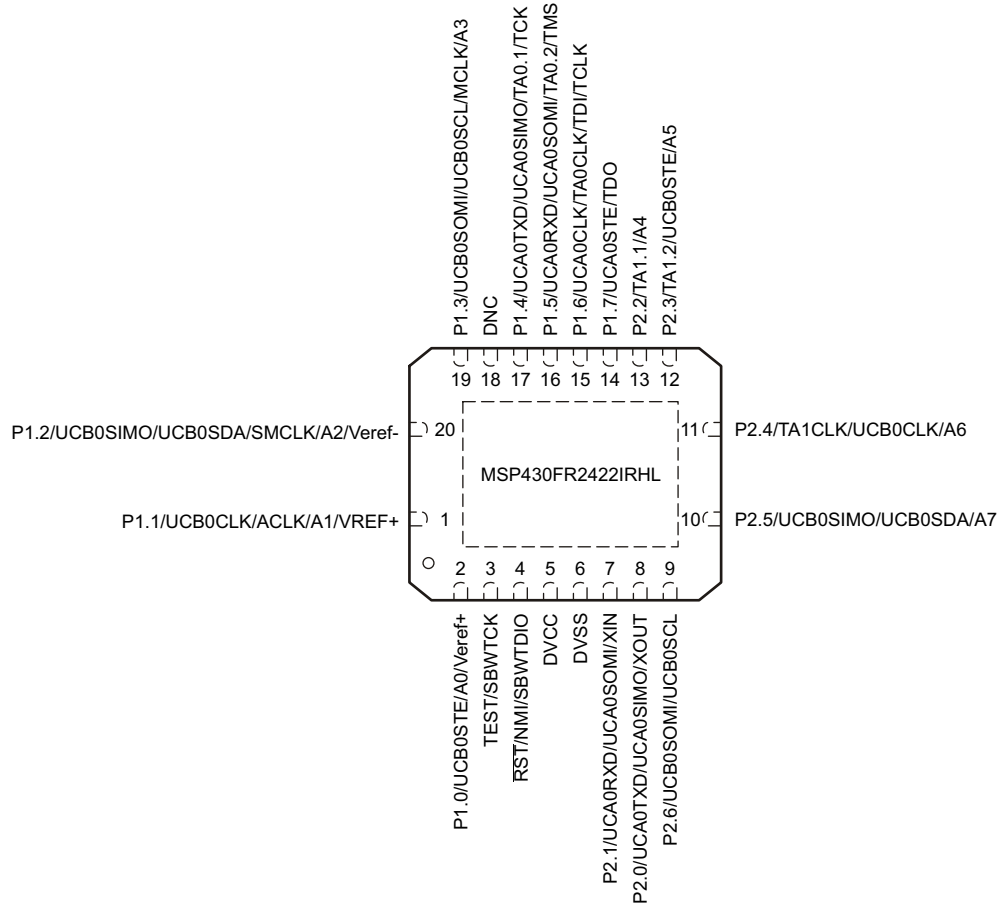


Figure 4-1. 20-Pin RHL Package (Top View)

Figure 4-2 shows the pinout of the 16-pin PW package.

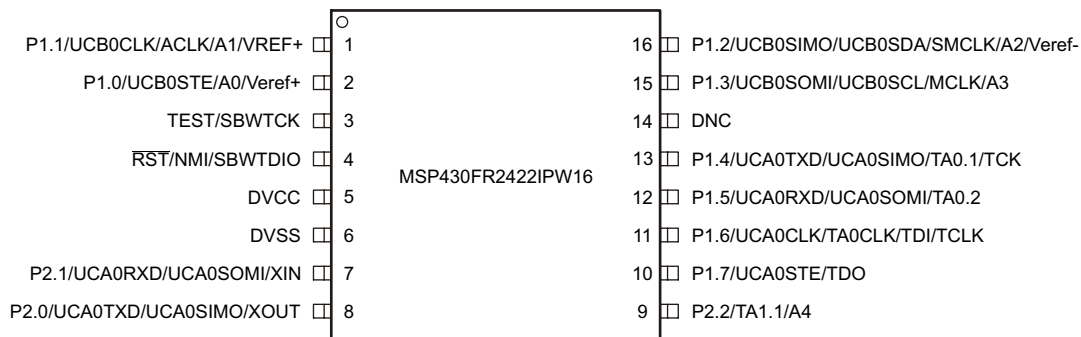


Figure 4-2. 16-Pin PW Package (Top View)

4.2 Pin Attributes

Table 4-1 lists the attributes of all pins.

Table 4-1. Pin Attributes

PIN NUMBER		SIGNAL NAME ^{(1) (2)}	SIGNAL TYPE ⁽³⁾	BUFFER TYPE ⁽⁴⁾	POWER SOURCE ⁽⁵⁾	RESET STATE AFTER BOR ⁽⁶⁾
RHL	PW16					
1	1	P1.1 (RD)	I/O	LVC MOS	DVCC	OFF
		UCB0CLK	I/O	LVC MOS	DVCC	–
		ACLK	I/O	LVC MOS	DVCC	–
		A1	I	Analog	DVCC	–
		VREF+	I	Analog	Power	–
2	2	P1.0 (RD)	I/O	LVC MOS	DVCC	OFF
		UCB0STE	I/O	LVC MOS	DVCC	–
		A0	I	Analog	DVCC	–
		Veref+	I	Analog	Power	–
3	3	TEST (RD)	I	LVC MOS	DVCC	OFF
		SBWTCK	I	LVC MOS	DVCC	–
4	4	$\overline{\text{RST}}$ (RD)	I	LVC MOS	DVCC	OFF
		NMI	I	LVC MOS	DVCC	–
		SBWTDIO	I/O	LVC MOS	DVCC	–
5	5	DVCC	P	Power	DVCC	N/A
6	6	DVSS	P	Power	DVCC	N/A
7	7	P2.1 (RD)	I/O	LVC MOS	DVCC	OFF
		UCA0RXD	I	LVC MOS	DVCC	–
		UCA0SOMI	I/O	LVC MOS	DVCC	–
		XIN	I	LVC MOS	DVCC	–
8	8	P2.0 (RD)	I/O	LVC MOS	DVCC	OFF
		UCA0TXD	O	LVC MOS	DVCC	–
		UCA0SIMO	I/O	LVC MOS	DVCC	–
		XOUT	O	LVC MOS	DVCC	–
9	–	P2.6 (RD)	I/O	LVC MOS	DVCC	OFF
		UCB0SOMI	I/O	LVC MOS	DVCC	–
		UCB0SCL	I/O	LVC MOS	DVCC	–
10	–	P2.5 (RD)	I/O	LVC MOS	DVCC	OFF
		UCB0SIMO	I/O	LVC MOS	DVCC	–
		UCB0SDA	I/O	LVC MOS	DVCC	–
		A7	I	Analog	DVCC	–
11	–	P2.4 (RD)	I/O	LVC MOS	DVCC	OFF
		TA1CLK	I	LVC MOS	DVCC	–
		UCB0CLK	I/O	LVC MOS	DVCC	–
		A6	I	Analog	DVCC	–

(1) Signals names with (RD) denote the reset default pin name.

(2) To determine the pin mux encodings for each pin, see [Section 6.11](#).

(3) Signal Types: I = Input, O = Output, I/O = Input or Output

(4) Buffer Types: LVC MOS, Analog, or Power (see [Table 4-3](#))

(5) The power source shown in this table is the I/O power source, which may differ from the module power source.

(6) Reset States:

OFF = High-impedance with Schmitt trigger and pullup or pulldown (if available) disabled

N/A = Not applicable

Table 4-1. Pin Attributes (continued)

PIN NUMBER		SIGNAL NAME ⁽¹⁾ (2)	SIGNAL TYPE ⁽³⁾	BUFFER TYPE ⁽⁴⁾	POWER SOURCE ⁽⁵⁾	RESET STATE AFTER BOR ⁽⁶⁾
RHL	PW16					
12	–	P2.3 (RD)	I/O	LVC MOS	DVCC	OFF
		TA1.2	I/O	LVC MOS	DVCC	–
		UCB0STE	I/O	LVC MOS	DVCC	–
		A5	I	Analog	DVCC	–
13	9	P2.2 (RD)	I/O	LVC MOS	DVCC	OFF
		TA1.1	I/O	LVC MOS	DVCC	–
		A4	I	Analog	DVCC	–
14	10	P1.7 (RD)	I/O	LVC MOS	DVCC	OFF
		UCA0STE	I/O	LVC MOS	DVCC	–
		TDO	O	LVC MOS	DVCC	–
15	11	P1.6 (RD)	I/O	LVC MOS	DVCC	OFF
		UCA0CLK	I/O	LVC MOS	DVCC	–
		TA0CLK	I	LVC MOS	DVCC	–
		TDI	I	LVC MOS	DVCC	–
		TCLK	I	LVC MOS	DVCC	–
16	12	P1.5 (RD)	I/O	LVC MOS	DVCC	OFF
		UCA0RXD	I	LVC MOS	DVCC	–
		UCA0SOMI	I/O	LVC MOS	DVCC	–
		TA0.1	I/O	LVC MOS	DVCC	–
		TMS	I	LVC MOS	DVCC	–
17	13	P1.4 (RD)	I/O	LVC MOS	DVCC	OFF
		UCA0TXD	O	LVC MOS	DVCC	–
		UCA0SIMO	I/O	LVC MOS	DVCC	–
		TA0.2	I/O	LVC MOS	DVCC	–
		TCK	I	LVC MOS	DVCC	–
18	14	DNC	–	–	–	–
19	15	P1.3 (RD)	I/O	LVC MOS	DVCC	OFF
		UCB0SOMI	I/O	LVC MOS	DVCC	–
		UCB0SCL	I/O	LVC MOS	DVCC	–
		MCLK	O	LVC MOS	DVCC	–
		A3	I	Analog	DVCC	–
20	16	P1.2 (RD)	I/O	LVC MOS	DVCC	OFF
		UCB0SIMO	I/O	LVC MOS	DVCC	–
		UCB0SDA	I/O	LVC MOS	DVCC	–
		SMCLK	O	LVC MOS	DVCC	–
		A2	I	Analog	DVCC	–
		Veref-	I	Analog	Power	–

4.3 Signal Descriptions

Table 4-2 describes the signals for all device variants and package options.

Table 4-2. Signal Descriptions

FUNCTION	SIGNAL NAME	PIN NUMBER		PIN TYPE ⁽¹⁾	DESCRIPTION
		RHL	PW		
ADC	A0	2	2	I	Analog input A0
	A1	1	1	I	Analog input A1
	A2	20	16	I	Analog input A2
	A3	19	15	I	Analog input A3
	A4	13	9	I	Analog input A4
	A5	12	–	I	Analog input A5
	A6	11	–	I	Analog input A6
	A7	10	–	I	Analog input A7
	Veref+	2	2	I	ADC positive reference
	Veref-	20	16	I	ADC negative reference
Clock	ACLK	1	1	I/O	ACLK output
	MCLK	19	15	O	MCLK output
	SMCLK	20	16	O	SMCLK output
	XIN	7	7	I	Input terminal for crystal oscillator
	XOUT	8	8	O	Output terminal for crystal oscillator
Debug	SBWTCK	3	3	I	Spy-Bi-Wire input clock
	SBWTDIO	4	4	I/O	Spy-Bi-Wire data input/output
	TCK	17	13	I	Test clock
	TCLK	15	11	I	Test clock input
	TDI	15	11	I	Test data input
	TDO	14	10	O	Test data output
	TEST	3	3	I	Test mode pin – selected digital I/O on JTAG pins
	TMS	16	12	I	Test mode select
GPIO	P1.0	2	2	I/O	General-purpose I/O
	P1.1	1	1	I/O	General-purpose I/O
	P1.2	20	16	I/O	General-purpose I/O
	P1.3	19	15	I/O	General-purpose I/O
	P1.4	17	13	I/O	General-purpose I/O ⁽²⁾
	P1.5	16	12	I/O	General-purpose I/O ⁽²⁾
	P1.6	15	11	I/O	General-purpose I/O ⁽²⁾
	P1.7	14	10	I/O	General-purpose I/O ⁽²⁾
	P2.0	8	8	I/O	General-purpose I/O
	P2.1	7	7	I/O	General-purpose I/O
	P2.2	13	9	I/O	General-purpose I/O
	P2.3	12	–	I/O	General-purpose I/O
	P2.4	11	–	I/O	General-purpose I/O
	P2.5	10	–	I/O	General-purpose I/O
	P2.6	9	–	I/O	General-purpose I/O

(1) Pin Types: I = Input, O = Output, I/O = Input or Output, P = Power

(2) Because this pin is multiplexed with the JTAG function, TI recommends disabling the pin interrupt function while in JTAG debug to prevent collisions.

Table 4-2. Signal Descriptions (continued)

FUNCTION	SIGNAL NAME	PIN NUMBER		PIN TYPE ⁽¹⁾	DESCRIPTION
		RHL	PW		
I ² C	UCB0SCL ⁽³⁾	19	15	I/O	eUSCI_B0 I ² C clock
	UCB0SDA ⁽³⁾	20	16	I/O	eUSCI_B0 I ² C data
	UCB0SCL ⁽³⁾	9	–	I/O	eUSCI_B0 I ² C clock
	UCB0SDA ⁽³⁾	10	–	I/O	eUSCI_B0 I ² C data
Power	DVCC	5	5	P	Power supply
	DVSS	6	6	P	Power ground
	VREF+	1	1	P	Output of positive reference voltage with ground as reference
SPI	UCA0STE	14	10	I/O	eUSCI_A0 SPI slave transmit enable
	UCA0CLK	15	11	I/O	eUSCI_A0 SPI clock input/output
	UCA0SOMI ⁽³⁾⁽⁴⁾	16	12	I/O	eUSCI_A0 SPI slave out/master in
	UCA0SIMO ⁽³⁾⁽⁴⁾	17	13	I/O	eUSCI_A0 SPI slave in/master out
	UCA0SOMI ⁽³⁾⁽⁴⁾	7	7	I/O	eUSCI_A0 SPI slave out/master in
	UCA0SIMO ⁽³⁾⁽⁴⁾	8	8	I/O	eUSCI_A0 SPI slave in/master out
	UCB0STE ⁽³⁾	2	2	I/O	eUSCI_B0 slave transmit enable
	UCB0CLK ⁽³⁾	1	1	I/O	eUSCI_B0 clock input/output
	UCB0SOMI ⁽³⁾	19	15	I/O	eUSCI_B0 SPI slave out/master in
	UCB0SIMO ⁽³⁾	20	16	I/O	eUSCI_B0 SPI slave in/master out
	UCB0STE ⁽³⁾	12	–	I/O	eUSCI_B0 slave transmit enable
	UCB0CLK ⁽³⁾	11	–	I/O	eUSCI_B0 clock input/output
	UCB0SOMI ⁽³⁾	9	–	I/O	eUSCI_B0 SPI slave out/master in
	UCB0SIMO ⁽³⁾	10	–	I/O	eUSCI_B0 SPI slave in/master out
System	NMI	4	4	I	Nonmaskable interrupt input
	RST	4	4	I	Active-low reset input
Timer_A	TA0.1	17	13	I/O	Timer TA0 CCR1 capture: CCI1A input, compare: Out1 outputs
	TA0.2	16	12	I/O	Timer TA0 CCR2 capture: CCI2A input, compare: Out2 outputs
	TA0CLK	15	11	I	Timer clock input TACLK for TA0
	TA1.1	13	9	I/O	Timer TA1 CCR1 capture: CCI1A input, compare: Out1 outputs
	TA1.2	12	–	I/O	Timer TA1 CCR2 capture: CCI2A input, compare: Out2 outputs
	TA1CLK	11	–	I	Timer clock input TACLK for TA1
UART	UCA0RXD ⁽³⁾	16	12	I	eUSCI_A0 UART receive data
	UCA0TXD ⁽³⁾	17	13	O	eUSCI_A0 UART transmit data
	UCA0RXD ⁽³⁾	7	7	I	eUSCI_A0 UART receive data
	UCA0TXD ⁽³⁾	8	8	O	eUSCI_A0 UART transmit data
DNC	Do not connect	18	14	–	Do not connect
QFN Pad	QFN thermal pad	Pad	–	–	QFN package exposed thermal pad. TI recommends connecting to V _{SS} .

- (3) These signal assignments are controlled by the USCIRMP bit of the SYSCFG3 register or the USCIBRMP bit of the SYSCFG2 register. Only one group can be selected at one time.
- (4) Signal assignments on these pins are controlled by the remap functionality and are selected by the USCIRMP bit in the SYSCFG3 register. Only one group can be selected at one time. The CLK and STE assignments are fixed and shared by both SPI function groups.

4.4 Pin Multiplexing

Pin multiplexing for this MCU is controlled by both register settings and operating modes (for example, if the MCU is in test mode). For details of the settings for each pin and diagrams of the multiplexed ports, see [Section 6.11](#).

4.5 Buffer Types

[Table 4-3](#) defines the pin buffer types that are listed in [Table 4-1](#)

Table 4-3. Buffer Types

BUFFER TYPE (STANDARD)	NOMINAL VOLTAGE	HYSTERESIS	PU OR PD	NOMINAL PU OR PD STRENGTH (μ A)	OUTPUT DRIVE STRENGTH (mA)	OTHER CHARACTERISTICS
LVC MOS	3.0 V	$\gamma^{(1)}$	Programmable	See Section 5.11.4	See Section 5.11.4	
Analog	3.0 V	N	N/A	N/A	N/A	See analog modules in Section 5 for details.
Power (DVCC)	3.0 V	N	N/A	N/A	N/A	SVS enables hysteresis on DVCC.
Power (AVCC)	3.0 V	N	N/A	N/A	N/A	

(1) Only for input pins.

4.6 Connection of Unused Pins

[Table 4-4](#) lists the correct termination of unused pins.

Table 4-4. Connection of Unused Pins⁽¹⁾

PIN	POTENTIAL	COMMENT
Px.0 to Px.7	Open	Switched to port function, output direction (PxDIR.n = 1)
$\overline{\text{RST}}/\text{NMI}$	DV _{CC}	47-k Ω pullup or internal pullup selected with 10-nF (or 1.1-nF) pulldown ⁽²⁾
TEST	Open	This pin always has an internal pull-down enabled.

- (1) Any unused pin with a secondary function that is shared with general-purpose I/O should follow the Px.0 to Px.7 unused pin connection guidelines.
- (2) The pulldown capacitor should not exceed 1.1 nF when using MCUs with Spy-Bi-Wire interface in Spy-Bi-Wire mode with TI tools like FET interfaces or GANG programmers.

5 Specifications

5.1 Absolute Maximum Ratings⁽¹⁾

over operating free-air temperature range (unless otherwise noted)

	MIN	MAX	UNIT
Voltage applied at DVCC pin to V _{SS}	−0.3	4.1	V
Voltage applied to any other pin ⁽²⁾	−0.3	V _{CC} + 0.3 (4.1 V Max)	V
Diode current at any device pin		±2	mA
Maximum junction temperature, T _J		85	°C
Storage temperature, T _{stg} ⁽³⁾	−40	125	°C

- (1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions* is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) All voltages referenced to V_{SS}.
- (3) Higher temperature may be applied during board soldering according to the current JEDEC J-STD-020 specification with peak reflow temperatures not higher than classified on the device label on the shipping boxes or reels.

5.2 ESD Ratings

		VALUE	UNIT
V _(ESD) Electrostatic discharge	Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 ⁽¹⁾	±1000	V
	Charged-device model (CDM), per JEDEC specification JESD22-C101 ⁽²⁾	±250	

- (1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process. Pins listed as ±1000 V may actually have higher performance.
- (2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process. Pins listed as ±250 V may actually have higher performance.

5.3 Recommended Operating Conditions

		MIN	NOM	MAX	UNIT
V _{CC}	Supply voltage applied at DVCC pin ⁽¹⁾⁽²⁾⁽³⁾⁽⁴⁾	1.8		3.6	V
V _{SS}	Supply voltage applied at DVSS pin		0		V
T _A	Operating free-air temperature	−40		85	°C
T _J	Operating junction temperature	−40		85	°C
C _{DVCC}	Recommended capacitor at DVCC ⁽⁵⁾	4.7	10		μF
f _{SYSTEM}	Processor frequency (maximum MCLK frequency) ⁽⁴⁾⁽⁶⁾	No FRAM wait states (NWAITSx = 0)		8	MHz
		With FRAM wait states (NWAITSx = 1) ⁽⁷⁾		16 ⁽⁸⁾	
f _{ACLK}	Maximum ACLK frequency			40	kHz
f _{SMCLK}	Maximum SMCLK frequency			16 ⁽⁸⁾	MHz

- (1) Supply voltage changes faster than 0.2 V/μs can trigger a BOR reset even within the recommended supply voltage range. Following the data sheet recommendation for capacitor C_{DVCC} limits the slopes accordingly.
- (2) Modules may have a different supply voltage range specification. See the specification of the respective module in this data sheet.
- (3) TI recommends that power to the DVCC pin must not exceed the limits specified in *Recommended Operating Conditions*. Exceeding the specified limits can cause malfunction of the device including erroneous writes to RAM and FRAM.
- (4) The minimum supply voltage is defined by the SVS levels. See the SVS threshold parameters in [Table 5-2](#).
- (5) A capacitor tolerance of ±20% or better is required. A low-ESR ceramic capacitor of 100 nF (minimum) should be placed as close as possible (within a few millimeters) to the respective pin pair.
- (6) Modules may have a different maximum input clock specification. See the specification of the respective module in this data sheet.
- (7) Wait states only occur on actual FRAM accesses (that is, on FRAM cache misses). RAM and peripheral accesses are always executed without wait states.
- (8) If clock sources such as HF crystals or the DCO with frequencies >16 MHz are used, the clock must be divided in the clock system to comply with this operating condition.

5.4 Active Mode Supply Current Into V_{CC} Excluding External Current

See ⁽¹⁾

PARAMETER	EXECUTION MEMORY	TEST CONDITION	FREQUENCY (f _{MCLK} = f _{SMCLK})						UNIT
			1 MHz 0 WAIT STATES (NWAITS _x = 0)		8 MHz 0 WAIT STATES (NWAITS _x = 0)		16 MHz 1 WAIT STATE (NWAITS _x = 1)		
			TYP	MAX	TYP	MAX	TYP	MAX	
I _{AM, FRAM} (0%)	FRAM 0% cache hit ratio	3 V, 25°C	454		2620		2935		μA
		3 V, 85°C	471		2700		2980	3250	
I _{AM, FRAM} (100%)	FRAM 100% cache hit ratio	3 V, 25°C	191		573		950		μA
		3 V, 85°C	199		592		974	1200	
I _{AM, RAM} ⁽²⁾	RAM	3 V, 25°C	216		772		1300		μA

(1) All inputs are tied to 0 V or to V_{CC} . Outputs do not source or sink any current. Characterized with program executing typical data processing.

$f_{ACLK} = 32768$ Hz, $f_{MCLK} = f_{SMCLK} = f_{DCO}$ at specified frequency

Program and data entirely reside in FRAM. All execution is from FRAM.

(2) Program and data reside entirely in RAM. All execution is from RAM. No access to FRAM.

5.5 Active Mode Supply Current Per MHz

 $V_{CC} = 3$ V, $T_A = 25^\circ C$ (unless otherwise noted)

PARAMETER	TEST CONDITIONS	TYP	UNIT
$dI_{AM,FRAM}/df$	Active mode current consumption per MHz, execution from FRAM, no wait states I_{AM} (75% cache hit rate) at 8 MHz – I_{AM} (75% cache hit rate) at 1 MHz / 7 MHz	120	$\mu A/MHz$

5.6 Low-Power Mode (LPM0) Supply Currents Into V_{CC} Excluding External Current

 $V_{CC} = 3$ V, $T_A = 25^\circ C$ (unless otherwise noted) ⁽¹⁾⁽²⁾

PARAMETER	V _{CC}	FREQUENCY (f _{SMCLK})						UNIT
		1 MHz		8 MHz		16 MHz		
		TYP	MAX	TYP	MAX	TYP	MAX	
I _{LPM0}	2 V	145		292		395		μA
	3 V	155		300		394		

(1) All inputs are tied to 0 V or to V_{CC} . Outputs do not source or sink any current.

(2) Current for watchdog timer clocked by SMCLK included.

$f_{ACLK} = 32768$ Hz, $f_{MCLK} = 0$ MHz, f_{SMCLK} at specified frequency.

5.7 Low-Power Mode (LPM3, LPM4) Supply Currents (Into V_{CC}) Excluding External Current

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) ⁽¹⁾

PARAMETER		V_{CC}	-40°C		25°C		85°C		UNIT
			TYP	MAX	TYP	MAX	TYP	MAX	
$I_{LPM3,XT1}$	Low-power mode 3, 12.5-pF crystal, includes SVS ⁽²⁾⁽³⁾⁽⁴⁾	3 V	0.96		1.11		2.75	6.2	μA
		2 V	0.93		1.08		2.78		
$I_{LPM3,VLO}$	Low-power mode 3, VLO, excludes SVS ⁽⁵⁾	3 V	0.77		0.92		2.66	6.0	μA
		2 V	0.75		0.90		2.60		
$I_{LPM3,RTC}$	Low-power mode 3, RTC, excludes SVS ⁽⁶⁾	3 V	0.90		1.05		2.77		μA
$I_{LPM4,SVS}$	Low-power mode 4, includes SVS ⁽⁷⁾	3 V	0.51		0.64		2.30		μA
		2 V	0.49		0.61		2.25		
I_{LPM4}	Low-power mode 4, excludes SVS ⁽⁷⁾	3 V	0.35		0.48		2.13		μA
		2 V	0.34		0.46		2.10		
$I_{LPM4,VLO}$	Low-power mode 4, RTC is sourced from VLO, excludes SVS ⁽⁸⁾	3 V	0.43		0.56		2.21		μA
		2 V	0.42		0.55		2.19		
$I_{LPM4,XT1}$	Low-power mode 4, RTC is sourced from XT1, excludes SVS ⁽⁹⁾	3 V	0.80		0.96		2.68		μA
		2 V	0.79		0.94		2.64		

(1) All inputs are tied to 0 V or to V_{CC} . Outputs do not source or sink any current.

(2) Not applicable for MCUs with HF crystal oscillator only.

(3) Characterized with a Seiko Crystal SC-32S crystal with a load capacitance chosen to closely match the required load.

(4) Low-power mode 3, 12.5-pF crystal, includes SVS test conditions:

Current for watchdog timer clocked by ACLK and RTC clocked by XT1 included. Current for brownout and SVS included (SVSHE = 1).

CPUOFF = 1, SCG0 = 1 SCG1 = 1, OSCOFF = 0 (LPM3),

f_{XT1} = 32768 Hz, f_{ACLK} = f_{XT1} , f_{MCLK} = f_{SMCLK} = 0 MHz

(5) Low-power mode 3, VLO, excludes SVS test conditions:

Current for watchdog timer clocked by VLO included. RTC disabled. Current for brownout included. SVS disabled (SVSHE = 0).

CPUOFF = 1, SCG0 = 1 SCG1 = 1, OSCOFF = 0 (LPM3)

f_{XT1} = 32768 Hz, f_{ACLK} = f_{MCLK} = f_{SMCLK} = 0 MHz

(6) RTC periodically wakes up every second with external 32768-Hz input as source.

(7) Low-power mode 4, CPUOFF = 1, SCG0 = 1 SCG1 = 1, OSCOFF = 1 (LPM4), CPU and all clocks are disabled, WDT and RTC disabled

(8) Low-power mode 4, VLO, excludes SVS test conditions:

Current for RTC clocked by VLO included. Current for brownout included. SVS disabled (SVSHE = 0).

CPUOFF = 1, SCG0 = 1 SCG1 = 1, OSCOFF = 1 (LPM4)

f_{XT1} = 0 Hz, f_{MCLK} = f_{SMCLK} = 0 MHz

(9) Low-power mode 4, XT1, excludes SVS test conditions:

Current for RTC clocked by XT1 included. Current for brownout included. SVS disabled (SVSHE = 0).

CPUOFF = 1, SCG0 = 1 SCG1 = 1, OSCOFF = 1 (LPM4)

f_{XT1} = 32768 Hz, f_{MCLK} = f_{SMCLK} = 0 MHz

5.8 Low-Power Mode (LPMx.5) Supply Currents (Into V_{CC}) Excluding External Current

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

PARAMETER		V_{CC}	–40°C		25°C		85°C		UNIT
			TYP	MAX	TYP	MAX	TYP	MAX	
$I_{LPM3.5, XT1}$	Low-power mode 3.5, 12.5-pF crystal, includes SVS ⁽¹⁾⁽²⁾⁽³⁾ (also see Figure 5-3)	3 V	0.57		0.63		0.81	1.54	μA
		2 V	0.54		0.60		0.79		
$I_{LPM4.5, SVS}$	Low-power mode 4.5, includes SVS ⁽⁴⁾	3 V	0.23		0.25		0.31	0.45	μA
		2 V	0.21		0.23		0.29		
$I_{LPM4.5}$	Low-power mode 4.5, excludes SVS ⁽⁵⁾	3 V	0.027		0.036		0.080	0.15	μA
		2 V	0.022		0.031		0.073		

(1) Not applicable for MCUs with HF crystal oscillator only.

(2) Characterized with a Seiko Crystal SC-32S crystal with a load capacitance chosen to closely match the required load.

(3) Low-power mode 3.5, 12.5-pF crystal, includes SVS test conditions:

Current for RTC clocked by XT1 included. Current for brownout and SVS included (SVSHE = 1). Core regulator disabled.

PMMREGOFF = 1, CPUOFF = 1, SCG0 = 1 SCG1 = 1, OSCOFF = 1 (LPMx.5),

f_{XT1} = 32768 Hz, f_{ACLK} = 0, f_{MCLK} = f_{SMCLK} = 0 MHz

(4) Low-power mode 4.5, includes SVS test conditions:

Current for brownout and SVS included (SVSHE = 1). Core regulator disabled.

PMMREGOFF = 1, CPUOFF = 1, SCG0 = 1 SCG1 = 1, OSCOFF = 1 (LPMx.5)

f_{XT1} = 0 Hz, f_{ACLK} = f_{MCLK} = f_{SMCLK} = 0 MHz

(5) Low-power mode 4.5, excludes SVS test conditions:

Current for brownout included. SVS disabled (SVSHE = 0). Core regulator disabled.

PMMREGOFF = 1, CPUOFF = 1, SCG0 = 1 SCG1 = 1, OSCOFF = 1 (LPMx.5)

f_{XT1} = 0 Hz, f_{ACLK} = f_{MCLK} = f_{SMCLK} = 0 MHz

5.9 Typical Characteristics - Low-Power Mode Supply Currents

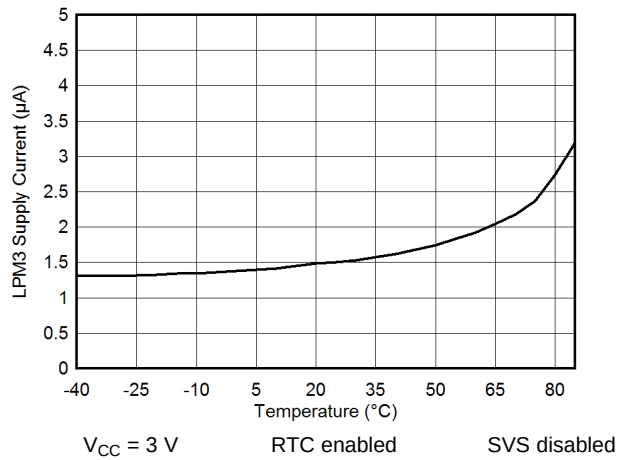


Figure 5-1. LPM3 Supply Current vs Temperature

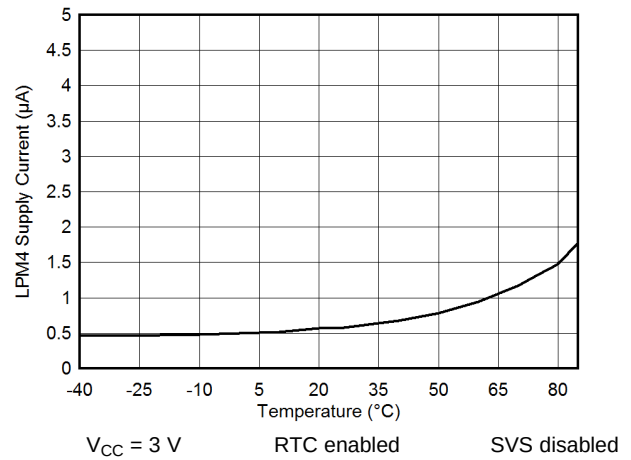


Figure 5-2. LPM4 Supply Current vs Temperature

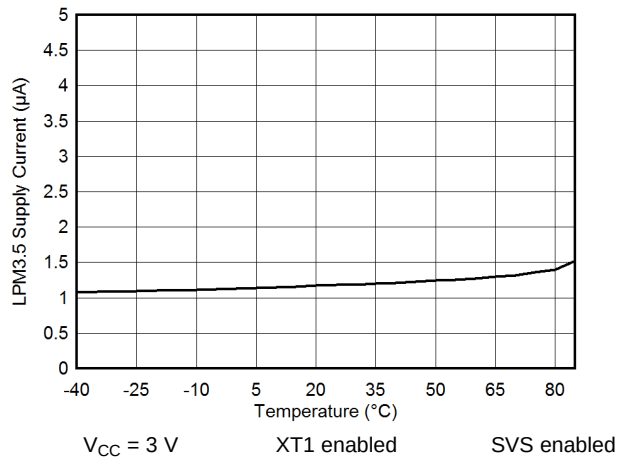


Figure 5-3. LPM3.5 Supply Current vs Temperature

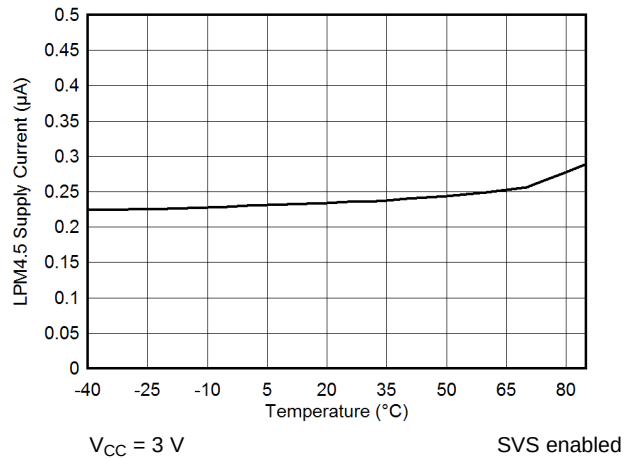


Figure 5-4. LPM4.5 Supply Current vs Temperature

Table 5-1. Typical Characteristics – Current Consumption Per Module

MODULE	TEST CONDITIONS	REFERENCE CLOCK	MIN	TYP	MAX	UNIT
Timer_A		Module input clock		5		µA/MHz
eUSCI_A	UART mode	Module input clock		7		µA/MHz
eUSCI_A	SPI mode	Module input clock		5		µA/MHz
eUSCI_B	SPI mode	Module input clock		5		µA/MHz
eUSCI_B	I ² C mode, 100 kbaud	Module input clock		5		µA/MHz
RTC		32 kHz		85		nA
CRC	From start to end of operation	MCLK		8.5		µA/MHz

5.10 Thermal Resistance Characteristics

THERMAL METRIC ⁽¹⁾		VALUE ⁽²⁾	UNIT
R θ_{JA}	Junction-to-ambient thermal resistance, still air	VQFN 20 pin (RHL)	37.8
		TSSOP 16 pin (PW16)	101.7
R θ_{JC}	Junction-to-case (top) thermal resistance	VQFN 20 pin (RHL)	34.1
		TSSOP 16 pin (PW16)	33.7
R θ_{JB}	Junction-to-board thermal resistance	VQFN 20 pin (RHL)	15.3
		TSSOP 16 pin (PW16)	47.5

- (1) For more information about traditional and new thermal metrics, see [Semiconductor and IC Package Thermal Metrics](#).
- (2) These values are based on a JEDEC-defined 2S2P system (with the exception of the Theta JC (R θ_{JC}) value, which is based on a JEDEC-defined 1S0P system) and will change based on environment and application. For more information, see these EIA/JEDEC standards:
- JESD51-2, *Integrated Circuits Thermal Test Method Environmental Conditions - Natural Convection (Still Air)*
 - JESD51-3, *Low Effective Thermal Conductivity Test Board for Leaded Surface Mount Packages*
 - JESD51-7, *High Effective Thermal Conductivity Test Board for Leaded Surface Mount Packages*
 - JESD51-9, *Test Boards for Area Array Surface Mount Package Thermal Measurements*

5.11 Timing and Switching Characteristics

5.11.1 Power Supply Sequencing

Table 5-2 lists the characteristics of the SVS and BOR.

Table 5-2. PMM, SVS and BOR

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
V _{BOR, safe}	Safe BOR power-down level ⁽¹⁾		0.1			V
t _{BOR, safe}	Safe BOR reset delay ⁽²⁾		10			ms
I _{SVSH,AM}	SVS _H current consumption, active mode	V _{CC} = 3.6 V			1.5	μA
I _{SVSH,LPM}	SVS _H current consumption, low-power modes	V _{CC} = 3.6 V		240		nA
V _{SVSH-}	SVS _H power-down level ⁽³⁾		1.71	1.80	1.87	V
V _{SVSH+}	SVS _H power-up level ⁽³⁾		1.76	1.88	1.99	V
V _{SVSH_hys}	SVS _H hysteresis			80		mV
t _{PD,SVSH,AM}	SVS _H propagation delay, active mode				10	μs
t _{PD,SVSH,LPM}	SVS _H propagation delay, low-power modes				100	μs

- (1) A safe BOR can be correctly generated only if DVCC drops below this voltage before it rises.
- (2) When an BOR occurs, a safe BOR can be correctly generated only if DVCC is kept low longer than this period before it reaches V_{SVSH+}.
- (3) For additional information, see the [Dynamic Voltage Scaling Power Solution for MSP430 Devices With Single-Channel LDO Reference Design](#).

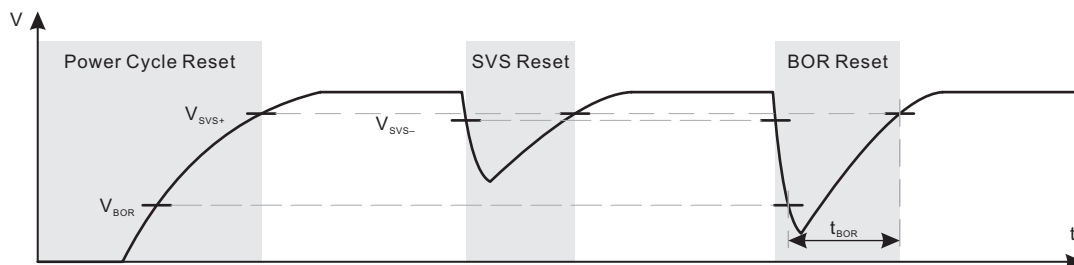


Figure 5-5. Power Cycle, SVS, and BOR Reset Conditions

5.11.2 Reset Timing

Table 5-3 lists the timing characteristics of wakeup from LPMs and reset.

Table 5-3. Wake-up Times From Low-Power Modes and Reset

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

PARAMETER		TEST CONDITIONS	V _{CC}	MIN	TYP	MAX	UNIT
t _{WAKE-UP FRAM}	Additional wake-up time to activate the FRAM in AM if previously disabled by the FRAM controller or from a LPM if immediate activation is selected for wakeup ⁽¹⁾		3 V		10		μs
t _{WAKE-UP LPM0}	Wake-up time from LPM0 to active mode ⁽¹⁾		3 V		200 + 2.5 / f _{DCO}		ns
t _{WAKE-UP LPM3}	Wake-up time from LPM3 to active mode ⁽²⁾		3 V		10		μs
t _{WAKE-UP LPM4}	Wake-up time from LPM4 to active mode		3 V		10		μs
t _{WAKE-UP LPM3.5}	Wake-up time from LPM3.5 to active mode ⁽²⁾		3 V		350		μs
t _{WAKE-UP LPM4.5}	Wake-up time from LPM4.5 to active mode ⁽²⁾	SVSHE = 1	3 V		350		μs
		SVSHE = 0			1		ms
t _{WAKE-UP-RESET}	Wake-up time from $\overline{\text{RST}}$ or BOR event to active mode ⁽²⁾		3 V		1		ms
t _{RESET}	Pulse duration required at $\overline{\text{RST}}$ /NMI pin to accept a reset		3 V		2		μs

- (1) The wake-up time is measured from the edge of an external wake-up signal (for example, port interrupt or wake-up event) to the first externally observable MCLK clock edge.
- (2) The wake-up time is measured from the edge of an external wake-up signal (for example, port interrupt or wake-up event) until the first instruction of the user program is executed.

5.11.3 Clock Specifications

Table 5-4 lists the characteristics of the LF XT1.

Table 5-4. XT1 Crystal Oscillator (Low Frequency)

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)⁽¹⁾⁽²⁾

PARAMETER	TEST CONDITIONS	V _{CC}	MIN	TYP	MAX	UNIT
f _{XT1, LF} XT1 oscillator crystal, low frequency	LFXTBYPASS = 0			32768		Hz
DC _{XT1, LF} XT1 oscillator LF duty cycle	Measured at MCLK, f _{LFXT} = 32768 Hz		30%		70%	
f _{XT1, SW} XT1 oscillator logic-level square-wave input frequency	LFXTBYPASS = 1 ⁽³⁾⁽⁴⁾			32.768		kHz
DC _{XT1, SW} LFXT oscillator logic-level square-wave input duty cycle	LFXTBYPASS = 1		40%		60%	
OA _{LFXT} Oscillation allowance for LF crystals ⁽⁵⁾	LFXTBYPASS = 0, LFXTDRIVE = {3}, f _{LFXT} = 32768 Hz, C _{L,eff} = 12.5 pF			200		kΩ
C _{L,eff} Integrated effective load capacitance ⁽⁶⁾	See ⁽⁷⁾			1		pF
t _{START, LFXT} Start-up time ⁽⁸⁾	f _{OSC} = 32768 Hz, LFXTBYPASS = 0, LFXTDRIVE = {3}, T _A = 25°C, C _{L,eff} = 12.5 pF			1000		ms
f _{Fault, LFXT} Oscillator fault frequency ⁽⁹⁾	XTS = 0 ⁽¹⁰⁾		0		3500	Hz

- (1) To improve EMI on the LFXT oscillator, observe the following guidelines:
 - Keep the trace between the device and the crystal as short as possible.
 - Design a good ground plane around the oscillator pins.
 - Prevent crosstalk from other clock or data lines into oscillator pins XIN and XOUT.
 - Avoid running PCB traces underneath or adjacent to the XIN and XOUT pins.
 - Use assembly materials and processes that avoid any parasitic load on the oscillator XIN and XOUT pins.
 - If conformal coating is used, make sure that it does not induce capacitive or resistive leakage between the oscillator pins.
- (2) See [MSP430 32-kHz Crystal Oscillators](#) for details on crystal section, layout, and testing.
- (3) When LFXTBYPASS is set, LFXT circuits are automatically powered down. Input signal is a digital square wave with parametrics defined in the Schmitt-trigger inputs section of this data sheet. Duty cycle requirements are defined by DC_{LFXT, SW}.
- (4) Maximum frequency of operation of the entire device cannot be exceeded.
- (5) Oscillation allowance is based on a safety factor of 5 for recommended crystals. The oscillation allowance is a function of the LFXTDRIVE settings and the effective load. In general, comparable oscillator allowance can be achieved based on the following guidelines, but should be evaluated based on the actual crystal selected for the application:
 - For LFXTDRIVE = {0}, C_{L,eff} = 3.7 pF
 - For LFXTDRIVE = {1}, 6 pF ≤ C_{L,eff} ≤ 9 pF
 - For LFXTDRIVE = {2}, 6 pF ≤ C_{L,eff} ≤ 10 pF
 - For LFXTDRIVE = {3}, 6 pF ≤ C_{L,eff} ≤ 12 pF
- (6) Includes parasitic bond and package capacitance (approximately 2 pF per pin).
- (7) Requires external capacitors at both terminals to meet the effective load capacitance specified by crystal manufacturers. Recommended effective load capacitance values supported are 3.7 pF, 6 pF, 9 pF, and 12.5 pF. Maximum shunt capacitance of 1.6 pF. The PCB adds additional capacitance, so it must also be considered in the overall capacitance. Verify that the recommended effective load capacitance of the selected crystal is met.
- (8) Includes start-up counter of 1024 clock cycles.
- (9) Frequencies above the MAX specification do not set the fault flag. Frequencies between the MIN and MAX specifications might set the flag. A static condition or stuck at fault condition sets the flag.
- (10) Measured with logic-level input frequency but also applies to operation with crystals.

Table 5-5 lists the frequency characteristics of the FLL.

Table 5-5. DCO FLL, Frequency

over recommended operating free-air temperature (unless otherwise noted)

PARAMETER	TEST CONDITIONS	V _{CC}	MIN	TYP	MAX	UNIT
f _{DCO, FLL}	FLL lock frequency, 16 MHz, 25°C	Measured at MCLK, Internal trimmed REFO as reference	3 V	–1.0%	1.0%	
	FLL lock frequency, 16 MHz, –40°C to 85°C		3 V	–2.0%	2.0%	
	FLL lock frequency, 16 MHz, –40°C to 85°C	Measured at MCLK, XT1 crystal as reference	3 V	–0.5%	0.5%	

Table 5-5. DCO FLL, Frequency (continued)

over recommended operating free-air temperature (unless otherwise noted)

PARAMETER	TEST CONDITIONS	V _{CC}	MIN	TYP	MAX	UNIT
f _{DUTY} Duty cycle	Measured at MCLK, XT1 crystal as reference	3 V	40%	50%	60%	
Jitter _{cc} Cycle-to-cycle jitter, 16 MHz		3 V		0.25%		
Jitter _{long} Long term jitter, 16 MHz		3 V		0.022%		
t _{FLL, lock} FLL lock time, 16MHz		3 V		280		ms

Table 5-6 lists the characteristics of the DCO.

Table 5-6. DCO Frequency

over recommended operating free-air temperature (unless otherwise noted) (see Figure 5-6)

PARAMETER	TEST CONDITIONS	V _{CC}	TYP	UNIT
f _{DCO, 16MHz} DCO frequency, 16 MHz	DCORSEL = 101b, DISMOD = 1b, DCOFTRIMEN = 1b, DCOFTRIM = 000b, DCO = 0	3 V	7.1	MHz
	DCORSEL = 101b, DISMOD = 1b, DCOFTRIMEN = 1b, DCOFTRIM = 000b, DCO = 511		11.8	
	DCORSEL = 101b, DISMOD = 1b, DCOFTRIMEN = 1b, DCOFTRIM = 111b, DCO = 0		17	
	DCORSEL = 101b, DISMOD = 1b, DCOFTRIMEN = 1b, DCOFTRIM = 111b, DCO = 511		27.7	
f _{DCO, 12MHz} DCO frequency, 12 MHz	DCORSEL = 100b, DISMOD = 1b, DCOFTRIMEN = 1b, DCOFTRIM = 000b, DCO = 0	3 V	5.5	MHz
	DCORSEL = 100b, DISMOD = 1b, DCOFTRIMEN = 1b, DCOFTRIM = 000b, DCO = 511		9.1	
	DCORSEL = 100b, DISMOD = 1b, DCOFTRIMEN = 1b, DCOFTRIM = 111b, DCO = 0		13.1	
	DCORSEL = 100b, DISMOD = 1b, DCOFTRIMEN = 1b, DCOFTRIM = 111b, DCO = 511		21.5	
f _{DCO, 8MHz} DCO frequency, 8 MHz	DCORSEL = 011b, DISMOD = 1b, DCOFTRIMEN = 1b, DCOFTRIM = 000b, DCO = 0	3 V	3.7	MHz
	DCORSEL = 011b, DISMOD = 1b, DCOFTRIMEN = 1b, DCOFTRIM = 000b, DCO = 511		6.3	
	DCORSEL = 011b, DISMOD = 1b, DCOFTRIMEN = 1b, DCOFTRIM = 111b, DCO = 0		9.0	
	DCORSEL = 011b, DISMOD = 1b, DCOFTRIMEN = 1b, DCOFTRIM = 111b, DCO = 511		14.9	
f _{DCO, 4MHz} DCO frequency, 4 MHz	DCORSEL = 010b, DISMOD = 1b, DCOFTRIMEN = 1b, DCOFTRIM = 000b, DCO = 0	3 V	1.9	MHz
	DCORSEL = 010b, DISMOD = 1b, DCOFTRIMEN = 1b, DCOFTRIM = 000b, DCO = 511		3.2	
	DCORSEL = 010b, DISMOD = 1b, DCOFTRIMEN = 1b, DCOFTRIM = 111b, DCO = 0		4.6	
	DCORSEL = 010b, DISMOD = 1b, DCOFTRIMEN = 1b, DCOFTRIM = 111b, DCO = 511		7.8	
f _{DCO, 2MHz} DCO frequency, 2 MHz	DCORSEL = 001b, DISMOD = 1b, DCOFTRIMEN = 1b, DCOFTRIM = 000b, DCO = 0	3 V	0.96	MHz
	DCORSEL = 001b, DISMOD = 1b, DCOFTRIMEN = 1b, DCOFTRIM = 000b, DCO = 511		1.6	
	DCORSEL = 001b, DISMOD = 1b, DCOFTRIMEN = 1b, DCOFTRIM = 111b, DCO = 0		2.3	
	DCORSEL = 001b, DISMOD = 1b, DCOFTRIMEN = 1b, DCOFTRIM = 111b, DCO = 511		4.0	

Table 5-6. DCO Frequency (continued)

over recommended operating free-air temperature (unless otherwise noted) (see [Figure 5-6](#))

PARAMETER	TEST CONDITIONS	V _{CC}	TYP	UNIT
f _{DCO, 1MHz} DCO frequency, 1 MHz	DCORSEL = 000b, DISMOD = 1b, DCOFTRIMEN = 1b, DCOFTRIM = 000b, DCO = 0	3 V	0.5	MHz
	DCORSEL = 000b, DISMOD = 1b, DCOFTRIMEN = 1b, DCOFTRIM = 000b, DCO = 511		0.85	
	DCORSEL = 000b, DISMOD = 1b, DCOFTRIMEN = 1b, DCOFTRIM = 111b, DCO = 0		1.2	
	DCORSEL = 000b, DISMOD = 1b, DCOFTRIMEN = 1b, DCOFTRIM = 111b, DCO = 511		2.0	

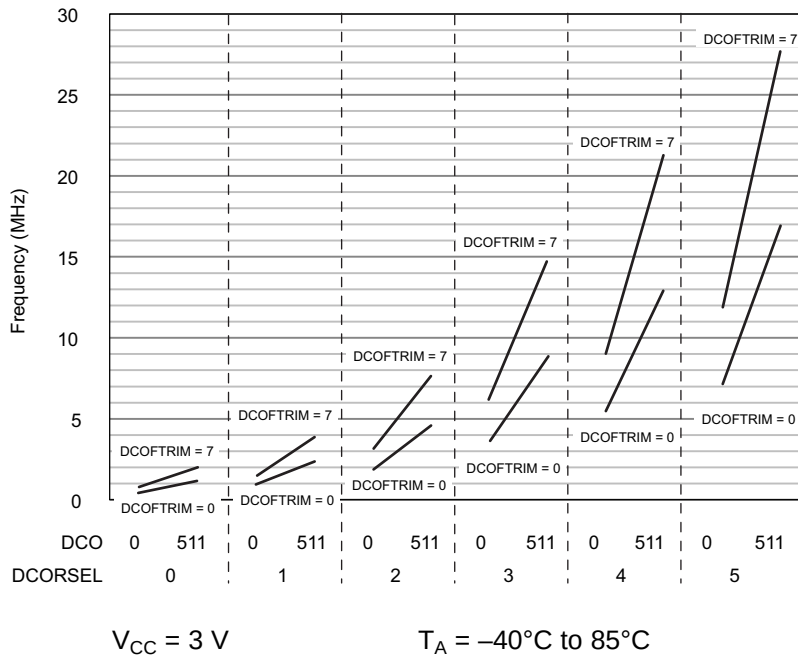


Figure 5-6. Typical DCO Frequency

[Table 5-7](#) lists the characteristics of the REFO.

Table 5-7. REFO

over recommended operating free-air temperature (unless otherwise noted)

PARAMETER	TEST CONDITIONS	V _{CC}	MIN	TYP	MAX	UNIT
I _{REFO}	REFO oscillator current consumption	T _A = 25°C		15		μA
f _{REFO}	REFO calibrated frequency	Measured at MCLK		32768		Hz
	REFO absolute calibrated tolerance	-40°C to 85°C				
df _{REFO} /dT	REFO frequency temperature drift	Measured at MCLK ⁽¹⁾		0.01		%/°C
df _{REFO} /dV _{CC}	REFO frequency supply voltage drift	Measured at MCLK at 25°C ⁽²⁾		1		%/V
f _{DC}	REFO duty cycle	Measured at MCLK		50%		
t _{START}	REFO start-up time	40% to 60% duty cycle		50		μs

(1) Calculated using the box method: (MAX(-40°C to 85°C) – MIN(-40°C to 85°C)) / MIN(-40°C to 85°C) / (85°C – (-40°C))

(2) Calculated using the box method: (MAX(1.8 V to 3.6 V) – MIN(1.8 V to 3.6 V)) / MIN(1.8 V to 3.6 V) / (3.6 V – 1.8 V)

Table 5-8 lists the characteristics of the VLO.

Table 5-8. Internal Very-Low-Power Low-Frequency Oscillator (VLO)

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

PARAMETER	TEST CONDITIONS	V _{CC}	TYP	UNIT
f _{VLO} VLO frequency	Measured at MCLK	3 V	10	kHz
df _{VLO} /dT VLO frequency temperature drift	Measured at MCLK ⁽¹⁾	3 V	0.5	%/°C
df _{VLO} /dV _{CC} VLO frequency supply voltage drift	Measured at MCLK ⁽²⁾	1.8 V to 3.6 V	4	%/V
f _{VLO,DC} Duty cycle	Measured at MCLK	3 V	50%	

(1) Calculated using the box method: (MAX(–40°C to 85°C) – MIN(–40°C to 85°C)) / MIN(–40°C to 85°C) / (85°C – (–40°C))

(2) Calculated using the box method: (MAX(1.8 V to 3.6 V) – MIN(1.8 V to 3.6 V)) / MIN(1.8 V to 3.6 V) / (3.6 V – 1.8 V)

NOTE

The VLO clock frequency is reduced by 15% (typical) when the device switches from active mode to LPM3 or LPM4, because the reference changes. This lower frequency is not a violation of the VLO specifications (see Table 5-8).

Table 5-9 lists the characteristics of the MODOSC.

Table 5-9. Module Oscillator (MODOSC)

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

PARAMETER	TEST CONDITIONS	V _{CC}	MIN	TYP	MAX	UNIT
f _{MODOSC} MODOSC frequency		3 V	3.8	4.8	5.8	MHz
f _{MODOSC} /dT MODOSC frequency temperature drift		3 V		0.102		%/°C
f _{MODOSC} /dV _{CC} MODOSC frequency supply voltage drift		1.8 V to 3.6 V		1.02		%/V
f _{MODOSC,DC} Duty cycle		3 V	40%	50%	60%	

5.11.4 Digital I/Os

Table 5-10 lists the characteristics of the digital inputs.

Table 5-10. Digital Inputs

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

PARAMETER	TEST CONDITIONS	V _{CC}	MIN	TYP	MAX	UNIT
V _{IT+} Positive-going input threshold voltage		2 V	0.90		1.50	V
		3 V	1.35		2.25	
V _{IT-} Negative-going input threshold voltage		2 V	0.50		1.10	V
		3 V	0.75		1.65	
V _{hys} Input voltage hysteresis (V _{IT+} – V _{IT-})		2 V	0.3		0.8	V
		3 V	0.4		1.2	
R _{Pull} Pullup or pulldown resistor	For pullup: V _{IN} = V _{SS} For pulldown: V _{IN} = V _{CC}		20	35	50	kΩ
C _{I,dig} Input capacitance, digital only port pins	V _{IN} = V _{SS} or V _{CC}			3		pF
C _{I,ana} Input capacitance, port pins with shared analog functions	V _{IN} = V _{SS} or V _{CC}			5		pF
I _{lkg(Px.y)} High-impedance leakage current of GPIO pins	See ⁽¹⁾ ⁽²⁾	2 V, 3 V	–20		20	nA
t _(int) External interrupt timing (external trigger pulse duration to set interrupt flag) ⁽³⁾	Ports with interrupt capability (see block diagram and terminal function descriptions)	2 V, 3 V	50			ns

- (1) The leakage current is measured with V_{SS} or V_{CC} applied to the corresponding pins, unless otherwise noted.
- (2) The leakage of the digital port pins is measured individually. The port pin is selected for input and the pullup or pulldown resistor is disabled.
- (3) An external signal sets the interrupt flag every time the minimum interrupt pulse duration t_(int) is met. It may be set by trigger signals shorter than t_(int).

Table 5-11 lists the characteristics of the digital outputs.

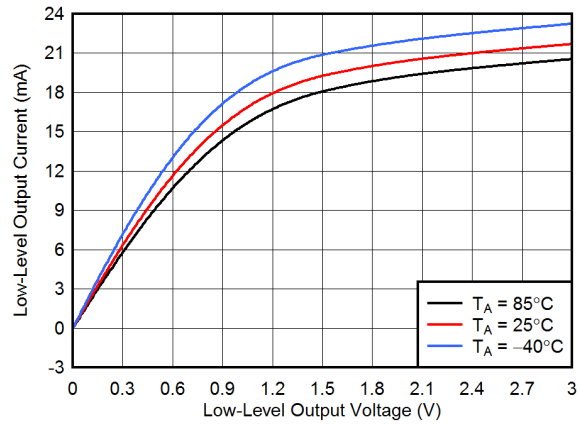
Table 5-11. Digital Outputs

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

PARAMETER	TEST CONDITIONS	V _{CC}	MIN	TYP	MAX	UNIT
V _{OH} High-level output voltage	I _(OHmax) = –3 mA ⁽¹⁾	2 V	1.4		2.0	V
	I _(OHmax) = –5 mA ⁽¹⁾	3 V	2.4		3.0	
V _{OL} Low-level output voltage	I _(OLmax) = 3 mA ⁽¹⁾	2 V	0.0		0.60	V
	I _(OHmax) = 5 mA ⁽¹⁾	3 V	0.0		0.60	
f _{Port_CLK} Clock output frequency	C _L = 20 pF ⁽²⁾	2 V	16			MHz
		3 V	16			
t _{rise,dig} Port output rise time, digital only port pins	C _L = 20 pF	2 V		10		ns
		3 V		7		
t _{fall,dig} Port output fall time, digital only port pins	C _L = 20 pF	2 V		10		ns
		3 V		5		

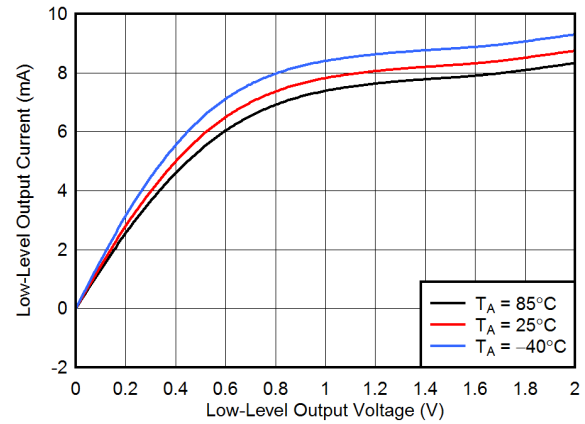
- (1) The maximum total current, I_(OHmax) and I_(OLmax), for all outputs combined should not exceed ±48 mA to hold the maximum voltage drop specified.
- (2) The port can output frequencies at least up to the specified limit and might support higher frequencies.

5.11.4.1 Typical Characteristics – Outputs at 3 V and 2 V



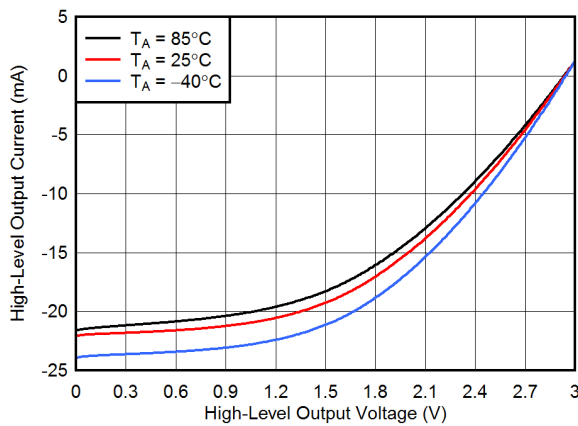
DVCC = 3 V

Figure 5-7. Typical Low-Level Output Current vs Low-Level Output Voltage



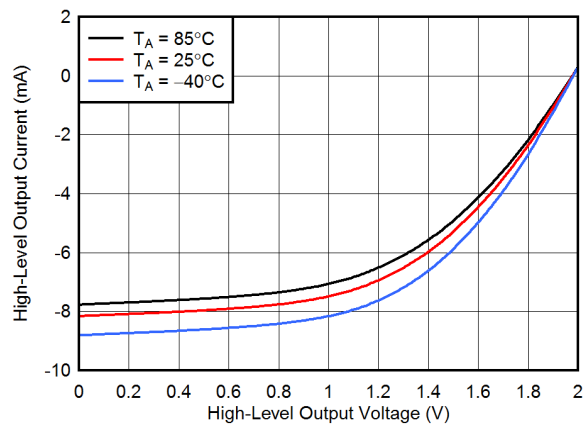
DVCC = 2 V

Figure 5-8. Typical Low-Level Output Current vs Low-Level Output Voltage



DVCC = 3 V

Figure 5-9. Typical High-Level Output Current vs High-Level Output Voltage



DVCC = 2 V

Figure 5-10. Typical High-Level Output Current vs High-Level Output Voltage

5.11.5 VREF+ Built-in Reference

Table 5-12 lists the characteristics of the VREF+.

Table 5-12. VREF+

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

PARAMETER	TEST CONDITIONS	V _{CC}	MIN	TYP	MAX	UNIT
V _{REF+}	Positive built-in reference voltage	EXTREFEN = 1 with 1-mA load current	2 V, 3 V	1.15	1.19	1.23 V
TC _{REF+}	Temperature coefficient of built-in reference voltage			30		μV/°C

5.11.6 Timer_A

Table 5-13 lists the characteristics of Timer_A.

Table 5-13. Timer_A

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

PARAMETER	TEST CONDITIONS	V _{CC}	MIN	TYP	MAX	UNIT
f _{TA}	Timer_A input clock frequency Internal: SMCLK, ACLK External: TACLK Duty cycle = 50% ±10%	2 V, 3 V			16	MHz
t _{TA,cap}	Timer_A capture timing All capture inputs, minimum pulse duration required for capture	2 V, 3 V	20			ns

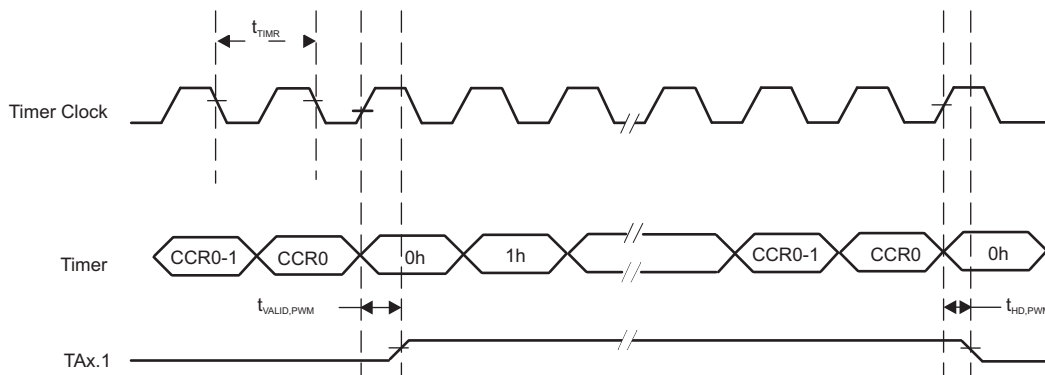


Figure 5-11. Timer PWM Mode

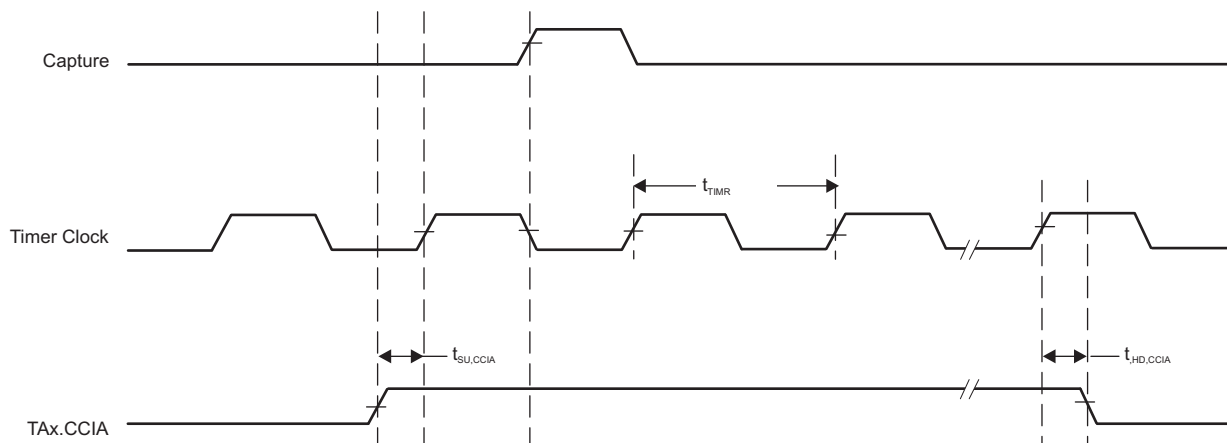


Figure 5-12. Timer Capture Mode

5.11.7 eUSCI

Table 5-14 lists the supported frequencies of the eUSCI in UART mode.

Table 5-14. eUSCI (UART Mode) Clock Frequency

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

PARAMETER	TEST CONDITIONS	V _{CC}	MIN	MAX	UNIT
f _{eUSCI} eUSCI input clock frequency	Internal: SMCLK, MODCLK External: UCLK Duty cycle = 50% ±10%	2 V, 3 V		16	MHz
f _{BITCLK} BITCLK clock frequency (equals baud rate in Mbaud)		2 V, 3 V		5	MHz

Table 5-15 lists the characteristics of the eUSCI in UART mode.

Table 5-15. eUSCI (UART Mode)

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

PARAMETER	TEST CONDITIONS	V _{CC}	TYP	UNIT
t _t UART receive deglitch time ⁽¹⁾	UCGLITx = 0	2 V, 3 V	12	ns
	UCGLITx = 1		40	
	UCGLITx = 2		68	
	UCGLITx = 3		110	

- (1) Pulses on the UART receive input (UCxRX) shorter than the UART receive deglitch time are suppressed. To ensure that pulses are correctly recognized, their duration should exceed the maximum specification of the deglitch time.

Table 5-16 lists the supported frequencies of the eUSCI in SPI master mode.

Table 5-16. eUSCI (SPI Master Mode) Clock Frequency

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

PARAMETER	TEST CONDITIONS	MIN	MAX	UNIT
f _{eUSCI} eUSCI input clock frequency	Internal: SMCLK, MODCLK Duty cycle = 50% ±10%		8	MHz

Table 5-17 lists the characteristics of the eUSCI in SPI master mode.

Table 5-17. eUSCI (SPI Master Mode)

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)⁽¹⁾

PARAMETER	TEST CONDITIONS	V _{CC}	MIN	MAX	UNIT
t _{STE,LEAD} STE lead time, STE active to clock	UCSTEM = 0, UCMODEx = 01 or 10		1		UCxCLK cycles
	UCSTEM = 1, UCMODEx = 01 or 10				
t _{STE,LAG} STE lag time, last clock to STE inactive	UCSTEM = 0, UCMODEx = 01 or 10		1		UCxCLK cycles
	UCSTEM = 1, UCMODEx = 01 or 10				
t _{SU,MI} SOMI input data setup time		2 V	48		ns
		3 V	37		
t _{HD,MI} SOMI input data hold time		2 V	0		ns
		3 V	0		
t _{VALID,MO} SIMO output data valid time ⁽²⁾	UCLK edge to SIMO valid, C _L = 20 pF	2 V		20	ns
		3 V		20	
t _{HD,MO} SIMO output data hold time ⁽³⁾	C _L = 20 pF	2 V	-6		ns
		3 V	-5		

- (1) $f_{UCxCLK} = 1/2t_{LO/HI}$ with $t_{LO/HI} = \max(t_{VALID,MO(eUSCI)} + t_{SU,SI(Slave)}, t_{SU,MI(eUSCI)} + t_{VALID,SO(Slave)})$
For the slave parameters $t_{SU,SI(Slave)}$ and $t_{VALID,SO(Slave)}$, see the SPI parameters of the attached slave.
- (2) Specifies the time to drive the next valid data to the SIMO output after the output changing UCLK clock edge. See the timing diagrams in Figure 5-13 and Figure 5-14.
- (3) Specifies how long data on the SIMO output is valid after the output changing UCLK clock edge. Negative values indicate that the data on the SIMO output can become invalid before the output changing clock edge observed on UCLK. See the timing diagrams in Figure 5-13 and Figure 5-14.

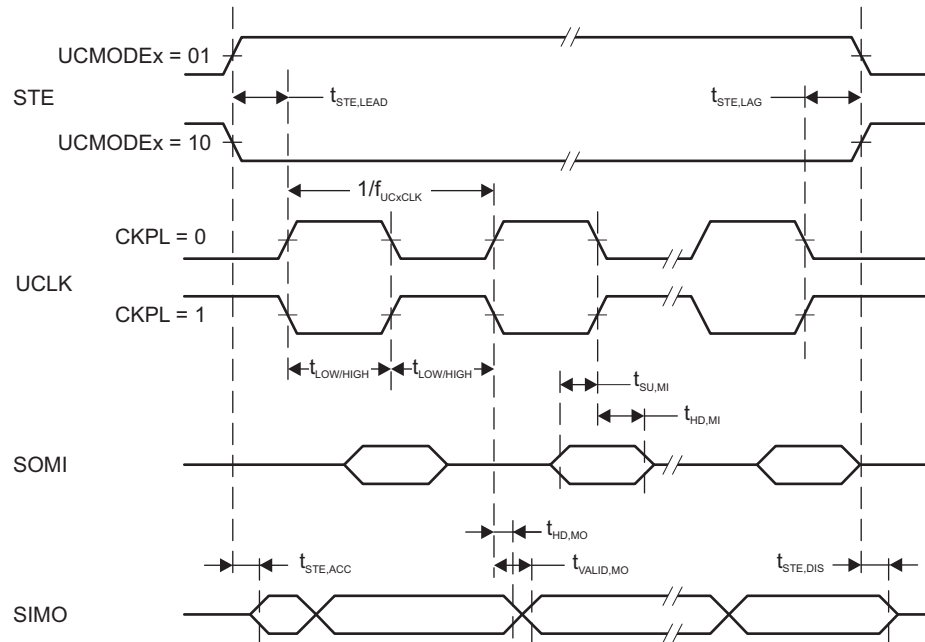


Figure 5-13. SPI Master Mode, CKPH = 0

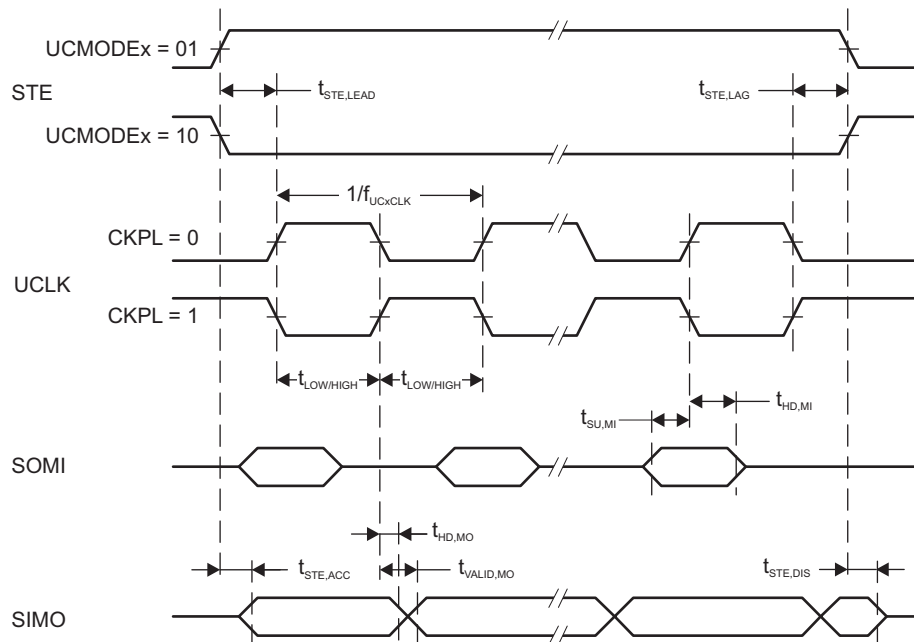


Figure 5-14. SPI Master Mode, CKPH = 1

Table 5-18 lists the characteristics of the eUSCI in SPI slave mode.

Table 5-18. eUSCI (SPI Slave Mode)

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)⁽¹⁾

PARAMETER	TEST CONDITIONS	V _{CC}	MIN	MAX	UNIT
t _{STE,LEAD} STE lead time, STE active to clock		2 V	55		ns
		3 V	45		
t _{STE,LAG} STE lag time, Last clock to STE inactive		2 V	20		ns
		3 V	20		
t _{STE,ACC} STE access time, STE active to SOMI data out		2 V		65	ns
		3 V		40	
t _{STE,DIS} STE disable time, STE inactive to SOMI high impedance		2 V		40	ns
		3 V		35	
t _{SU,SI} SIMO input data setup time		2 V	8		ns
		3 V	6		
t _{HD,SI} SIMO input data hold time		2 V	12		ns
		3 V	12		
t _{VALID,SO} SOMI output data valid time ⁽²⁾	UCLK edge to SOMI valid, C _L = 20 pF	2 V		68	ns
		3 V		42	
t _{HD,SO} SOMI output data hold time ⁽³⁾	C _L = 20 pF	2 V	5		ns
		3 V	5		

- (1) $f_{UCXCLK} = 1/2t_{LO/HI}$ with $t_{LO/HI} \geq \max(t_{VALID,MO(Master)} + t_{SU,SI(eUSCI)}, t_{SU,MI(Master)} + t_{VALID,SO(eUSCI)})$
For the master parameters $t_{SU,MI(Master)}$ and $t_{VALID,MO(Master)}$, see the SPI parameters of the attached master.
- (2) Specifies the time to drive the next valid data to the SOMI output after the output changing UCLK clock edge. See the timing diagrams in [Figure 5-15](#) and [Figure 5-16](#).
- (3) Specifies how long data on the SOMI output is valid after the output changing UCLK clock edge. See the timing diagrams in [Figure 5-15](#) and [Figure 5-16](#).

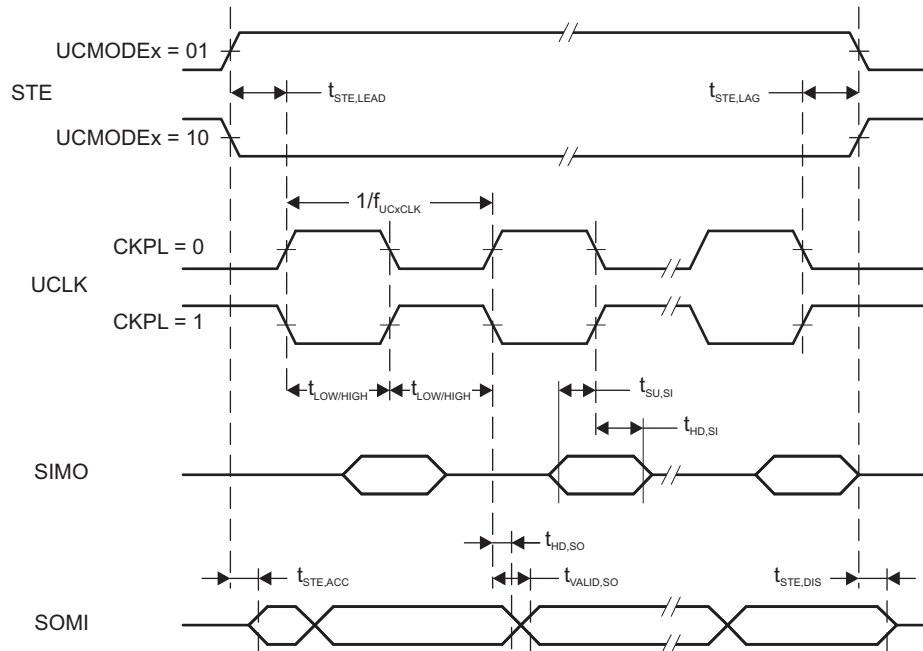


Figure 5-15. SPI Slave Mode, CKPH = 0

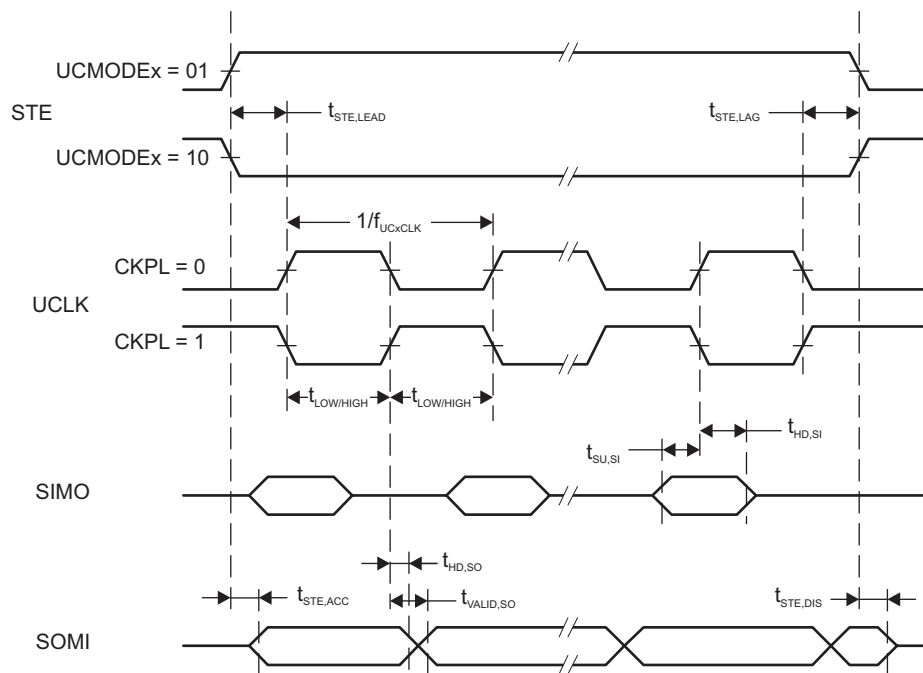


Figure 5-16. SPI Slave Mode, CKPH = 1

Table 5-19 lists the characteristics of the eUSCI in I²C mode.

Table 5-19. eUSCI (I²C Mode)

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Figure 5-17)

PARAMETER	TEST CONDITIONS	V _{CC}	MIN	TYP	MAX	UNIT
f _{eUSCI} eUSCI input clock frequency	Internal: SMCLK, MODCLK External: UCLK Duty cycle = 50% ±10%				16	MHz
f _{SCL} SCL clock frequency		2 V, 3 V	0		400	kHz
t _{HD,STA} Hold time (repeated) START	f _{SCL} = 100 kHz f _{SCL} > 100 kHz	2 V, 3 V	4.0 0.6			μs
t _{SU,STA} Setup time for a repeated START	f _{SCL} = 100 kHz f _{SCL} > 100 kHz	2 V, 3 V	4.7 0.6			μs
t _{HD,DAT} Data hold time		2 V, 3 V	0			ns
t _{SU,DAT} Data setup time		2 V, 3 V	250			ns
t _{SU,STO} Setup time for STOP	f _{SCL} = 100 kHz f _{SCL} > 100 kHz	2 V, 3 V	4.0 0.6			μs
t _{SP} Pulse duration of spikes suppressed by input filter	UCGLITx = 0 UCGLITx = 1 UCGLITx = 2 UCGLITx = 3	2 V, 3 V	50 25 12.5 6.3		600 300 150 75	ns
t _{TIMEOUT} Clock low time-out	UCCLTOx = 1 UCCLTOx = 2 UCCLTOx = 3	2 V, 3 V		27 30 33		ms

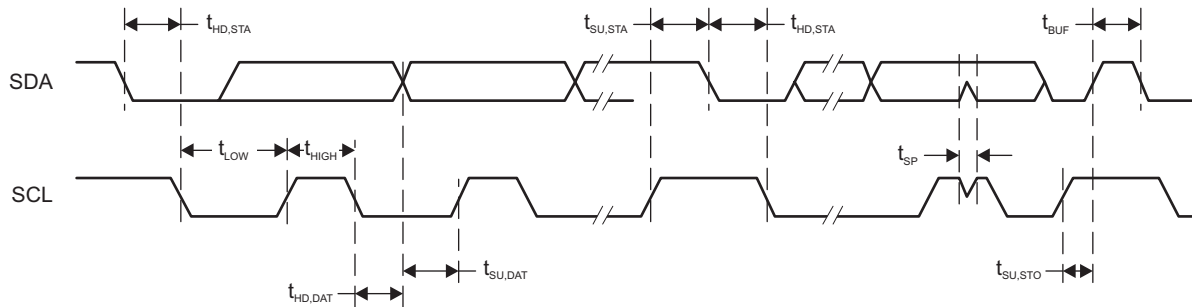


Figure 5-17. I²C Mode Timing

5.11.8 ADC

Table 5-20 lists the characteristics of the ADC power supply and input range conditions.

Table 5-20. ADC, Power Supply and Input Range Conditions

over operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	V _{CC}	MIN	TYP	MAX	UNIT
DV _{CC}	ADC supply voltage		2.0		3.6	V
V _(Ax)	Analog input voltage range	All ADC pins	0		DV _{CC}	V
I _{ADC}	Operating supply current into DV _{CC} terminal, reference current not included, repeat-single-channel mode	2 V		185		μA
		3 V		207		
C _I	Input capacitance	Only one terminal Ax can be selected at one time from the pad to the ADC capacitor array, including wiring and pad	2.2 V	2.5	3.5	pF
R _I	Input MUX ON resistance	DV _{CC} = 2 V, 0 V ≤ V _{Ax} ≤ DV _{CC}			36	kΩ

Table 5-21 lists the ADC 10-bit timing parameters.

Table 5-21. ADC, 10-Bit Timing Parameters

over operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS	V _{CC}	MIN	TYP	MAX	UNIT
f _{ADCCLK}		For specified performance of ADC linearity parameters	2 V to 3.6 V	0.45	5	5.5	MHz
f _{ADCOSC}	Internal ADC oscillator (MODOSC)	ADCDIV = 0, f _{ADCCLK} = f _{ADCOSC}	2 V to 3.6 V	3.8	4.8	5.8	MHz
t _{CONVERT}	Conversion time	REFON = 0, Internal oscillator, 10 ADCCLK cycles, 10-bit mode, f _{ADCOSC} = 4.5 MHz to 5.5 MHz	2 V to 3.6 V	2.18		2.67	μs
		External f _{ADCCLK} from ACLK, MCLK, or SMCLK, ADCSSEL ≠ 0	2 V to 3.6 V		12 × 1 / f _{ADCCLK}		
t _{ADCON}	Turnon settling time of the ADC	The error in a conversion started after t _{ADCON} is less than ±0.5 LSB. Reference and input signal are already settled.				100	ns
t _{Sample}	Sampling time	R _S = 1000 Ω, R _I = 36000 Ω, C _I = 3.5 pF. Approximately 8 Tau (t) are required for an error of less than ±0.5 LSB. ⁽¹⁾	3 V	2.0			μs

(1) $t_{\text{Sample}} = \ln(2^{n+1}) \times \tau$, where n = ADC resolution, $\tau = (R_I + R_S) \times C_I$

Table 5-22 lists the ADC 10-bit linearity parameters.

Table 5-22. ADC, 10-Bit Linearity Parameters

over operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS	V _{CC}	MIN	TYP	MAX	UNIT
E _I	Integral linearity error (10-bit mode)	V _{REF} + reference	2.4 V to 3.6 V	–2		2	LSB
	Integral linearity error (8-bit mode)		2.0 V to 3.6 V	–2		2	
E _D	Differential linearity error (10-bit mode)	V _{REF} + reference	2.4 V to 3.6 V	–1		1	LSB
	Differential linearity error (8-bit mode)		2.0 V to 3.6 V	–1		1	
E _O	Offset error (10-bit mode)	V _{REF} + reference	2.4 V to 3.6 V	–6.5		6.5	mV
	Offset error (8-bit mode)		2.0 V to 3.6 V	–6.5		6.5	
E _G	Gain error (10-bit mode)	V _{REF} + as reference	2.4 V to 3.6 V	–2.0		2.0	LSB
		Internal 1.5-V reference		–3.0%		3.0%	
	Gain error (8-bit mode)	V _{REF} + as reference	2.0 V to 3.6 V	–2.0		2.0	LSB
		Internal 1.5-V reference		–3.0%		3.0%	
E _T	Total unadjusted error (10-bit mode)	V _{REF} + as reference	2.4 V to 3.6 V	–2.0		2.0	LSB
		Internal 1.5-V reference		–3.0%		3.0%	
	Total unadjusted error (8-bit mode)	V _{REF} + as reference	2.0 V to 3.6 V	–2.0		2.0	LSB
		Internal 1.5-V reference		–3.0%		3.0%	
V _{SENSOR}	See ⁽¹⁾	ADCON = 1, INCH = 0Ch, T _A = 0°C	3 V		913		mV
TC _{SENSOR}	See ⁽²⁾	ADCON = 1, INCH = 0Ch	3 V		3.35		mV/°C
t _{SENSOR} (sample)	Sample time required if channel 12 is selected ⁽³⁾	ADCON = 1, INCH = 0Ch, Error of conversion result ≤1 LSB, AM and all LPMs above LPM3	3 V		30		μs
		ADCON = 1, INCH = 0Ch, Error of conversion result ≤1 LSB, LPM3	3 V		100		

- (1) The temperature sensor offset can vary significantly. TI recommends a single-point calibration to minimize the offset error of the built-in temperature sensor.
- (2) The device descriptor structure contains calibration values for 30°C and 85°C for each available reference voltage level. The sensor voltage can be computed as $V_{SENSE} = TC_{SENSOR} \times (\text{Temperature, } ^\circ\text{C}) + V_{SENSOR}$, where TC_{SENSOR} and V_{SENSOR} can be computed from the calibration values for higher accuracy.
- (3) The typical equivalent impedance of the sensor is 700 kΩ. The sample time required includes the sensor on time, t_{SENSOR(on)}.

5.11.9 FRAM

Table 5-23 lists the characteristics of the FRAM.

Table 5-23. FRAM

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Read and write endurance		10 ¹⁵			cycles
t _{Retention} Data retention duration	T _J = 25°C	100			years
	T _J = 70°C	40			
	T _J = 85°C	10			
I _{WRITE} Current to write into FRAM			I _{READ} ⁽¹⁾		nA
I _{ERASE} Erase current			N/A ⁽²⁾		nA
t _{WRITE} Write time			t _{READ} ⁽³⁾		ns
t _{READ} Read time	NWAITSx = 0		1 / f _{SYSTEM} ⁽⁴⁾		ns
	NWAITSx = 1		2 / f _{SYSTEM} ⁽⁴⁾		

- (1) Writing to FRAM does not require a setup sequence or additional power when compared to reading from FRAM. The FRAM read current I_{READ} is included in the active mode current consumption parameter I_{AM,FRAM}.
- (2) FRAM does not require a special erase sequence.
- (3) Writing into FRAM is as fast as reading.
- (4) The maximum read (and write) speed is specified by f_{SYSTEM} using the appropriate wait state settings (NWAITSx).

5.11.10 Debug and Emulation

Table 5-24 lists the characteristics of the 2-wire SBW interface.

Table 5-24. JTAG, Spy-Bi-Wire Interface

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Figure 5-18)

PARAMETER		V _{CC}	MIN	TYP	MAX	UNIT
f _{SBW}	Spy-Bi-Wire input frequency	2 V, 3 V	0		8	MHz
t _{SBW,Low}	Spy-Bi-Wire low clock pulse duration	2 V, 3 V	0.028		15	μs
t _{SU, SBWTDIO}	SBWTDIO setup time (before falling edge of SBWTCK in TMS and TDI slot, Spy-Bi-Wire)	2 V, 3 V	4			ns
t _{HD, SBWTDIO}	SBWTDIO hold time (after rising edge of SBWTCK in TMS and TDI slot, Spy-Bi-Wire)	2 V, 3 V	19			ns
t _{Valid, SBWTDIO}	SBWTDIO data valid time (after falling edge of SBWTCK in TDO slot, Spy-Bi-Wire)	2 V, 3 V			31	ns
t _{SBW, En}	Spy-Bi-Wire enable time (TEST high to acceptance of first clock edge) ⁽¹⁾	2 V, 3 V			110	μs
t _{SBW,Ret}	Spy-Bi-Wire return to normal operation time ⁽²⁾	2 V, 3 V	15		100	μs
R _{internal}	Internal pulldown resistance on TEST	2 V, 3 V	20	35	50	kΩ

- (1) Tools that access the Spy-Bi-Wire interface must wait for the t_{SBW,En} time after pulling the TEST/SBWTCK pin high before applying the first SBWTCK clock edge.
- (2) Maximum t_{SBW,Ret} time after pulling or releasing the TEST/SBWTCK pin low until the Spy-Bi-Wire pins revert from their Spy-Bi-Wire function to their application function. This time applies only if the Spy-Bi-Wire mode is selected.

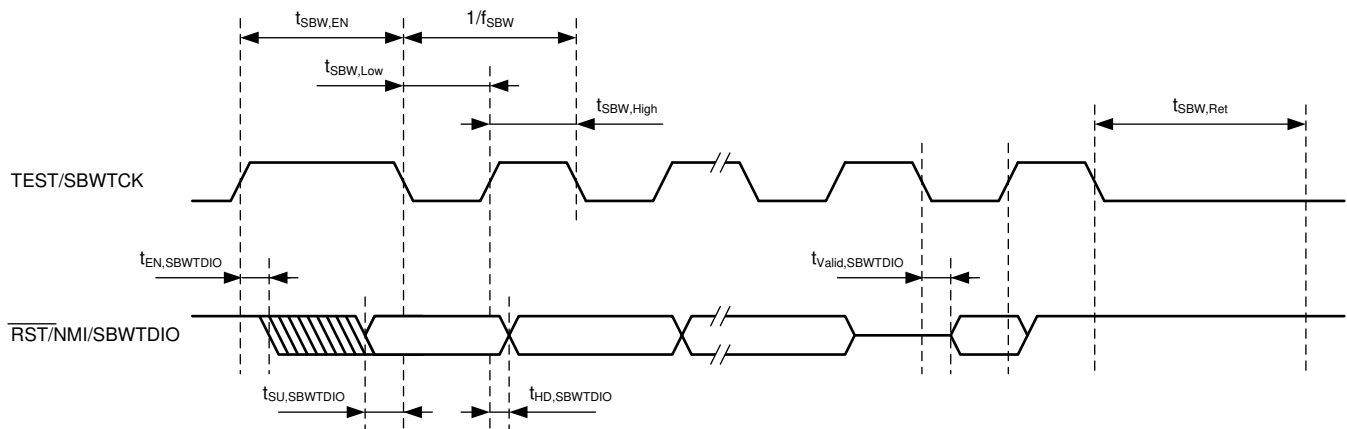


Figure 5-18. JTAG Spy-Bi-Wire Timing

Table 5-25 lists the characteristics of the 4-wire JTAG interface.

Table 5-25. JTAG, 4-Wire Interface

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Figure 5-19)

PARAMETER		V _{CC}	MIN	TYP	MAX	UNIT
f _{TCK}	TCK input frequency ⁽¹⁾	2 V, 3 V	0		10	MHz
t _{TCK,Low}	TCK low clock pulse duration	2 V, 3 V	15			ns
t _{TCK,High}	TCK high clock pulse duration	2 V, 3 V	15			ns
t _{SU,TMS}	TMS setup time (before rising edge of TCK)	2 V, 3 V	11			ns
t _{HD,TMS}	TMS hold time (after rising edge of TCK)	2 V, 3 V	3			ns
t _{SU,TDI}	TDI setup time (before rising edge of TCK)	2 V, 3 V	13			ns
t _{HD,TDI}	TDI hold time (after rising edge of TCK)	2 V, 3 V	5			ns
t _{Z-Valid,TDO}	TDO high impedance to valid output time (after falling edge of TCK)	2 V, 3 V			26	ns
t _{Valid,TDO}	TDO to new valid output time (after falling edge of TCK)	2 V, 3 V			26	ns
t _{Valid-Z,TDO}	TDO valid to high-impedance output time (after falling edge of TCK)	2 V, 3 V			26	ns
t _{JTAG,Ret}	Spy-Bi-Wire return to normal operation time		15		100	μs
R _{internal}	Internal pulldown resistance on TEST	2 V, 3 V	20	35	50	kΩ

(1) f_{TCK} may be restricted to meet the timing requirements of the module selected.

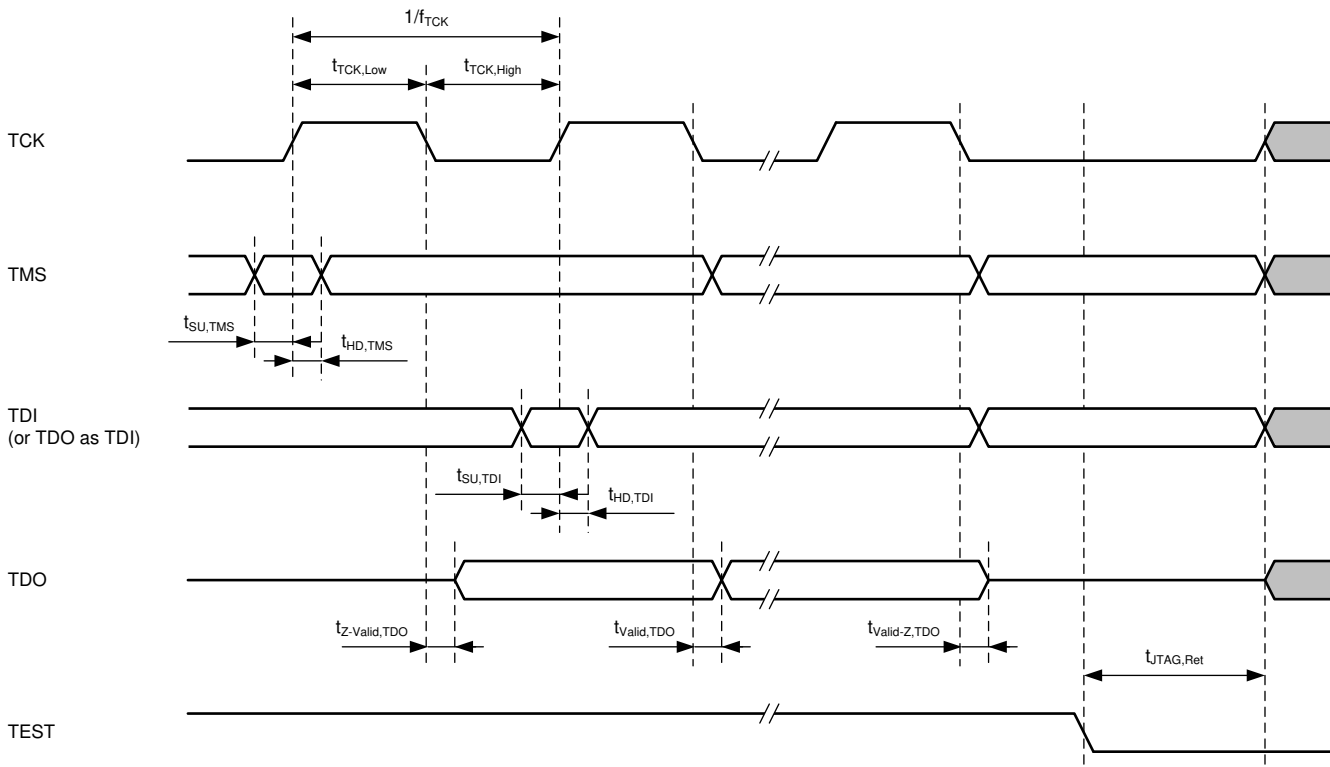


Figure 5-19. JTAG 4-Wire Timing

6 Detailed Description

6.1 Overview

The MSP430FR2422 is an ultra-low-power MCU. The architecture, combined with extensive low-power modes, is optimized to achieve extended battery life in, for example, portable measurement applications. The MCU features two 16-bit timers, two eUSCs that support UART, SPI, and I²C, a hardware multiplier, an RTC module, and a high-performance 10-bit ADC.

6.2 CPU

The MSP430 CPU has a 16-bit RISC architecture that is highly transparent to the application. All operations, other than program-flow instructions, are performed as register operations in conjunction with seven addressing modes for source operand and four addressing modes for destination operand.

The CPU is integrated with 16 registers that provide reduced instruction execution time. The register-to-register operation execution time is one cycle of the CPU clock.

Four of the registers, R0 to R3, are dedicated as program counter (PC), stack pointer (SP), status register (SR), and constant generator (CG), respectively. The remaining registers are general-purpose registers.

Peripherals are connected to the CPU using data, address, and control buses. Peripherals can be handled with all instructions.

6.3 Operating Modes

The MSP430 has one active mode and several software-selectable low-power modes of operation (see [Table 6-1](#)). An interrupt event can wake the MCU from low-power mode LPM0, LPM3 or LPM4, service the request, and restore the MCU back to the low-power mode on return from the interrupt program. Low-power modes LPM3.5 and LPM4.5 disable the core supply to minimize power consumption.

NOTE

XT1CLK and VLOCLK can be active during LPM4 mode if requested by low-frequency peripherals, such as RTC and WDT.

Table 6-1. Operating Modes

MODE		AM	LPM0	LPM3	LPM4	LPM3.5	LPM4.5
		ACTIVE MODE (FRAM ON)	CPU OFF	STANDBY	OFF	ONLY RTC	SHUTDOWN
Maximum system clock		16 MHz	16 MHz	40 kHz	0	40 kHz	0
Power consumption at 25°C, 3 V		126 μ A/MHz	40 μ A/MHz	1.2 μ A with RTC counter only in LFXT	0.49 μ A without SVS	0.73 μ A with RTC counter only in LFXT	16 nA without SVS
Wake-up time		N/A	Instant	10 μ s	10 μ s	350 μ s	350 μ s
Wake-up events		N/A	All	All	I/O	RTC I/O	I/O
Power	Regulator	Full Regulation	Full Regulation	Partial Power Down	Partial Power Down	Partial Power Down	Power Down
	SVS	On	On	Optional	Optional	Optional	Optional
	Brownout	On	On	On	On	On	On
Clock ⁽¹⁾	MCLK	Active	Off	Off	Off	Off	Off
	SMCLK	Optional	Optional	Off	Off	Off	Off
	FLL	Optional	Optional	Off	Off	Off	Off
	DCO	Optional	Optional	Off	Off	Off	Off
	MODCLK	Optional	Optional	Off	Off	Off	Off
	REFO	Optional	Optional	Optional	Off	Off	Off
	ACLK	Optional	Optional	Optional	Off	Off	Off
	XT1CLK	Optional	Optional	Optional	Off	Optional	Off
Core	VLOCLK	Optional	Optional	Optional	Off	Optional	Off
	CPU	On	Off	Off	Off	Off	Off
	FRAM	On	On	Off	Off	Off	Off
	RAM	On	On	On	On	Off	Off
Peripherals	Backup memory ⁽²⁾	On	On	On	On	On	Off
	Timer0_A3	Optional	Optional	Optional	Off	Off	Off
	Timer1_A3	Optional	Optional	Optional	Off	Off	Off
	WDT	Optional	Optional	Optional	Off	Off	Off
	eUSCI_A0	Optional	Optional	Optional	Off	Off	Off
	eUSCI_B0	Optional	Optional	Optional	Off	Off	Off
	CRC	Optional	Optional	Off	Off	Off	Off
	ADC	Optional	Optional	Optional	Off	Off	Off
I/O	RTC	Optional	Optional	Optional	Off	Optional	Off
	General-purpose digital input/output	On	Optional	State Held	State Held	State Held	State Held

(1) The status shown for LPM4 applies to internal clocks only.

(2) Backup memory contains 32 bytes of register space in peripheral memory. See [Table 6-20](#) and [Table 6-35](#) for its memory allocation.

6.4 Interrupt Vector Addresses

The interrupt vectors and the power-up start address are in the address range 0FFFFh to 0FF80h (see [Table 6-2](#)). The vector contains the 16-bit address of the appropriate interrupt-handler instruction sequence.

Table 6-2. Interrupt Sources, Flags, and Vectors

INTERRUPT SOURCE	INTERRUPT FLAG	SYSTEM INTERRUPT	WORD ADDRESS	PRIORITY
System Reset Power up, Brownout, Supply supervisor External reset RST Watchdog time-out, Key violation FRAM uncorrectable bit error detection Software POR, BOR FLL unlock error	SVSHIFG PMMRSTIFG WDTIFG PMMPORIFG, PMMBORIFG SYSRSTIV FLLUNLOCKIFG	Reset	FFFEh	63, Highest
System NMI Vacant memory access JTAG mailbox FRAM access time error FRAM bit error detection	VMAIFG JMBINIFG, JMBOUTIFG CBDIFG, UBDIFG	Nonmaskable	FFFCh	62
User NMI External NMI Oscillator fault	NMIIIFG OFIFG	Nonmaskable	FFFAh	61
Timer0_A3	TA0CCR0 CCIFG0	Maskable	FFF8h	60
Timer0_A3	TA0CCR1 CCIFG1, TA0CCR2 CCIFG2, TA0IFG (TA0IV)	Maskable	FFF6h	59
Timer1_A3	TA1CCR0 CCIFG0	Maskable	FFF4h	58
Timer1_A3	TA1CCR1 CCIFG1, TA1CCR2 CCIFG2, TA1IFG (TA1IV)	Maskable	FFF2h	57
RTC	RTCIFG	Maskable	FFF0h	56
Watchdog timer interval mode	WDTIFG	Maskable	FFEEh	55
eUSCI_A0 receive or transmit	UCTXCPTIFG, UCSTTIFG, UCRXIFG, UCTXIFG (UART mode) UCRXIFG, UCTXIFG (SPI mode) (UCA0IV)	Maskable	FFECCh	54
eUSCI_B0 receive or transmit	UCB0RXIFG, UCB0TXIFG (SPI mode) UCALIFG, UCNACKIFG, UCSTTIFG, UCSTPIFG, UCRXIFG0, UCTXIFG0, UCRXIFG1, UCTXIFG1, UCRXIFG2, UCTXIFG2, UCRXIFG3, UCTXIFG3, UCCNTIFG, UCBIT9IFG (I ² C mode) (UCB0IV)	Maskable	FFEAh	53
ADC	ADCIFG0, ADCINIFG, ADCLOIFG, ADCHIIFG, ADCTOVIFG, ADCOVIFG (ADCIV)	Maskable	FFE8h	52
P1	P1IFG.0 to P1IFG.7 (P1IV)	Maskable	FFE6h	51
P2	P2IFG.0 to P2IFG.6 (P2IV)	Maskable	FFE4h	50
Reserved	Reserved	Maskable	FFE0h–FF88h	

Table 6-3. Signatures

SIGNATURE	WORD ADDRESS
BSL Signature2	0FF86h
BSL Signature1	0FF84h
JTAG Signature2	0FF82h
JTAG Signature1	0FF80h

6.5 Bootloader (BSL)

The BSL lets users program the FRAM or RAM using either the UART serial interface or the I²C interface. Access to the MCU memory through the BSL is protected by a user-defined password. Use of the BSL requires four pins (see [Table 6-4](#) and [Table 6-5](#)). The BSL entry requires a specific entry sequence on the $\overline{\text{RST}}/\text{NMI}/\text{SBWTDIO}$ and $\text{TEST}/\text{SBWTCK}$ pins. This device can support the blank device detection automatically to invoke the BSL with bypass this special entry sequence for saving time and on board programmable. For the complete description of the feature of the BSL, see the [MSP430 FRAM Device Bootloader \(BSL\) User's Guide](#).

Table 6-4. UART BSL Pin Requirements and Functions

DEVICE SIGNAL	BSL FUNCTION
$\overline{\text{RST}}/\text{NMI}/\text{SBWTDIO}$	Entry sequence signal
$\text{TEST}/\text{SBWTCK}$	Entry sequence signal
P1.4	Data transmit
P1.5	Data receive
DVCC	Power supply
DVSS	Ground supply

Table 6-5. I²C BSL Pin Requirements and Functions

DEVICE SIGNAL	BSL FUNCTION
$\overline{\text{RST}}/\text{NMI}/\text{SBWTDIO}$	Entry sequence signal
$\text{TEST}/\text{SBWTCK}$	Entry sequence signal
P1.2	Data transmit and receive
P1.3	Clock
DVCC	Power supply
DVSS	Ground supply

6.6 JTAG Standard Interface

The MSP low-power microcontrollers support the standard JTAG interface, which requires four signals for sending and receiving data. The JTAG signals are shared with general-purpose I/O. The $\text{TEST}/\text{SBWTCK}$ pin enables the JTAG signals. In addition to these signals, the $\overline{\text{RST}}/\text{NMI}/\text{SBWTDIO}$ is required to interface with MSP430 development tools and device programmers. [Table 6-6](#) lists the JTAG pin requirements. For further details on interfacing to development tools and device programmers, see the [MSP430 Hardware Tools User's Guide](#). For details on using the JTAG interface, see [MSP430 Programming With the JTAG Interface](#).

Table 6-6. JTAG Pin Requirements and Function

DEVICE SIGNAL	DIRECTION	JTAG FUNCTION
P1.4/.../TCK	IN	JTAG clock input
P1.5/.../TMS	IN	JTAG state control
P1.6/.../TDI/TCLK	IN	JTAG data input, TCLK input
P1.7/.../TDO	OUT	JTAG data output
$\text{TEST}/\text{SBWTCK}$	IN	Enable JTAG pins
$\overline{\text{RST}}/\text{NMI}/\text{SBWTDIO}$	IN	External reset
DVCC	–	Power supply
DVSS	–	Ground supply

6.7 Spy-Bi-Wire Interface (SBW)

The MSP low-power microcontrollers support the 2-wire SBW interface. SBW can be used to interface with MSP development tools and device programmers. [Table 6-7](#) lists the SBW interface pin requirements. For further details on interfacing to development tools and device programmers, see the [MSP430 Hardware Tools User's Guide](#). For details on using the SBW interface, see the [MSP430 Programming With the JTAG Interface](#).

Table 6-7. Spy-Bi-Wire Pin Requirements and Functions

DEVICE SIGNAL	DIRECTION	SBW FUNCTION
TEST/SBWTCK	IN	Spy-Bi-Wire clock input
$\overline{\text{RST}}/\text{NMI}/\text{SBWTDIO}$	IN, OUT	Spy-Bi-Wire data input and output
DVCC	–	Power supply
DVSS	–	Ground supply

6.8 FRAM

The FRAM can be programmed using the JTAG port, SBW, the BSL, or in-system by the CPU. Features of the FRAM include:

- Byte and word access capability
- Programmable wait state generation
- Error correction coding (ECC)

6.9 Memory Protection

The device features memory protection for user access authority and write protection, including options to:

- Secure the whole memory map to prevent unauthorized access from JTAG port or BSL, by writing JTAG and BSL signatures using the JTAG port, SBW, the BSL, or in-system by the CPU.
- Enable write protection to prevent unwanted write operation to FRAM contents by setting the control bits in the System Configuration 0 register. For detailed information, see the SYS chapter in the [MP430FR4xx and MP430FR2xx Family User's Guide](#).

6.10 Peripherals

Peripherals are connected to the CPU through data, address, and control buses. All peripherals can be handled by using all instructions in the memory map. For complete module description, see the [MP430FR4xx and MP430FR2xx Family User's Guide](#).

6.10.1 Power-Management Module (PMM)

The PMM includes an integrated voltage regulator that supplies the core voltage to the device. The PMM also includes supply voltage supervisor (SVS) and brownout protection. The brownout reset circuit (BOR) is implemented to provide the proper internal reset signal to the device during power on and power off. The SVS circuitry detects if the supply voltage drops below a user-selectable safe level. SVS circuitry is available on the primary supply.

The device contains two on-chip reference: 1.5 V for internal reference and 1.2 V for external reference.

The 1.5-V reference is internally connected to ADC channel 13. DVCC is internally connected to ADC channel 15. When DVCC is set as the reference voltage for ADC conversion, the DVCC can be easily represent as [Equation 1](#) by using ADC sampling 1.5-V reference without any external components support.

$$\text{DVCC} = (1023 \times 1.5 \text{ V}) \div 1.5\text{-V reference ADC result} \quad (1)$$

A 1.2-V reference voltage can be buffered, when EXTREFEN = 1 on PMMCTL2 register, and it can be output to P1.1/./A1/VREF+ , meanwhile the ADC channel 1 can also be selected to monitor this voltage. For more detailed information, see the [MSP430FR4xx and MSP430FR2xx Family User's Guide](#).

6.10.2 Clock System (CS) and Clock Distribution

The clock system includes a 32-kHz crystal oscillator (XT1), an internal very-low-power low-frequency oscillator (VLO), an integrated 32-kHz RC oscillator (REFO), an integrated internal digitally controlled oscillator (DCO) that may use frequency-locked loop (FLL) locking with internal or external 32-kHz reference clock, and an on-chip asynchronous high-speed clock (MODOSC). The clock system is designed for cost-effective designs with minimal external components. A fail-safe mechanism is included for XT1. The clock system module offers the following clock signals.

- **Main Clock (MCLK):** The system clock used by the CPU and all relevant peripherals accessed by the bus. All clock sources except MODOSC can be selected as the source with a predivider of 1, 2, 4, 8, 16, 32, 64, or 128.
- **Sub-Main Clock (SMCLK):** The subsystem clock used by the peripheral modules. SMCLK derives from the MCLK with a predivider of 1, 2, 4, or 8. This means SMCLK is always equal to or less than MCLK.
- **Auxiliary Clock (ACLK):** This clock is derived from the external XT1 clock or internal REFO clock up to 40 kHz.

All peripherals may have one or several clock sources depending on specific functionality. [Table 6-8](#) lists the clock distribution used in this device.

Table 6-8. Clock Distribution

	CLOCK SOURCE SELECT BITS	MCLK	SMCLK	ACLK	MODCLK	XT1CLK	VLOCLK	EXTERNAL PIN
Frequency Range		DC to 16 MHz	DC to 16 MHz	DC to 40 kHz	5 MHz ±10%	DC to 40 kHz	10 kHz ±50%	–
CPU	N/A	Default	–	–	–	–	–	–
FRAM	N/A	Default	–	–	–	–	–	–
RAM	N/A	Default	–	–	–	–	–	–
CRC	N/A	Default	–	–	–	–	–	–
I/O	N/A	Default	–	–	–	–	–	–
TA0	TASSEL	–	10b	01b	–	–	11b	00b (TA0CLK pin)
TA1	TASSEL	–	10b	01b	–	–	–	00b (TA1CLK pin)
eUSCI_A0	UCSSEL	–	10b or 11b	01b	–	–	–	00b (UCA0CLK pin)
eUSCI_B0	UCSSEL	–	10b or 11b	01b	–	–	–	00b (UCB0CLK pin)
WDT	WDTSSEL	–	00b	01b	–	–	10b	–
ADC	ADCSSEL	–	10b or 11b	01b	00b	–	–	–
RTC	RTCSS	–	01b ⁽¹⁾	01b ⁽¹⁾	–	10b	11b	–

(1) Controlled by the RTCCKSEL bit in the SYSCFG2 register

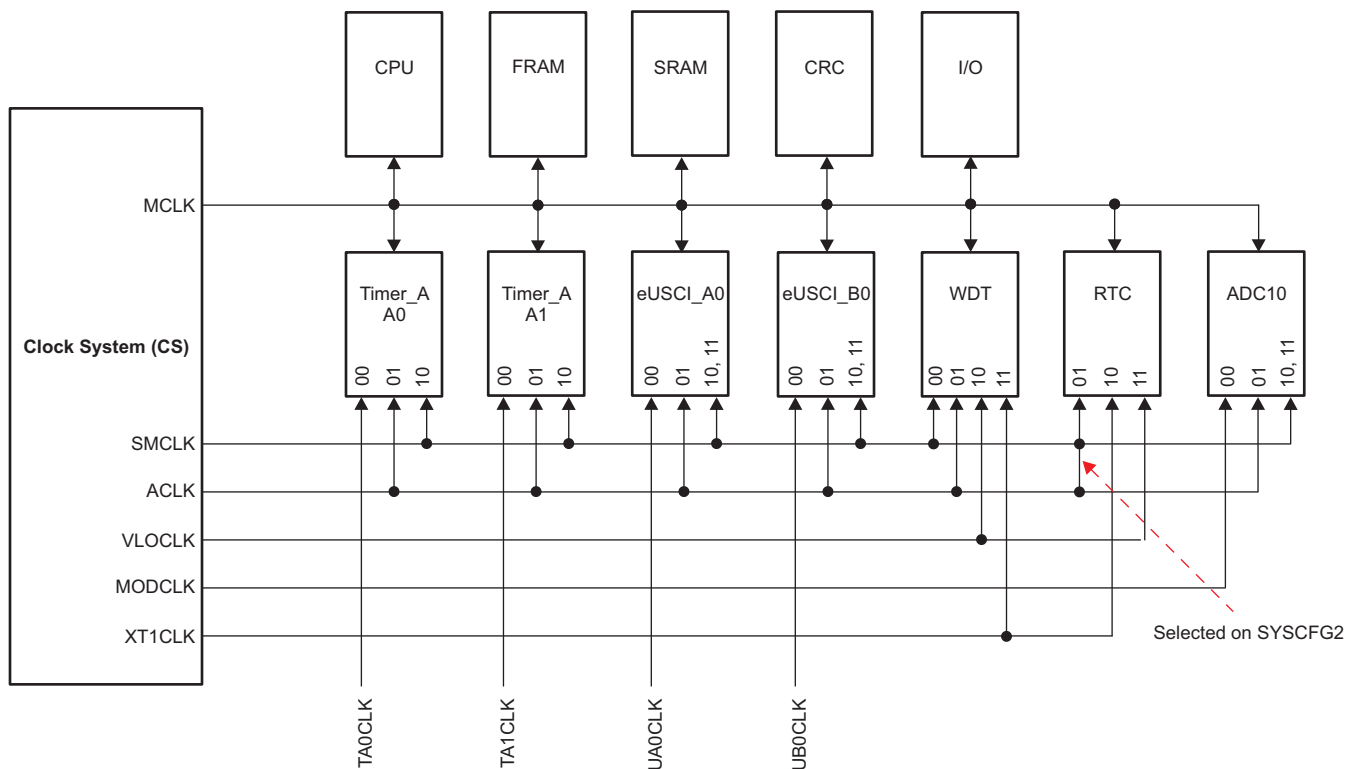


Figure 6-1. Clock Distribution Block Diagram

6.10.3 General-Purpose Input/Output Port (I/O)

Up to 15 I/O ports are implemented.

- P1 implements 8 bits, and P2 implements 7 bits.
- All individual I/O bits are independently programmable.
- Any combination of input, output, and interrupt conditions is possible.
- Programmable pullup or pulldown on all ports.
- Edge-selectable interrupt and LPMx.5 wake-up input capability are available for P1 and P2.
- Read and write access to port-control registers is supported by all instructions.
- Ports can be accessed byte-wise or word-wise as a pair.

NOTE

Configuration of digital I/Os after BOR reset

To prevent any cross currents during start-up of the device, all port pins are high-impedance with Schmitt triggers and module functions disabled. To enable the I/O functions after a BOR reset, the ports must be configured first and then the LOCKLPM5 bit must be cleared. For details, see the *Configuration After Reset* section in the Digital I/O chapter of the [MP430FR4xx and MP430FR2xx Family User's Guide](#).

6.10.4 Watchdog Timer (WDT)

The primary function of the WDT module is to perform a controlled system restart after a software problem occurs. If the selected time interval expires, a system reset is generated. If the watchdog function is not needed in an application, the module can be configured as an interval timer and can generate interrupts at selected time intervals. [Table 6-9](#) lists the system clocks that can be used to source the WDT.

Table 6-9. WDT Clocks

WDTSEL	NORMAL OPERATION (WATCHDOG AND INTERVAL TIMER MODE)
00	SMCLK
01	ACLK
10	VLOCLK
11	Reserved

6.10.5 System (SYS) Module

The SYS module handles many of the system functions within the device. These features include power-on reset (POR) and power-up clear (PUC) handling, NMI source selection and management, reset interrupt vector generators, bootloader entry mechanisms, and configuration management (device descriptors). The SYS module also includes a data exchange mechanism through SBW called a JTAG mailbox mail box that can be used in the application. [Table 6-10](#) summarizes the interrupts that are managed by the SYS module.

Table 6-10. System Module Interrupt Vector Registers

INTERRUPT VECTOR REGISTER	ADDRESS	INTERRUPT EVENT	VALUE	PRIORITY
SYSRSTIV, System Reset	015Eh	No interrupt pending	00h	
		Brownout (BOR)	02h	Highest
		RSTIFG $\overline{\text{RST}}$ /NMI (BOR)	04h	
		PMMSWBOR software BOR (BOR)	06h	
		LPMx.5 wakeup (BOR)	08h	
		Security violation (BOR)	0Ah	
		Reserved	0Ch	
		SVSHIFG SVSH event (BOR)	0Eh	
		Reserved	10h	
		Reserved	12h	
		PMMSWPOR software POR (POR)	14h	
		WDTIFG watchdog time-out (PUC)	16h	
		WDTPW password violation (PUC)	18h	
		FRCTLPW password violation (PUC)	1Ah	
		Uncorrectable FRAM bit error detection	1Ch	
		Peripheral area fetch (PUC)	1Eh	
		PMMPW PMM password violation (PUC)	20h	
		FLL unlock (PUC)	24h	
		Reserved	22h, 26h to 3Eh	Lowest
SYSSNIV, System NMI	015Ch	No interrupt pending	00h	
		SVS low-power reset entry	02h	Highest
		Uncorrectable FRAM bit error detection	04h	
		Reserved	06h	
		Reserved	08h	
		Reserved	0Ah	
		Reserved	0Ch	
		Reserved	0Eh	
		Reserved	10h	
		VMAIFG vacant memory access	12h	
		JMBINIFG JTAG mailbox input	14h	
		JMBOUTIFG JTAG mailbox output	16h	
		Correctable FRAM bit error detection	18h	
		Reserved	1Ah to 1Eh	Lowest
SYSUNIV, User NMI	015Ah	No interrupt pending	00h	
		NMIIFG NMI pin or SVS _H event	02h	Highest
		OFIFG oscillator fault	04h	
		Reserved	06h to 1Eh	Lowest

6.10.6 Cyclic Redundancy Check (CRC)

The 16-bit cyclic redundancy check (CRC) module produces a signature based on a sequence of data values and can be used for data checking purposes. The CRC generation polynomial is compliant with CRC-16-CCITT standard of $x^{16} + x^{12} + x^5 + 1$.

6.10.7 Enhanced Universal Serial Communication Interface (eUSCI_A0, eUSCI_B0)

The eUSCI modules are used for serial data communications. The eUSCI_A module supports either UART or SPI communications. The eUSCI_B module supports either SPI or I²C communications. Additionally, eUSCI_A supports automatic baud-rate detection and IrDA. The eUSCI_A and eUSCI_B are connected either from P1 port or P2 port, it can be selected from the USCIARMP of SYSCFG3 or USCIBRMP bit of SYSCFG2. [Table 6-11](#) lists the pin configurations that are required for each eUSCI mode.

Table 6-11. eUSCI Pin Configurations

eUSCI_A0	PIN (USCIARMP = 0)	UART	SPI
	P1.4	TXD	SIMO
	P1.5	RXD	SOMI
	P1.6	–	SCLK
	P1.7	–	STE
	PIN (USCIARMP = 1)	UART	SPI
	P2.0	TXD	SIMO
	P2.1	RXD	SOMI
	P1.6	–	SCLK
	P1.7	–	STE
eUSCI_B0	PIN (USCIBRMP = 0)	I ² C	SPI
	P1.0	–	STE
	P1.1	–	SCLK
	P1.2	SDA	SIMO
	P1.3	SCL	SOMI
	PIN (USCIBRMP = 1)	I ² C	SPI
	P2.3	–	STE
	P2.4	–	SCLK
	P2.5	SDA	SIMO
	P2.6	SCL	SOMI

6.10.8 Timers (Timer0_A3, Timer1_A3)

The Timer0_A3 and Timer1_A3 modules are 16-bit timers and counters with three capture/compare registers each. Each timer supports multiple captures or compares, PWM outputs, and interval timing (see Figure 6-2). Each timer has extensive interrupt capabilities. Interrupts may be generated from the counter on overflow conditions and from each of the capture/compare registers. The CCR0 registers on both Timer0_A3 and Timer1_A3 are not externally connected and can only be used for hardware period timing and interrupt generation. In Up mode, they can be used to set the overflow value of the counter.

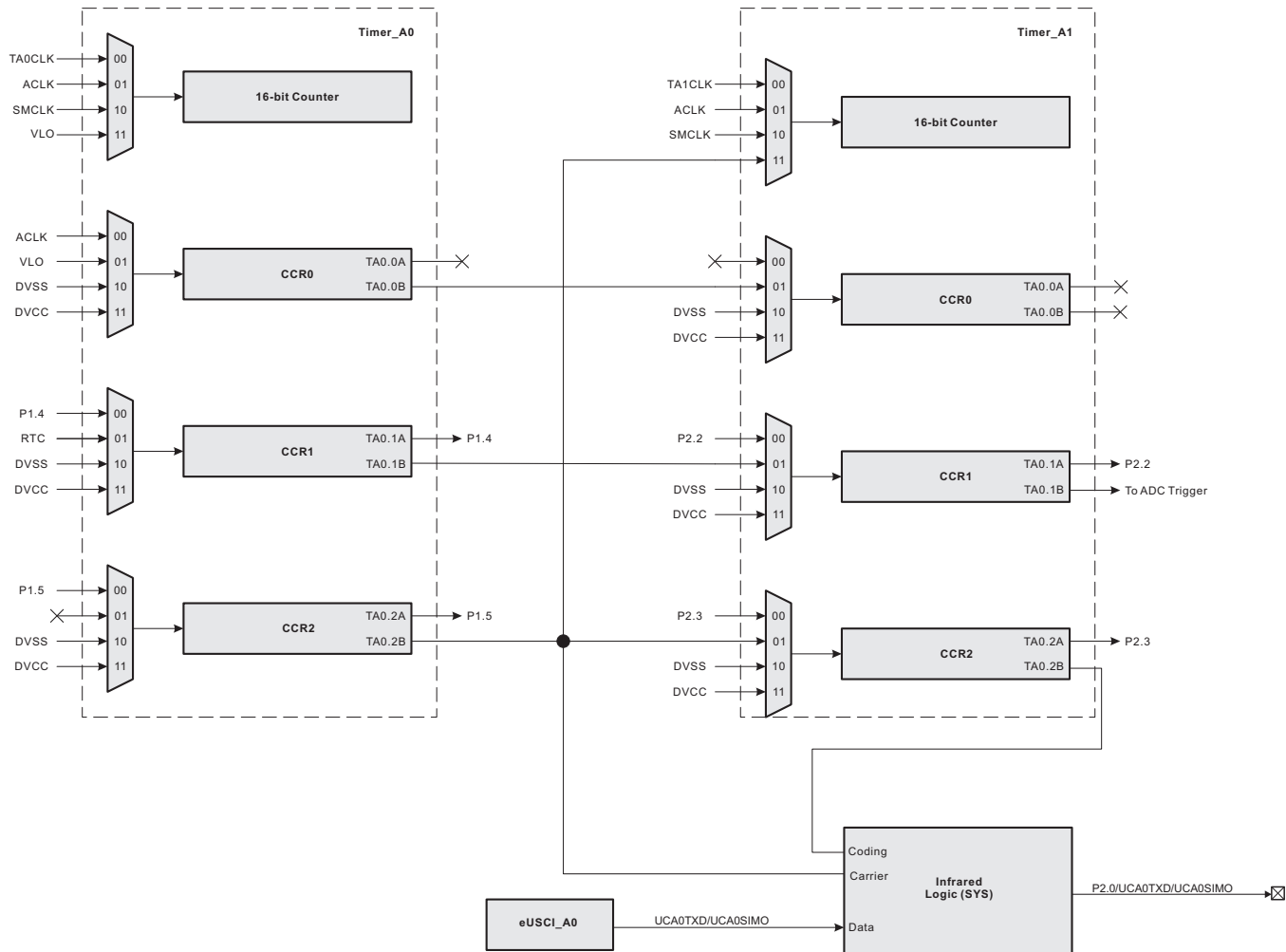


Figure 6-2. Timer0_A3 and Timer1_A3 Signal Connections

The interconnection of Timer0_A3 and Timer1_A3 can be used to modulate the eUSCI_A pin of UCA0TXD/UCA0SIMO in either ASK or FSK mode, with which a user can easily acquire a modulated infrared command for directly driving an external IR diode. The IR functions are fully controlled by SYS configuration registers 1 including IREN (enable), IRPSEL (polarity select), IRMSEL (mode select), IRDSSEL (data select), and IRDATA (data) bits. For more information, see the SYS chapter in the [MP430FR4xx and MP430FR2xx Family User's Guide](#).

6.10.9 Hardware Multiplier (MPY)

The multiplication operation is supported by a dedicated peripheral module. The module performs operations with 32-, 24-, 16-, and 8-bit operands. The MPY module supports signed multiplication, unsigned multiplication, signed multiply-and-accumulate, and unsigned multiply-and-accumulate operations.

6.10.10 Backup Memory (BAKMEM)

The BAKMEM supports data retention during LPM3.5. This device provides up to 32 bytes that are retained during LPM3.5.

6.10.11 Real-Time Clock (RTC)

The RTC is a 16-bit modulo counter that is functional in AM, LPM0, LPM3, and LPM3.5. This module can periodically wake up the CPU from LPM0, LPM3, or LPM3.5 based on timing from a low-power clock source such as the XT1 and VLO clocks. RTC also can be sourced from ACLK controlled by RTCCLK in SYSCFG2. In AM, RTC can be driven by SMCLK to generate high-frequency timing events and interrupts. The RTC overflow events trigger:

- Timer0_B3 CCI1B
- ADC conversion trigger when ADCSHSx bits are set as 01b

Table 6-12. RTC Clock Source

RTCSS	CLOCK SOURCE
00	Reserved
01	SMCLK or ACLK is selected ⁽¹⁾
10	XT1CLK
11	VLOCLK

(1) Controlled by the RTCCLK bit of the SYSCFG2 register

6.10.12 10-Bit Analog-to-Digital Converter (ADC)

The 10-bit ADC module supports fast 10-bit analog-to-digital conversions with single-ended input. The module implements a 10-bit SAR core, sample select control, a reference generator, and a conversion result buffer. A window comparator with lower and upper limits allows CPU-independent result monitoring with three window comparator interrupt flags.

The ADC supports 10 external inputs and 4 internal inputs (see [Table 6-13](#)).

Table 6-13. ADC Channel Connections

ADCINCHx	ADC CHANNELS	EXTERNAL PIN
0	A0/Vref+	P1.0
1	A1 ⁽¹⁾	P1.1
2	A2/Vref-	P1.2
3	A3	P1.3
4	A4	P2.2
5	A5	P2.3
6	A6	P2.4
7	A7	P2.5
8	Not used	N/A
9	Not used	N/A
10	Not used	N/A
11	Not used	N/A
12	On-chip temperature sensor	N/A
13	Reference voltage (1.5 V)	N/A

(1) When A7 is used, the PMM 1.2-V reference voltage can be output to this pin by setting the PMM control register. The 1.2-V voltage can be measured by the A1 channel.

Table 6-13. ADC Channel Connections (continued)

ADCINCHx	ADC CHANNELS	EXTERNAL PIN
14	DVSS	N/A
15	DVCC	N/A

The analog-to-digital conversion can be started by software or a hardware trigger. [Table 6-14](#) lists the trigger sources that are available.

Table 6-14. ADC Trigger Signal Connections

ADCSHSx		TRIGGER SOURCE
BINARY	DECIMAL	
00	0	ADCSC bit (software trigger)
01	1	RTC event
10	2	TA1.1B
11	3	Reserved

6.10.13 Embedded Emulation Module (EEM)

The EEM supports real-time in-system debugging. The EEM on these devices has the following features:

- Three hardware triggers or breakpoints on memory access
- One hardware trigger or breakpoint on CPU register write access
- Up to four hardware triggers can be combined to form complex triggers or breakpoints
- One cycle counter
- Clock control on module level
- EEM version: S

6.11 Input/Output Diagrams

6.11.1 Port P1 (P1.0 to P1.7) Input/Output With Schmitt Trigger

Figure 6-3 shows the port diagram. Table 6-15 summarizes the selection of pin function.

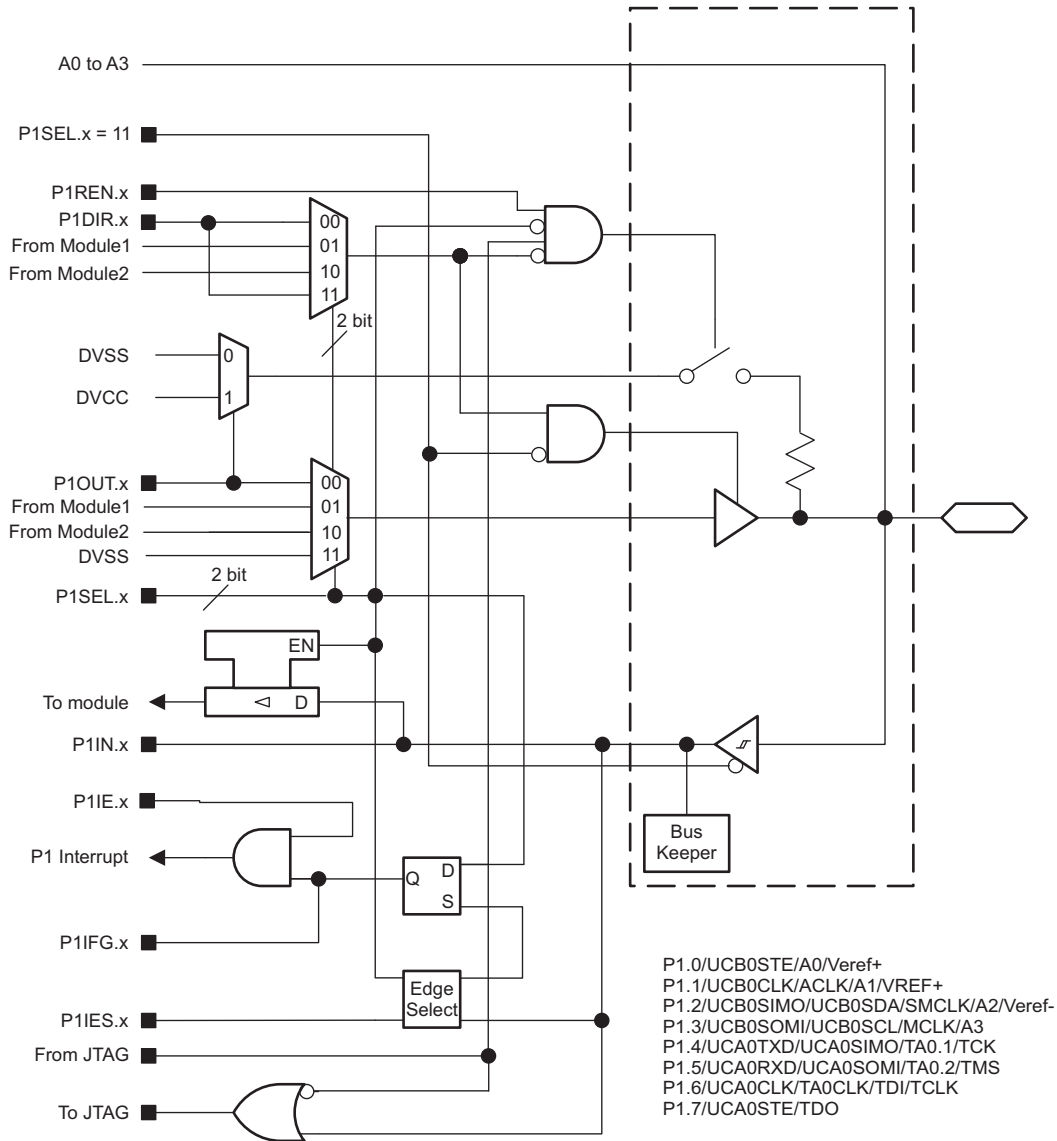


Figure 6-3. Port P1 (P1.0 to P1.7) Input/Output With Schmitt Trigger

Table 6-15. Port P1 (P1.0 to P1.7) Pin Functions

PIN NAME (P1.x)	x	FUNCTION	CONTROL BITS AND SIGNALS ⁽¹⁾			
			P1DIR.x	P1SELx	ANALOG FUNCTION ⁽²⁾	JTAG
P1.0/UCB0STE/A0/Veref+	0	P1.0 (I/O)	I: 0; O: 1	00	0	0
		UCB0STE	X	01	0	0
		A0,Veref+	X	ADCPCTLx = 1 (x = 0) from SYSCFG2		N/A
P1.1/UCB0CLK/ACLK/A1/VREF+	1	P1.1 (I/O)	I: 0; O: 1	00	0	0
		UCB0CLK	X	01	0	0
		ACLK	1	10	0	0
		A1,VREF+	X	ADCPCTLx = 1 (x = 1) from SYSCFG2		N/A
P1.2/UCB0SIMO/UCB0SDA/SMCLK/A2/Veref-	2	P1.2 (I/O)	I: 0; O: 1	00	0	0
		UCB0SIMO/UCB0SDA	X	01	0	0
		SMCLK	1	10	0	0
		A2, Veref-	X	ADCPCTLx = 1 (x = 2) from SYSCFG2		N/A
P1.3/UCB0SOMI/UCB0SCL/MCLK/A3	3	P1.3 (I/O)	I: 0; O: 1	00	0	0
		UCB0SOMI/UCB0SCL	X	01	0	0
		MCLK	1	10	0	0
		A3	X	ADCPCTLx = 1 (x = 3) from SYSCFG2		N/A
P1.4/UCA0TXD/UCA0SIMO/TA0.1/TCK	4	P1.4 (I/O)	I: 0; O: 1	00	0	Disabled
		UCA0TXD/UCA0SIMO	X	01	0	Disabled
		TA0.CCI1A	0	10	0	Disabled
		TA0.1	1			
		JTAG TCK	X	X	X	TCK
P1.5/UCA0RXD/UCA0SOMI/TA0.2/TMS	5	P1.5 (I/O)	I: 0; O: 1	00	0	Disabled
		UCA0RXD/UCA0SOMI	X	01	0	Disabled
		TA0.CCI2A	0	10	0	Disabled
		TA0.2	1			
		JTAG TMS	X	X	X	TMS
P1.6/UCA0CLK/TA0CLK/TDI/TCLK	6	P1.6 (I/O)	I: 0; O: 1	00	0	Disabled
		UCA0CLK	X	01	0	Disabled
		TA0CLK	0	10	0	Disabled
		JTAG TDI/TCLK	X	X	X	TDI/TCLK
P1.7/UCA0STE/TDO	7	P1.7 (I/O)	I: 0; O: 1	00	0	Disabled
		UCA0STE	X	01	0	Disabled
		JTAG TDO	X	X	X	TDO

(1) X = don't care

(2) Setting the bits disables both the output driver and input Schmitt trigger to prevent leakage when analog signals are applied.

6.11.2 Port P2 (P2.0 to P2.6) Input/Output With Schmitt Trigger

Figure 6-4 shows the port diagram. Table 6-16 summarizes the selection of pin function.

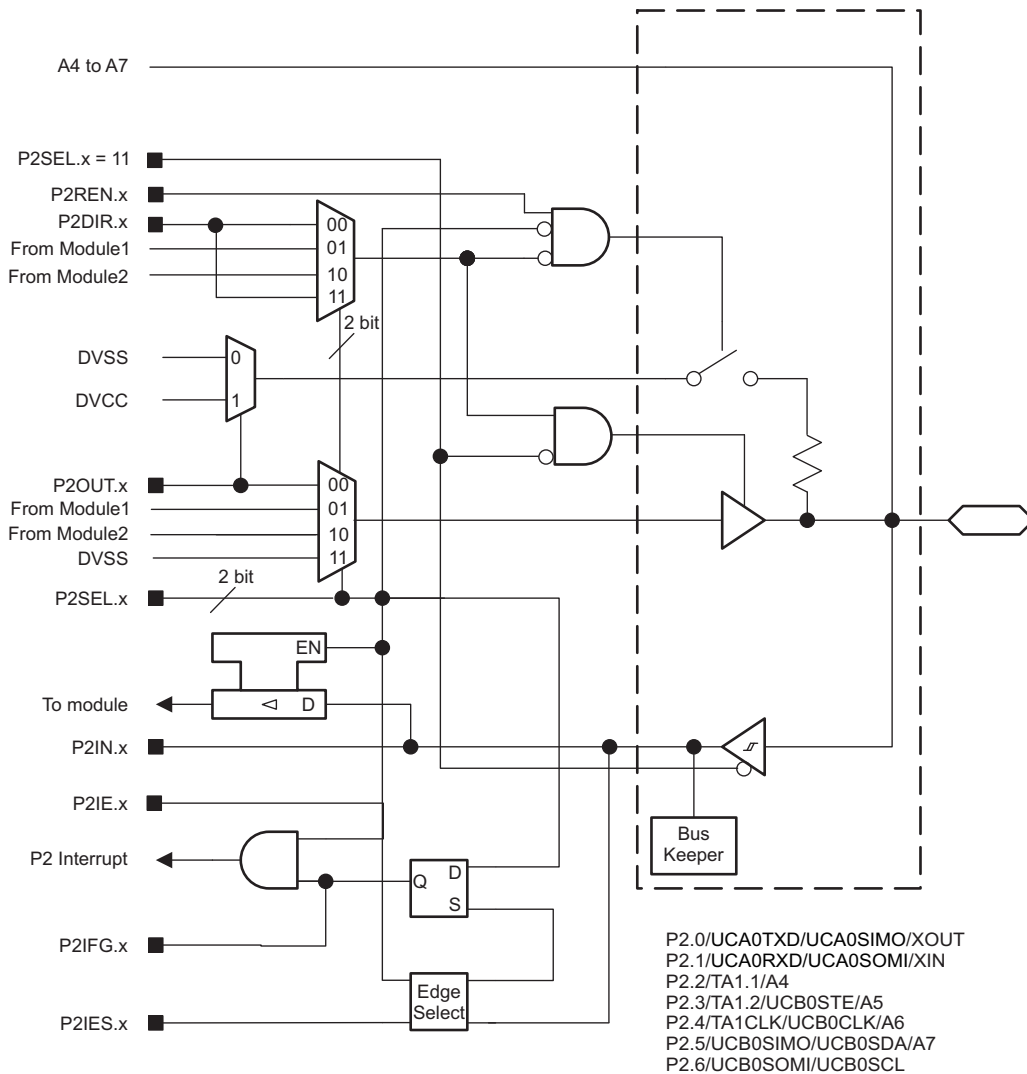


Figure 6-4. Port P2 (P2.0 to P2.6) Input/Output With Schmitt Trigger

Table 6-16. Port P2 (P2.0 to P2.6) Pin Functions

PIN NAME (P2.x)	x	FUNCTION	CONTROL BITS AND SIGNALS ⁽¹⁾		
			P2DIR.x	P2SELx	ANALOG FUNCTION ⁽²⁾
P2.0/UCA0TXD/ UCA0SIMO/XOUT	0	P2.0 (I/O)	I: 0; O: 1	00	0
		UCA0TXD/UCA0SIMO	X	01	0
		XOUT	X	10	0
P2.1/UCA0RXD/ UCA0SOMI/XIN	1	P2.1 (I/O)	I: 0; O: 1	00	0
		UCA0RXD/UCA0SOMI	X	01	0
		XIN	X	10	0
P2.2/TA1.1/A4	2	P2.2 (I/O)	I: 0; O: 1	00	0
		TA1.CCI1A	0	01	0
		TA1.1	1		
		A4	X	X	ADCPCTLx = 1 (x = 4) from SYSCFG2 ⁽²⁾
P2.3/TA1.2/ UCB0STE/A5	3	P2.3 (I/O)	I: 0; O: 1	00	0
		TA1.CCI2A	0	01	0
		TA1.2	1		
		UCB0STE	X	10	0
		A5	X	X	ADCPCTLx = 1 (x = 5) from SYSCFG2 ⁽²⁾
P2.4/TA1CLK/ UCB0CLK/A6	4	P2.4 (I/O)	I: 0; O: 1	00	0
		TA1CLK	0	01	0
		UCB0CLK	X	10	0
		A6	X	X	ADCPCTLx = 1 (x = 6) from SYSCFG2 ⁽²⁾
P2.5/UCB0SIMO/ UCB0SDA/A7	5	P2.5 (I/O)	I: 0; O: 1	00	0
		UCB0SIMO/UCB0SDA	X	10	0
		A7	X	X	ADCPCTLx = 1 (x = 7) from SYSCFG2 ⁽²⁾
P2.6/UCB0SOMI/ UCB0SCL	6	P2.6 (I/O)	I: 0; O: 1	00	0
		UCB0SOMI/UCB0SCL	X	10	0

(1) X = don't care

(2) Setting the bits disables both the output driver and input Schmitt trigger to prevent leakage when analog signals are applied.

6.12 Device Descriptors

Table 6-17 lists the Device IDs of the devices. Table 6-18 lists the contents of the device descriptor tag-length-value (TLV) structure for the devices.

Table 6-17. Device IDs

DEVICE	DEVICE ID	
	1A05h	1A04h
MSP430FR2422	83h	11h

Table 6-18. Device Descriptors

DESCRIPTION		MSP430FR2422	
		ADDRESS	VALUE
Information Block	Info length	1A00h	06h
	CRC length	1A01h	06h
	CRC value ⁽¹⁾	1A02h	Per unit
		1A03h	Per unit
	Device ID	1A04h	See Table 6-17.
		1A05h	
	Hardware revision	1A06h	Per unit
Die Record	Firmware revision	1A07h	Per unit
	Die record tag	1A08h	08h
	Die record length	1A09h	0Ah
	Lot wafer ID	1A0Ah	Per unit
		1A0Bh	Per unit
		1A0Ch	Per unit
		1A0Dh	Per unit
	Die X position	1A0Eh	Per unit
		1A0Fh	Per unit
	Die Y position	1A10h	Per unit
		1A11h	Per unit
	Test result	1A12h	Per unit
		1A13h	Per unit
ADC calibration	ADC calibration tag	1A14h	Per unit
	ADC calibration length	1A15h	Per unit
	ADC gain factor	1A16h	Per unit
		1A17h	Per unit
	ADC offset	1A18h	Per unit
		1A19h	Per unit
	ADC 1.5-V reference, temperature 30°C	1A1Ah	Per unit
		1A1Bh	Per unit
	ADC 1.5-V reference, temperature 85°C	1A1Ch	Per unit
		1A1Dh	Per unit

(1) The CRC value covers the check sum from 0x1A04h to 0x1AF5h by applying the CRC-CCITT-16 polynomial of $x^{16} + x^{12} + x^5 + 1$.

Table 6-18. Device Descriptors (continued)

DESCRIPTION		MSP430FR2422	
		ADDRESS	VALUE
Reference and DCO Calibration	Calibration tag	1A1Eh	12h
	Calibration length	1A1Fh	04h
	1.5-V reference factor	1A20h	Per unit
		1A21h	Per unit
		1A22h	Per unit
	DCO tap setting for 16 MHz, temperature 30°C ⁽²⁾	1A23h	Per unit

- (2) This value can be directly loaded into DCO bits in CSCTL0 registers to get accurate 16-MHz frequency at room temperature, especially when the MCU exits from LPM3 and below. TI suggests using the predivider to decrease the frequency if the temperature drift might result an overshoot beyond 16 MHz.

6.13 Memory

6.13.1 Memory Organization

Table 6-19 summarizes the memory organization of the devices.

Table 6-19. Memory Organization

	ACCESS	MSP430FR2422
Memory (FRAM) Main: interrupt vectors and signatures Main: code memory	Read/Write (Optional Write Protect) ⁽¹⁾	7.25KB FFFFh to FF80h FFFFh to E300h
RAM	Read/Write	2KB 27FFh to 2000h
Information Memory (FRAM)	Read/Write (Optional Write Protect) ⁽²⁾	256B 18FFh to 1800h
Bootloader (BSL1) Memory (ROM)	Read only	2KB 17FFh to 1000h
Bootloader (BSL2) Memory (ROM)	Read only	1KB FFFFh to FFC00h
Peripherals	Read/Write	4KB 0FFFh to 0000h

- (1) The Program FRAM can be write protected by setting PFWP bit in SYSCFG0 register. See the SYS chapter in the [MP430FR4xx and MP430FR2xx Family User's Guide](#) for more details
- (2) The Information FRAM can be write protected by setting DFWP bit in SYSCFG0 register. See the SYS chapter in the [MP430FR4xx and MP430FR2xx Family User's Guide](#) for more details

6.13.2 Peripheral File Map

Table 6-20 lists the available peripherals and the register base address for each.

Table 6-20. Peripherals Summary

MODULE NAME	BASE ADDRESS	SIZE
Special Functions (See Table 6-21)	0100h	0010h
PMM (See Table 6-22)	0120h	0020h
SYS (See Table 6-23)	0140h	0040h
CS (See Table 6-24)	0180h	0020h
FRAM (See Table 6-25)	01A0h	0010h
CRC (See Table 6-26)	01C0h	0008h
WDT (See Table 6-27)	01CCh	0002h
Port P1, P2 (See Table 6-28)	0200h	0020h
RTC (See Table 6-29)	0300h	0010h
Timer0_A3 (See Table 6-30)	0380h	0030h
Timer1_A3 (See Table 6-31)	03C0h	0030h
MPY32 (See Table 6-32)	04C0h	0030h
eUSCI_A0 (See Table 6-33)	0500h	0020h
eUSCI_B0 (See Table 6-34)	0540h	0030h
Backup Memory (See Table 6-35)	0660h	0020h
ADC (See Table 6-36)	0700h	0040h

Table 6-21. Special Function Registers (Base Address: 0100h)

REGISTER DESCRIPTION	ACRONYM	OFFSET
SFR interrupt enable	SFRIE1	00h
SFR interrupt flag	SFRIFG1	02h
SFR reset pin control	SFRRPCR	04h

Table 6-22. PMM Registers (Base Address: 0120h)

REGISTER DESCRIPTION	ACRONYM	OFFSET
PMM control 0	PMMCTL0	00h
PMM control 1	PMMCTL1	02h
PMM control 2	PMMCTL2	04h
PMM interrupt flags	PMMIFG	0Ah
PM5 control 0	PM5CTL0	10h

Table 6-23. SYS Registers (Base Address: 0140h)

REGISTER DESCRIPTION	ACRONYM	OFFSET
System control	SYSCTL	00h
Bootloader configuration area	SYSBSLC	02h
JTAG mailbox control	SYSJMBBC	06h
JTAG mailbox input 0	SYSJMBI0	08h
JTAG mailbox input 1	SYSJMBI1	0Ah
JTAG mailbox output 0	SYSJMBO0	0Ch
JTAG mailbox output 1	SYSJMBO1	0Eh
Bus error vector generator	SYSBERRIV	18h
User NMI vector generator	SYSUNIV	1Ah
System NMI vector generator	SYSSNIV	1Ch
Reset vector generator	SYSRSTIV	1Eh
System configuration 0	SYSCFG0	20h
System configuration 1	SYSCFG1	22h
System configuration 2	SYSCFG2	24h

Table 6-24. CS Registers (Base Address: 0180h)

REGISTER DESCRIPTION	ACRONYM	OFFSET
CS control 0	CSCTL0	00h
CS control 1	CSCTL1	02h
CS control 2	CSCTL2	04h
CS control 3	CSCTL3	06h
CS control 4	CSCTL4	08h
CS control 5	CSCTL5	0Ah
CS control 6	CSCTL6	0Ch
CS control 7	CSCTL7	0Eh
CS control 8	CSCTL8	10h

Table 6-25. FRAM Registers (Base Address: 01A0h)

REGISTER DESCRIPTION	ACRONYM	OFFSET
FRAM control 0	FRCTL0	00h
General control 0	GCCTL0	04h
General control 1	GCCTL1	06h

Table 6-26. CRC Registers (Base Address: 01C0h)

REGISTER DESCRIPTION	ACRONYM	OFFSET
CRC data input	CRC16DI	00h
CRC data input reverse byte	CRCDIRB	02h
CRC initialization and result	CRCINIRES	04h
CRC result reverse byte	CRCRESR	06h

Table 6-27. WDT Registers (Base Address: 01CCh)

REGISTER DESCRIPTION	ACRONYM	OFFSET
Watchdog timer control	WDTCTL	00h

Table 6-28. Port P1, P2 Registers (Base Address: 0200h)

REGISTER DESCRIPTION	ACRONYM	OFFSET
Port P1 input	P1IN	00h
Port P1 output	P1OUT	02h
Port P1 direction	P1DIR	04h
Port P1 pulling enable	P1REN	06h
Port P1 selection 0	P1SEL0	0Ah
Port P1 selection 1	P1SEL1	0Ch
Port P1 interrupt vector word	P1IV	0Eh
Port P1 interrupt edge select	P1IES	18h
Port P1 complement selection	P1SELC	16h
Port P1 interrupt enable	P1IE	1Ah
Port P1 interrupt flag	P1IFG	1Ch
Port P2 input	P2IN	01h
Port P2 output	P2OUT	03h
Port P2 direction	P2DIR	05h
Port P2 pulling enable	P2REN	07h
Port P2 selection 0	P2SEL0	0Bh
Port P2 selection 1	P2SEL1	0Ch
Port P2 complement selection	P2SELC	17h
Port P2 interrupt vector word	P2IV	1Eh
Port P2 interrupt edge select	P2IES	19h
Port P2 interrupt enable	P2IE	1Bh
Port P2 interrupt flag	P2IFG	1Dh

Table 6-29. RTC Registers (Base Address: 0300h)

REGISTER DESCRIPTION	ACRONYM	OFFSET
RTC control	RTCCTL	00h
RTC interrupt vector	RTCIV	04h
RTC modulo	RTCMOD	08h
RTC counter	RTCCNT	0Ch

Table 6-30. Timer0_A3 Registers (Base Address: 0380h)

REGISTER DESCRIPTION	ACRONYM	OFFSET
TA0 control	TA0CTL	00h
Capture/compare control 0	TA0CCTL0	02h
Capture/compare control 1	TA0CCTL1	04h
Capture/compare control 2	TA0CCTL2	06h
TA0 counter	TA0R	10h
Capture/compare 0	TA0CCR0	12h
Capture/compare 1	TA0CCR1	14h
Capture/compare 2	TA0CCR2	16h
TA0 expansion 0	TA0EX0	20h
TA0 interrupt vector	TA0IV	2Eh

Table 6-31. Timer1_A3 Registers (Base Address: 03C0h)

REGISTER DESCRIPTION	ACRONYM	OFFSET
TA1 control	TA1CTL	00h
Capture/compare control 0	TA1CCTL0	02h
Capture/compare control 1	TA1CCTL1	04h
Capture/compare control 2	TA1CCTL2	06h
TA1 counter	TA1R	10h
Capture/compare 0	TA1CCR0	12h
Capture/compare 1	TA1CCR1	14h
Capture/compare 2	TA1CCR2	16h
TA1 expansion 0	TA1EX0	20h
TA1 interrupt vector	TA1IV	2Eh

Table 6-32. MPY32 Registers (Base Address: 04C0h)

REGISTER DESCRIPTION	ACRONYM	OFFSET
16-bit operand 1 – multiply	MPY	00h
16-bit operand 1 – signed multiply	MPYS	02h
16-bit operand 1 – multiply accumulate	MAC	04h
16-bit operand 1 – signed multiply accumulate	MACS	06h
16-bit operand 2	OP2	08h
16 × 16 result low word	RESLO	0Ah
16 × 16 result high word	RESHI	0Ch
16 × 16 sum extension	SUMEXT	0Eh
32-bit operand 1 – multiply low word	MPY32L	10h
32-bit operand 1 – multiply high word	MPY32H	12h
32-bit operand 1 – signed multiply low word	MPYS32L	14h
32-bit operand 1 – signed multiply high word	MPYS32H	16h
32-bit operand 1 – multiply accumulate low word	MAC32L	18h
32-bit operand 1 – multiply accumulate high word	MAC32H	1Ah
32-bit operand 1 – signed multiply accumulate low word	MACS32L	1Ch
32-bit operand 1 – signed multiply accumulate high word	MACS32H	1Eh
32-bit operand 2 – low word	OP2L	20h
32-bit operand 2 – high word	OP2H	22h
32 × 32 result 0 – least significant word	RES0	24h
32 × 32 result 1	RES1	26h
32 × 32 result 2	RES2	28h
32 × 32 result 3 – most significant word	RES3	2Ah
MPY32 control 0	MPY32CTL0	2Ch

Table 6-33. eUSCI_A0 Registers (Base Address: 0500h)

REGISTER DESCRIPTION	ACRONYM	OFFSET
eUSCI_A control word 0	UCA0CTLW0	00h
eUSCI_A control word 1	UCA0CTLW1	02h
eUSCI_A control rate 0	UCA0BR0	06h
eUSCI_A control rate 1	UCA0BR1	07h
eUSCI_A modulation control	UCA0MCTLW	08h
eUSCI_A status	UCA0STAT	0Ah
eUSCI_A receive buffer	UCA0RXBUF	0Ch
eUSCI_A transmit buffer	UCA0TXBUF	0Eh
eUSCI_A LIN control	UCA0ABCTL	10h
eUSCI_A IrDA transmit control	IUCA0IRTCTL	12h
eUSCI_A IrDA receive control	IUCA0IRRCTL	13h
eUSCI_A interrupt enable	UCA0IE	1Ah
eUSCI_A interrupt flags	UCA0IFG	1Ch
eUSCI_A interrupt vector word	UCA0IV	1Eh

Table 6-34. eUSCI_B0 Registers (Base Address: 0540h)

REGISTER DESCRIPTION	ACRONYM	OFFSET
eUSCI_B control word 0	UCB0CTLW0	00h
eUSCI_B control word 1	UCB0CTLW1	02h
eUSCI_B bit rate 0	UCB0BR0	06h
eUSCI_B bit rate 1	UCB0BR1	07h

Table 6-34. eUSCI_B0 Registers (Base Address: 0540h) (continued)

REGISTER DESCRIPTION	ACRONYM	OFFSET
eUSCI_B status word	UCB0STATW	08h
eUSCI_B byte counter threshold	UCB0TBCNT	0Ah
eUSCI_B receive buffer	UCB0RXBUF	0Ch
eUSCI_B transmit buffer	UCB0TXBUF	0Eh
eUSCI_B I2C own address 0	UCB0I2COA0	14h
eUSCI_B I2C own address 1	UCB0I2COA1	16h
eUSCI_B I2C own address 2	UCB0I2COA2	18h
eUSCI_B I2C own address 3	UCB0I2COA3	1Ah
eUSCI_B receive address	UCB0ADDRX	1Ch
eUSCI_B address mask	UCB0ADDMASK	1Eh
eUSCI_B I2C slave address	UCB0I2CSA	20h
eUSCI_B interrupt enable	UCB0IE	2Ah
eUSCI_B interrupt flags	UCB0IFG	2Ch
eUSCI_B interrupt vector word	UCB0IV	2Eh

Table 6-35. Backup Memory Registers (Base Address: 0660h)

REGISTER DESCRIPTION	ACRONYM	OFFSET
Backup memory 0	BAKMEM0	00h
Backup memory 1	BAKMEM1	02h
Backup memory 2	BAKMEM2	04h
Backup memory 3	BAKMEM3	06h
Backup memory 4	BAKMEM4	08h
Backup memory 5	BAKMEM5	0Ah
Backup memory 6	BAKMEM6	0Ch
Backup memory 7	BAKMEM7	0Eh
Backup memory 8	BAKMEM8	10h
Backup memory 9	BAKMEM9	12h
Backup memory 10	BAKMEM10	14h
Backup memory 11	BAKMEM11	16h
Backup memory 12	BAKMEM12	18h
Backup memory 13	BAKMEM13	1Ah
Backup memory 14	BAKMEM14	1Ch
Backup memory 15	BAKMEM15	1Eh

Table 6-36. ADC Registers (Base Address: 0700h)

REGISTER DESCRIPTION	REGISTER	OFFSET
ADC control 0	ADCCTL0	00h
ADC control 1	ADCCTL1	02h
ADC control 2	ADCCTL2	04h
ADC window comparator low threshold	ADCLO	06h
ADC window comparator high threshold	ADCHI	08h
ADC memory control 0	ADCMCTL0	0Ah
ADC conversion memory	ADCMEM0	12h
ADC interrupt enable	ADCIE	1Ah
ADC interrupt flags	ADCIFG	1Ch
ADC interrupt vector word	ADCIV	1Eh

6.14 Identification

6.14.1 Revision Identification

The device revision information is included as part of the top-side marking on the device package. The device-specific errata sheet describes these markings.

The hardware revision is also stored in the Device Descriptor structure in the Info Block section. For details on this value, see the Hardware Revision entries in [Section 6.12](#).

6.14.2 Device Identification

The device type can be identified from the top-side marking on the device package. The device-specific errata sheet describes these markings.

A device identification value is also stored in the Device Descriptor structure in the Info Block section. For details on this value, see the Device ID entries in [Section 6.12](#).

6.14.3 JTAG Identification

Programming through the JTAG interface, including reading and identifying the JTAG ID, is described in detail in [MSP430 Programming With the JTAG Interface](#).

7 Applications, Implementation, and Layout

NOTE

Information in the following Applications section is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

7.1 Device Connection and Layout Fundamentals

This section discusses the recommended guidelines when designing with the MSP430 devices. These guidelines are to make sure that the device has proper connections for powering, programming, debugging, and optimum analog performance.

7.1.1 Power Supply Decoupling and Bulk Capacitors

TI recommends connecting a combination of a 10- μ F plus a 100-nF low-ESR ceramic decoupling capacitor to the DVCC and DVSS pins. Higher-value capacitors may be used but can impact supply rail ramp-up time. Decoupling capacitors must be placed as close as possible to the pins that they decouple (within a few millimeters). Additionally, TI recommends separated grounds with a single-point connection for better noise isolation from digital-to-analog circuits on the board and to achieve high analog accuracy.

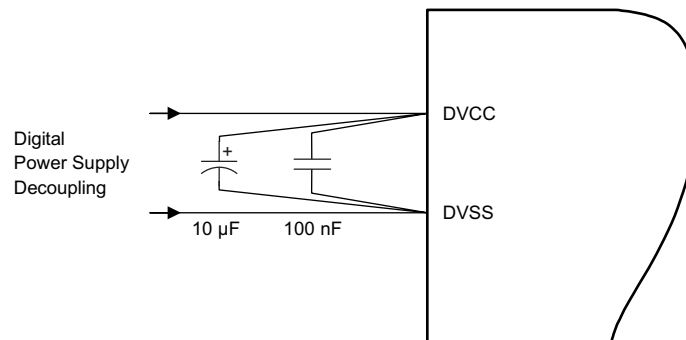


Figure 7-1. Power Supply Decoupling

7.1.2 External Oscillator

This device supports only a low-frequency crystal (32 kHz) on the XIN and XOUT pins. External bypass capacitors for the crystal oscillator pins are required.

It is also possible to apply digital clock signals to the XIN input pin that meet the specifications of the respective oscillator if the appropriate XT1BYPASS mode is selected. In this case, the associated XOUT pin can be used for other purposes. If the XIN and XOUT pins are not used, they must be terminated according to [Section 4.6](#).

[Figure 7-2](#) shows a typical connection diagram.

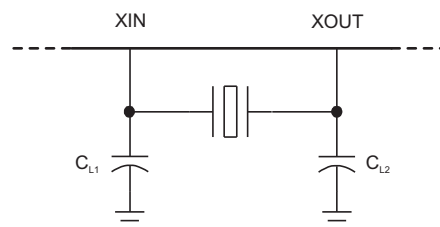


Figure 7-2. Typical Crystal Connection

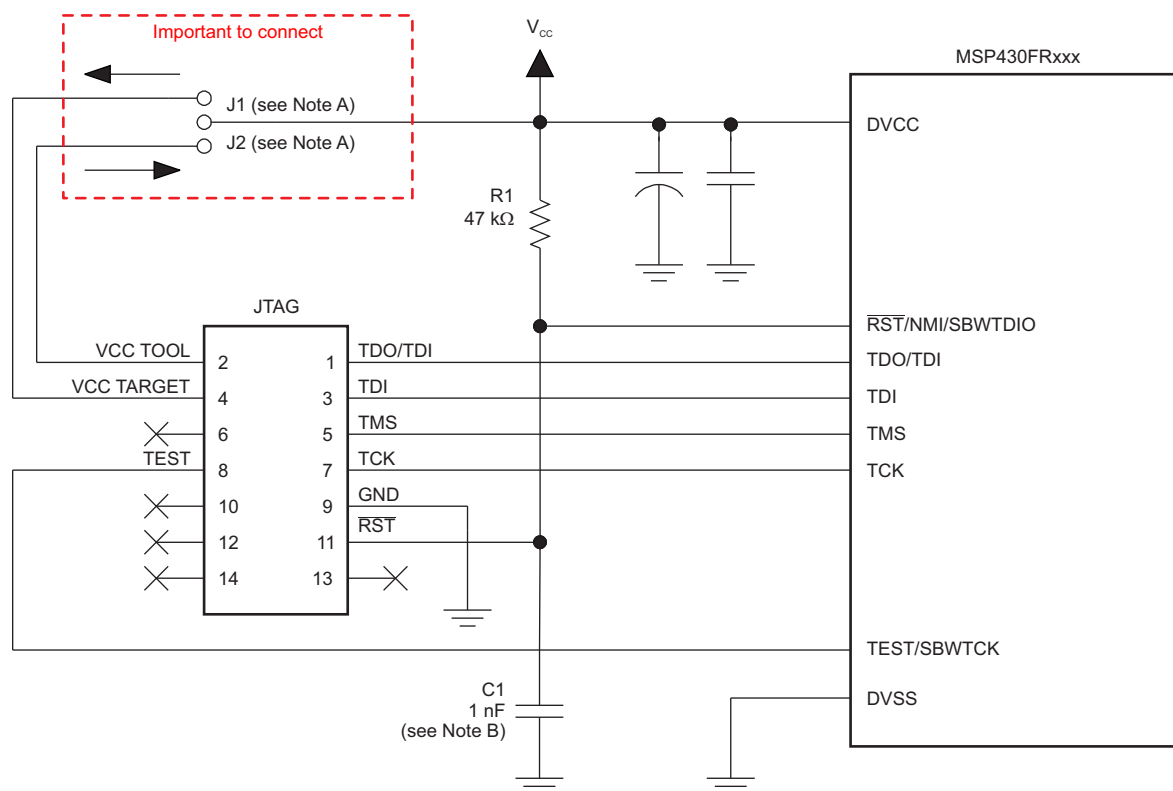
See [MSP430 32-kHz Crystal Oscillators](#) for more information on selecting, testing, and designing a crystal oscillator with the MSP430 devices.

7.1.3 JTAG

With the proper connections, the debugger and a hardware JTAG interface (such as the MSP-FET or MSP-FET430UIF) can be used to program and debug code on the target board. In addition, the connections also support the MSP-GANG production programmers, thus providing an easy way to program prototype boards, if desired. [Figure 7-3](#) shows the connections between the 14-pin JTAG connector and the target device required to support in-system programming and debugging for 4-wire JTAG communication. [Figure 7-4](#) shows the connections for 2-wire JTAG mode (Spy-Bi-Wire).

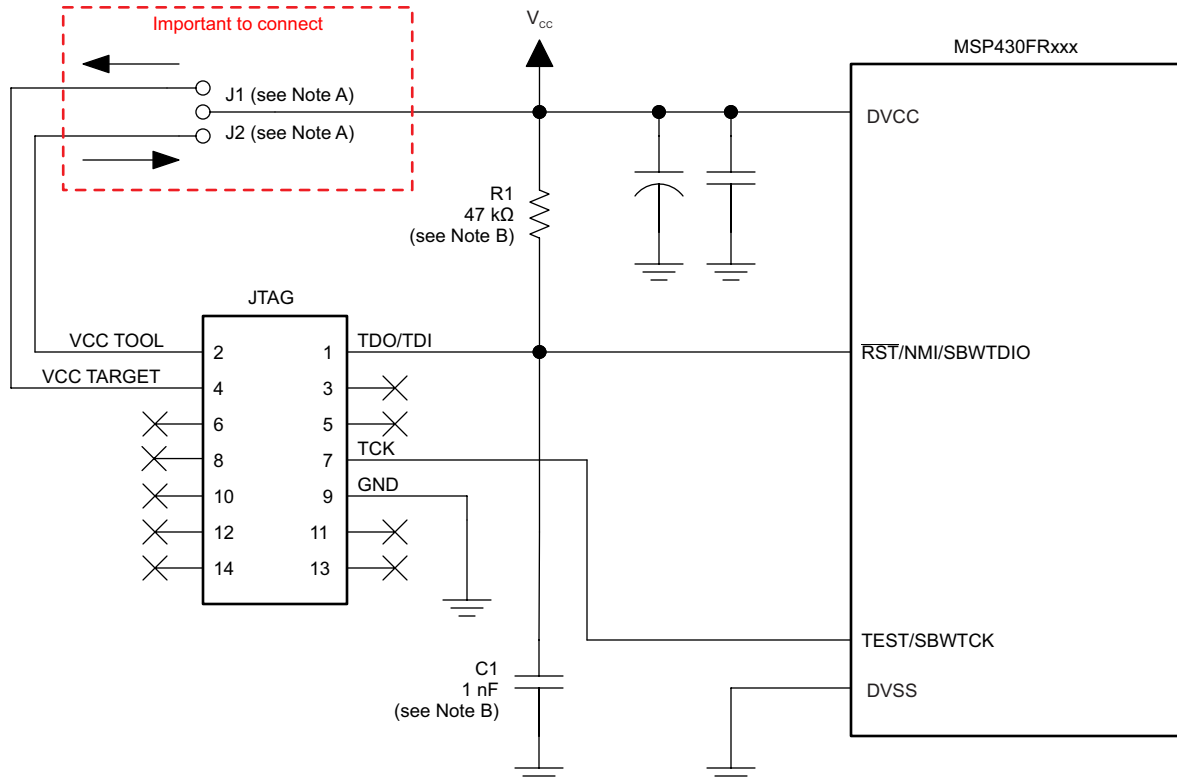
The connections for the MSP-FET and MSP-FET430UIF interface modules and the MSP-GANG are identical. Both can supply V_{CC} to the target board (through pin 2). In addition, the MSP-FET and MSP-FET430UIF interface modules and MSP-GANG have a V_{CC} sense feature that, if used, requires an alternate connection (pin 4 instead of pin 2). The V_{CC} sense feature detects the local V_{CC} present on the target board (that is, a battery or other local power supply) and adjusts the output signals accordingly. [Figure 7-3](#) and [Figure 7-4](#) show a jumper block that supports both scenarios of supplying V_{CC} to the target board. If this flexibility is not required, the desired V_{CC} connections may be hard-wired to eliminate the jumper block. Pins 2 and 4 must not be connected at the same time.

For additional design information regarding the JTAG interface, see the [MSP430 Hardware Tools User's Guide](#).



- A. If a local target power supply is used, make connection J1. If power from the debug or programming adapter is used, make connection J2.
- B. The upper limit for C1 is 1.1 nF when using current TI tools.

Figure 7-3. Signal Connections for 4-Wire JTAG Communication



- Make connection J1 if a local target power supply is used, or make connection J2 if the target is powered from the debug or programming adapter.
- The device $\overline{\text{RST}}/\text{NMI}/\text{SBWTIO}$ pin is used in 2-wire mode for bidirectional communication with the device during JTAG access, and any capacitance that is attached to this signal may affect the ability to establish a connection with the device. The upper limit for C1 is 1.1 nF when using current TI tools.

Figure 7-4. Signal Connections for 2-Wire JTAG Communication (Spy-Bi-Wire)

7.1.4 Reset

The reset pin can be configured as a reset function (default) or as an NMI function in the Special Function Register (SFR), `SFRRPCR`.

In reset mode, the $\overline{\text{RST}}/\text{NMI}$ pin is active low, and a pulse applied to this pin that meets the reset timing specifications generates a BOR-type device reset.

Setting `SYSNMI` causes the $\overline{\text{RST}}/\text{NMI}$ pin to be configured as an external NMI source. The external NMI is edge sensitive, and its edge is selectable by `SYSNMIIES`. Setting the `NMIIE` enables the interrupt of the external NMI. When an external NMI event occurs, the `NMIIFG` is set.

The $\overline{\text{RST}}/\text{NMI}$ pin can have either a pullup or pulldown that is enabled or not. `SYSRSTUP` selects either pullup or pulldown, and `SYSRSTRE` causes the pullup (default) or pulldown to be enabled (default) or not. If the $\overline{\text{RST}}/\text{NMI}$ pin is unused, it is required either to select and enable the internal pullup or to connect an external 47-kΩ pullup resistor to the $\overline{\text{RST}}/\text{NMI}$ pin with a 10-nF pulldown capacitor. The pulldown capacitor should not exceed 1.1 nF when using devices with Spy-Bi-Wire interface in Spy-Bi-Wire mode or in 4-wire JTAG mode with TI tools like FET interfaces or GANG programmers.

See the [MP430FR4xx and MP430FR2xx Family User's Guide](#) for more information on the referenced control registers and bits.

7.1.5 Unused Pins

For details on the connection of unused pins, see [Section 4.6](#).

7.1.6 General Layout Recommendations

- Proper grounding and short traces for external crystal to reduce parasitic capacitance. See [MSP430 32-kHz Crystal Oscillators](#) for recommended layout guidelines.
- Proper bypass capacitors on DVCC and reference pins, if used.
- Avoid routing any high-frequency signal close to an analog signal line. For example, keep digital switching signals such as PWM or JTAG signals away from the oscillator circuit.
- Proper ESD level protection should be considered to protect the device from unintended high-voltage electrostatic discharge. See [MSP430 System-Level ESD Considerations](#) for guidelines.

7.1.7 Do's and Don'ts

During power up, power down, and device operation, DVCC must not exceed the limits specified in [Section 5.1](#). Exceeding the specified limits may cause malfunction of the device including erroneous writes to RAM and FRAM.

7.2 Peripheral- and Interface-Specific Design Information

7.2.1 ADC Peripheral

7.2.1.1 Partial Schematic

[Figure 7-5](#) shows the recommended decoupling circuit when an external voltage reference is used.

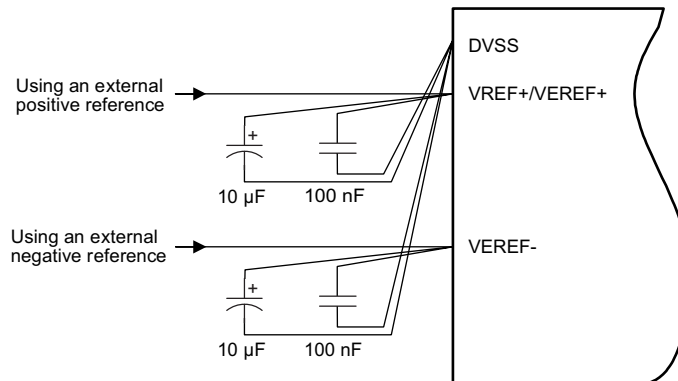


Figure 7-5. ADC Grounding and Noise Considerations

7.2.1.2 Design Requirements

As with any high-resolution ADC, appropriate printed-circuit-board layout and grounding techniques should be followed to eliminate ground loops, unwanted parasitic effects, and noise.

Ground loops are formed when return current from the ADC flows through paths that are common with other analog or digital circuitry. If care is not taken, this current can generate small unwanted offset voltages that can add to or subtract from the reference or input voltages of the ADC. The general guidelines in [Section 7.1.1](#) combined with the connections shown in [Figure 7-5](#) prevent this.

Quickly switching digital signals and noisy power supply lines can corrupt the conversion results, so keep the ADC input trace shielded from those digital and power supply lines. Putting the MCU in low-power mode during the ADC conversion improves the ADC performance in a noisy environment. If the device includes the analog power pair inputs (AVCC and AVSS), TI recommends a noise-free design using separate analog and digital ground planes with a single-point connection to achieve high accuracy.

[Figure 7-5](#) shows the recommended decoupling circuit when an external voltage reference is used. The internal reference module has a maximum drive current as described in the sections *ADC Pin Enable* and *1.2-V Reference Settings* of the [MSP430FR4xx and MSP430FR2xx Family User's Guide](#).

The reference voltage must be a stable voltage for accurate measurements. The capacitor values that are selected in the general guidelines filter out the high- and low-frequency ripple before the reference voltage enters the device. In this case, the 10- μ F capacitor buffers the reference pin and filters any low-frequency ripple. A bypass capacitor of 100 nF filters out any high-frequency noise.

7.2.1.3 Layout Guidelines

Components that are shown in the partial schematic (see [Figure 7-5](#)) should be placed as close as possible to the respective device pins to avoid long traces, because they add additional parasitic capacitance, inductance, and resistance on the signal.

Avoid routing analog input signals close to a high-frequency pin (for example, a high-frequency PWM), because the high-frequency switching can be coupled into the analog signal.

8 器件和文档支持

8.1 入门和后续步骤

有关帮助您进行开发的 MSP 低功耗微控制器、工具和库的更多信息，请访问《[MSP430™ 超低功耗传感和测量 MCU 概述](#)》。

8.2 器件命名规则

为了标示产品开发周期所处的阶段，TI 为所有 MSP MCU 器件的部件号分配了前缀。每个 MSP MCU 商用系列产品成员都具有以下两个前缀之一：MSP 或 XMS。这些前缀代表了产品的发展阶段，即从工程原型 (XMS) 直到完全合格的生产器件 (MSP)。

XMS - 实验器件，不一定代表最终器件的电气规格

MSP - 完全合格的生产器件

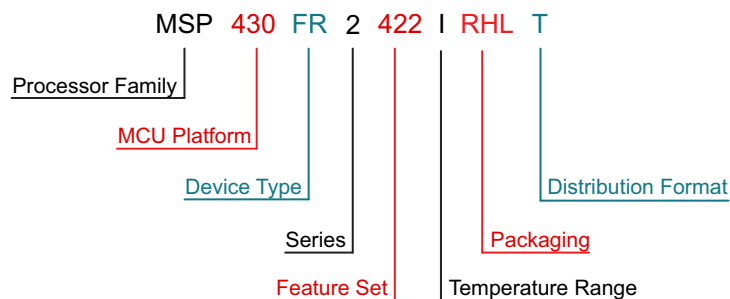
XMS 器件在供货时附带如下免责声明：

“开发中的产品用于内部评估用途。”

MSP 器件的特性已经全部明确，并且器件的质量和可靠性已经完全论证。TI 的标准保修证书对该器件适用。

预测显示原型器件 (XMS) 的故障率大于标准生产器件。由于这些器件的预计最终使用故障率尚不确定，德州仪器 (TI) 建议不要将它们用于任何生产系统。请仅使用合格的生产器件。

TI 器件的命名规则还包括一个带有器件系列名称的后缀。此后缀表示温度范围、封装类型和配送形式。图 8-1 提供了解读完整器件名称的图例。



Processor Family	MSP = Mixed-Signal Processor XMS = Experimental Silicon	
MCU Platform	430 = MSP430 16-bit low-power platform	
Device Type	Memory Type FR = FRAM	
Series	2 = Up to 16 MHz without LCD	
Feature Set	First and Second Digits: ADC10 Channels / eUSCs / 16-bit Timers / I/Os 42 = Up to 8 / 2 / 2 / Up to 15	Third Digit: FRAM (KB) / SRAM (KB) 2 = 8 / 2
Temperature Range	I = -40°C to 85°C	
Packaging	www.ti.com/packaging	
Distribution Format	T = Small reel R = Large reel No Marking = Tube or tray	

图 8-1. 器件命名规则

8.3 工具和软件

表 8-1 列出 调试 的调试功能。请参阅《适用于 MSP430 MCU 的 Code Composer Studio IDE 用户指南》，以了解有关可用 功能）的详细信息。

表 8-1. 硬件 特性

MSP430 架构	四线制 JTAG	两线制 JTAG	断点 (N)	范围断点	时钟控制	状态序列发生器	跟踪缓冲器	LPMx.5 调试支持	EEM 版本
MSP430xv2	有	有	3	有	是	否	否	否	S

设计套件与评估模块

适用于 MSP430FR2x MCU 的 MSP-TS430RHL20 20 引脚目标开发板

MSP-TS430RHL20 是独立的 ZIF 插接目标板，用于通过 JTAG 接口或 Spy Bi-Wire（双线制 JTAG）协议对 MSP430 进行系统内编程和调试。该开发板支持采用 20 引脚 VQFN 封装（TI 封装代码：RHL）的所有 MSP430FR252x 和 MSP430FR242x 闪存部件。

MSP-FET + MSP-TS430RHL20 FRAM 微控制器开发套件包

MSP-FET430RHL20-BNDL 开发套件包包含适用于 MSP430FR2422 微控制器（例如 MSP430FR2422RHL）且支持 20 引脚 RHL 封装的两种调试工具。这两种工具分别为 MSP-TS430RHL20 和 MSP-FET。

软件

MSP430Ware™ 软件

MSP430Ware 软件集合了所有 MSP430 器件的代码示例、数据表以及其他设计资源，打包提供给用户。除了提供已有 MSP430 设计资源的完整集合外，MSP430Ware 软件还包含名为 MSP430 驱动程序库的高级 API。借助该库可以轻松地对 MSP430 硬件进行编程。MSP430Ware 软件以 CCS 组件或独立软件包两种形式提供。

MSP430FR2422 代码示例

根据不同应用需求配置各集成外设的每个 MSP 器件均具备相应的 C 代码示例。

MSP 驱动程序库

驱动程序库的抽象化 API 通过提供易于使用的函数调用使您不再拘泥于 MSP430 硬件的细节。完整的文档通过具有帮助意义的 API 指南交付，其中包括有关每个函数调用和经过验证的参数的详细信息。开发人员可以使用驱动程序库功能，以最低开销编写完整项目。

MSP EnergyTrace™ 技术

MSP430 微控制器的 EnergyTrace 技术是基于能量的代码分析工具，用于测量和显示应用的能量配置，同时协助优化应用以实现超低功耗。

ULP（超低功耗）Advisor

ULP Advisor™ 软件是一款辅助工具，旨在指导开发人员编写更为高效的代码，从而充分利用 MSP 和 MSP432 微控制器独特的超低功耗功能。ULP Advisor 的目标人群是微控制器的资深开发者和开发新手，可以根据详尽的 ULP 检验表检查代码，以便最大限度地利用应用程序。在编译时，ULP Advisor 会提供通知和备注以突出显示代码中可以进一步优化的区域，进而实现更低功耗。

适用于 MSP 超低功耗微控制器的 FRAM 嵌入式软件实用程序

FRAM 实用程序旨在作为不断扩充的嵌入式软件实用程序集合，其中的实用程序充分利用 **FRAM** 的超低功耗和近乎无限次的写入寿命。这些实用程序适用于 **MSP430FRxx** **FRAM** 微控制器并提供示例代码协助应用程序开发。其中的实用程序包含功耗计算实用程序 (**CTPL**)。CTPL 是一套实用程序 API 集，通过 CTPL 能够轻松使用 **LPMx.5** 低功耗模式以及强大的关断模式，允许应用程序在检测到功率损耗时节约能耗并恢复关键的系统元件。

IEC60730 软件包

IEC60730 MSP430 软件包经过专门开发，用于协助客户达到 **IEC 60730-1:2010**（家用及类似用途的自动化电气控制 - 第 1 部分：一般要求）**B** 类产品的要求。其中涵盖家用电器、电弧检测器、电源转换器、电动工具、电动自行车及其他诸多产品。**IEC60730 MSP430** 软件包可以嵌入在 **MSP430** 中运行的客户应用，从而帮助客户简化其消费类器件在功能安全方面遵循 **IEC 60730-1:2010 B** 类规范的认证工作。

适用于 MSP 的定点数学库

MSP IQmath 和 **Qmath** 库是为 **C** 语言开发者提供的一套经过高度优化的高精度数学运算函数集合，能够将浮点算法无缝嵌入 **MSP430** 和 **MSP432** 器件的定点代码中。这些例程通常用于计算密集型实时应用，而优化的执行速度、高精度以及超低能耗通常是影响这些实时应用的关键因素。与使用浮点数学算法编写的同等代码相比，使用 **IQmath** 和 **Qmath** 库可以大幅提高执行速度并显著降低能耗。

适用于 MSP430 的浮点数学库

TI 在低功耗和低成本微控制器领域锐意创新，为您提供 **MSPMATHLIB**。这是标量函数的浮点数学库，能够充分利用器件的智能外设，使性能提升高达 **26** 倍。**Mathlib** 能够轻松集成到您的设计中。该运算库免费使用并集成在 **Code Composer Studio** 和 **IAR IDE** 中。如需深入了解该数学库及相关基准，请阅读用户指南。

开发工具

适用于 MSP 微控制器的 Code Composer Studio™ 集成开发环境

Code Composer Studio 是一种集成开发环境 (**IDE**)，支持所有 **MSP** 微控制器。**Code Composer Studio** 包含一整套开发和调试嵌入式应用的嵌入式软件实用程序的工具。它包含了优化的 **C/C++** 编译器、源代码编辑器、项目构建环境、调试器、描述器以及其他多种功能。直观的 **IDE** 提供了单个用户界面，有助于完成应用程序开发流程的每个步骤。熟悉的实用程序和界面可提升用户的入门速度。**Code Composer Studio** 将 **Eclipse** 软件框架的优点和 **TI** 先进的嵌入式调试功能相结合，为嵌入式开发人员提供了一种功能丰富的优异开发环境。当 **CCS** 与 **MSP MCU** 搭配使用时，可以使用独特而强大的插件和嵌入式软件实用程序，从而充分利用 **MSP** 微控制器的功能。

命令行编程器

MSP Flasher 是一款基于 **shell** 的开源接口，可使用 **JTAG** 或 **Spy-Bi-Wire (SBW)** 通信通过 **FET** 编程器或 **eZ430** 对 **MSP** 微控制器进行编程。**MSP Flasher** 可用于将二进制文件 (**.txt** 或 **.hex** 文件) 直接下载到 **MSP** 微控制器，而无需使用 **IDE**。

MSP MCU 编程器和调试器

MSP-FET 是一款强大的仿真开发工具（通常称为调试探针），可让用户在 MSP 低功耗微控制器 (MCU) 上快速进行应用开发。创建 MCU 软件通常需要将生成的二进制程序下载到 MSP 器件，以进行验证和调试。MSP-FET 在主机和目标 MSP 间提供调试通信通道。此外，MSP-FET 还在计算机的 USB 接口和 MSP UART 之间提供反向通道 UART 连接。这为 MSP 编程器提供了一种便捷方法，实现了 MSP 和在计算机上运行的终端之间的串行通信。

MSP-GANG 生产编程器

MSP Gang 编程器可同时对多达八个完全相同的 MSP430 或 MSP432 闪存或 FRAM 器件进行编程。MSP Gang 编程器可使用标准的 RS-232 或 USB 连接与主机 PC 相连并提供灵活的编程选项，允许用户完全自定义流程。MSP Gang 编程器配有扩展板“Gang 分离器”，可在 MSP Gang 编程器和多个目标器件间实现互连。

8.4 文档支持

以下文档介绍了 MSP430FR2422 微控制器。www.ti.com.cn 网站上提供了这些文档的副本。

接收文档更新通知

如需接收文档更新通知（包括器件勘误表），请转至 ti.com.cn 上相关器件的产品文件夹（例如，[MSP430FR2422](#)）。请单击右上角的“通知我”按钮。点击注册后，即可收到产品信息更改每周摘要（如有）。有关更改的详细信息，请查阅已修订文档的修订历史记录。

勘误

《MSP430FR2422 器件勘误表》

介绍了该器件的所有器件修订版本功能规格的已知例外情况。

用户指南

《MSP430FR4xx 和 MSP430FR2xx 系列用户指南》

可说明。

《MSP430 FRAM 器件引导加载程序 (BSL) 用户指南》

BSL 能在 MSP430 MCU 项目开发和更新阶段对存储器进行编程。BSL 可由使用串行协议发送命令的工具激活。BSL 支持用户控制 MSP430 器件的活动，可与个人计算机或其他设备进行数据交换。

《通过 JTAG 接口对 MSP430 进行编程》

此文档介绍了使用 JTAG 通信端口擦除、编程和验证基于 MSP430 闪存和 FRAM 的微控制器系列的存储器模块所需的功能。此外，该文档还介绍了如何编程所有 MSP430 器件上均具备的 JTAG 访问安全保险丝。此文档介绍了使用标准四线制 JTAG 接口和两线制 JTAG 接口（也称为 Spy-Bi-Wire (SBW)）的器件访问。

《MSP430 硬件工具用户指南》

此手册介绍了 TI MSP-FET430 闪存仿真工具 (FET) 的硬件。FET 是针对 MSP430 超低功耗微控制器的程序开发工具。

应用报告

《MSP430 32kHz 晶体振荡器》

选择合适的晶体、正确的负载电路和适当的电路板布局是实现稳定的晶体振荡器的关键。该应用报告总结了晶体振荡器的功能，介绍了用于选择合适的晶体以实现 MSP430 超低功耗运行的参数。此外，还给出了正确电路板布局的提示和示例。此外，为了确保振荡器在大规模生产后能够稳定运行，还可能需要进行一些振荡器测试，该文档中提供了有关这些测试的详细信息。

《MSP430 系统级 ESD 注意事项》

随着芯片技术向更低电压方向发展以及设计具有成本效益的超低功耗组件的需求的出现，系统级 ESD 要求变得越来越苛刻。该应用报告介绍了不同的 ESD 主题，旨在帮助电路板设计人员和 OEM 理解并设计出稳健耐用的系统级设计。另外还介绍了若干实际应用系统级 ESD 保护设计示例及其结果。

8.5 社区资源

下列链接提供到 TI 社区资源的连接。链接的内容由各个分销商“按照原样”提供。这些内容并不构成 TI 技术规范，并且不一定反映 TI 的观点；请参见 TI 的《使用条款》。

TI E2E™ 社区

TI 的工程师交流 (E2E) 社区。此社区的创建目的是为了促进工程师之间协作。在 e2e.ti.com 中，您可以提问、共享知识、拓展思路，在同领域工程师的帮助下解决问题。

TI 嵌入式处理器维基网页

德州仪器 (TI) 嵌入式处理器维基网页。此网站的建立是为了帮助开发人员熟悉德州仪器 (TI) 的嵌入式处理器，并且也为了促进与这些器件相关的硬件和软件的总体知识的创新和增长。

8.6 商标

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8.7 静电放电警告



ESD 可能会损坏该集成电路。德州仪器 (TI) 建议通过适当的预防措施处理所有集成电路。如果不遵守正确的处理措施和安装程序，可能会损坏集成电路。

ESD 的损坏小至导致微小的性能降级，大至整个器件故障。精密的集成电路可能更容易受到损坏，这是因为非常细微的参数更改都可能会导致器件与其发布的规格不相符。

8.8 Export Control Notice

Recipient agrees to not knowingly export or re-export, directly or indirectly, any product or technical data (as defined by the U.S., EU, and other Export Administration Regulations) including software, or any controlled product restricted by other applicable national regulations, received from disclosing party under nondisclosure obligations (if any), or any direct product of such technology, to any destination to which such export or re-export is restricted or prohibited by U.S. or other applicable laws, without obtaining prior authorization from U.S. Department of Commerce and other competent Government authorities to the extent required by those laws.

8.9 Glossary

TI Glossary This glossary lists and explains terms, acronyms, and definitions.

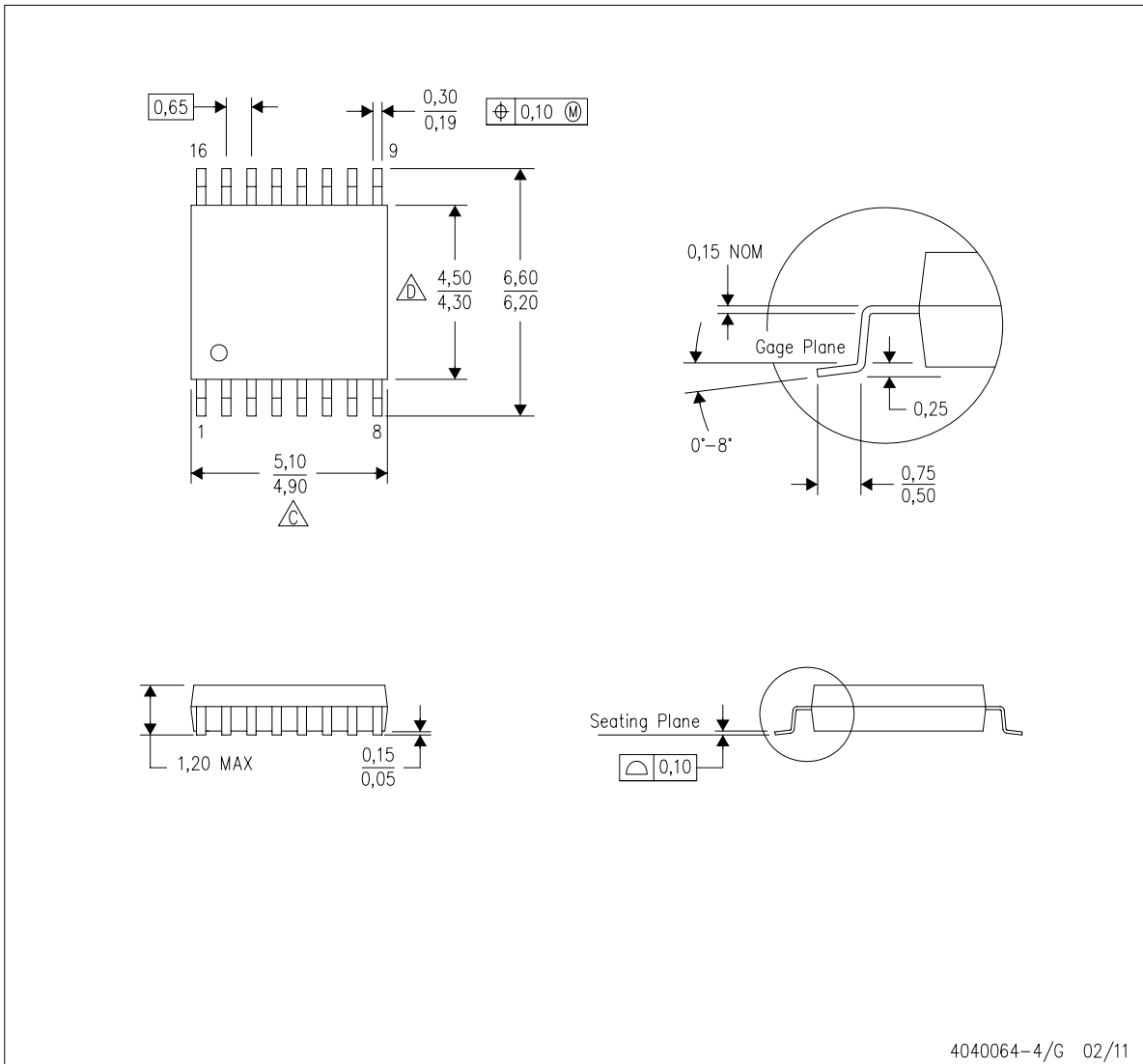
9 机械、封装和可订购信息

以下页面包含机械、封装和可订购信息。这些信息是指定器件的最新可用数据。这些数据会在无通知且不对本文档进行修订的情况下发生改变。欲获得该数据表的浏览器版本，请查阅左侧的导航栏。

MECHANICAL DATA

PW (R-PDSO-G16)

PLASTIC SMALL OUTLINE



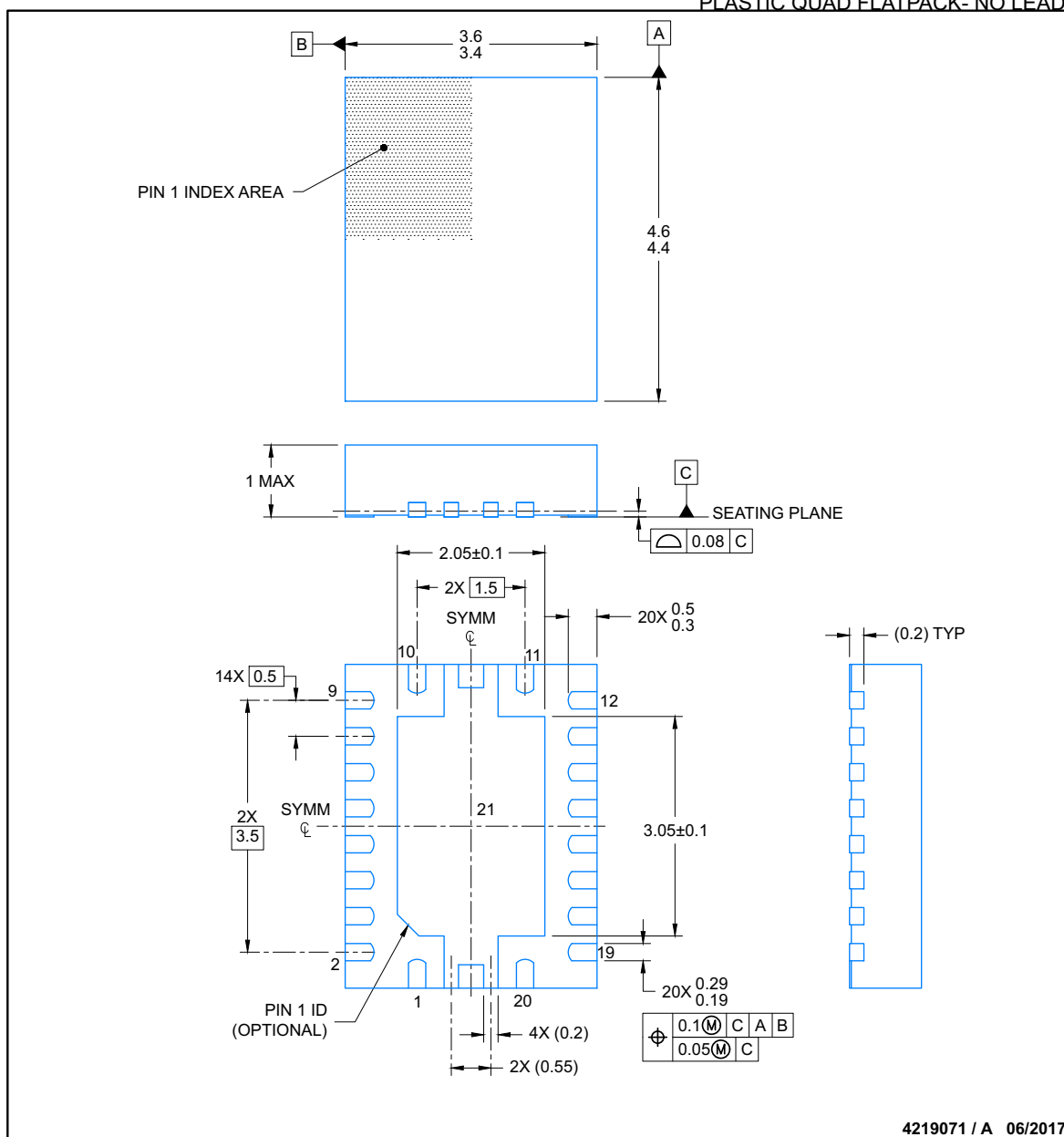
- NOTES:
- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.
 - B. This drawing is subject to change without notice.
 -  C. Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.
 -  D. Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.
 - E. Falls within JEDEC MO-153

PACKAGE OUTLINE

RHL0020A

VQFN - 1 mm max height

PLASTIC QUAD FLATPACK- NO LEAD

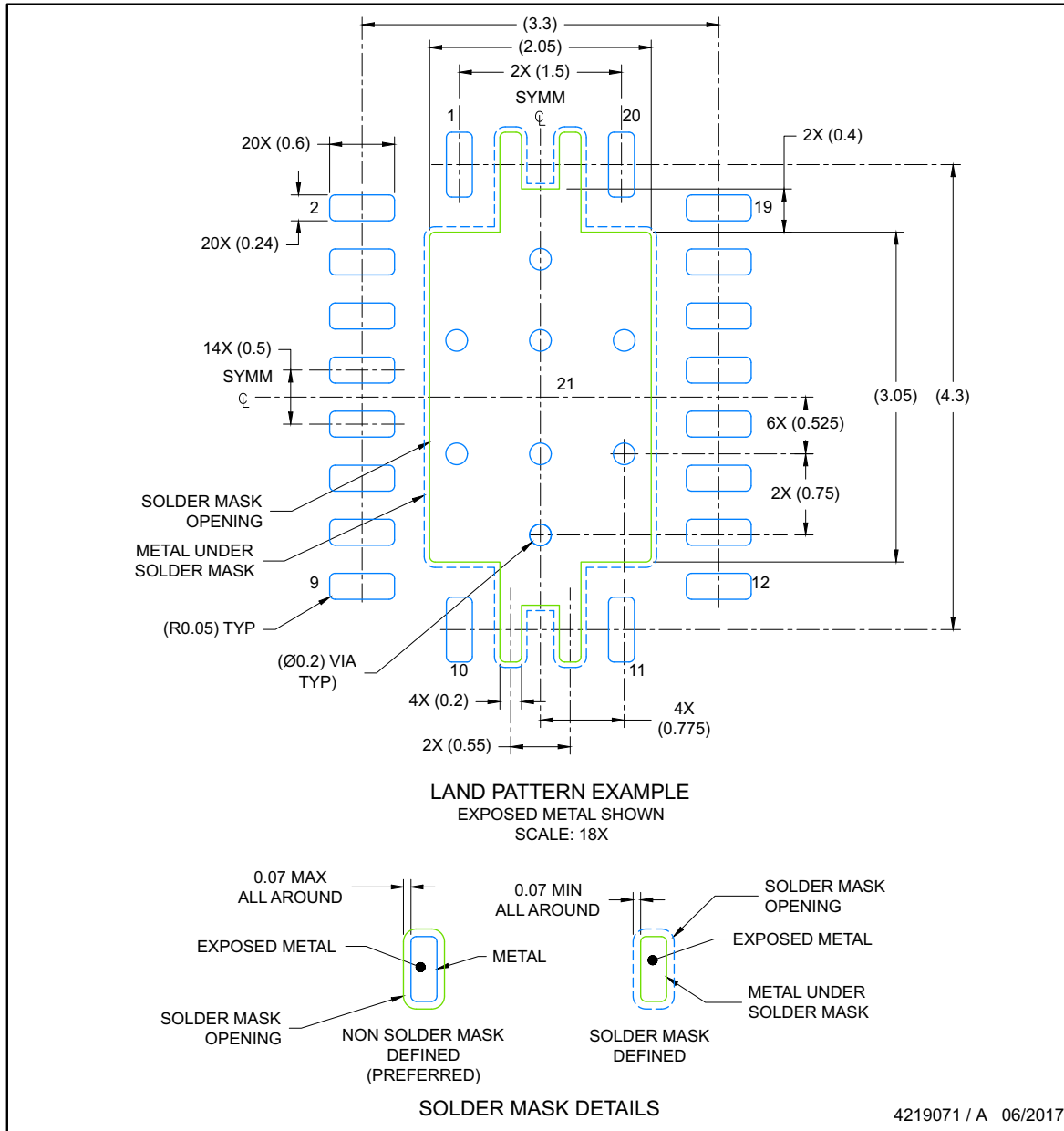


NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. The package thermal pad must be soldered to the printed circuit board for thermal and mechanical performance.

EXAMPLE BOARD LAYOUT**RHL0020A****VQFN - 1 mm max height**

PLASTIC QUAD FLATPACK- NO LEAD



NOTES: (continued)

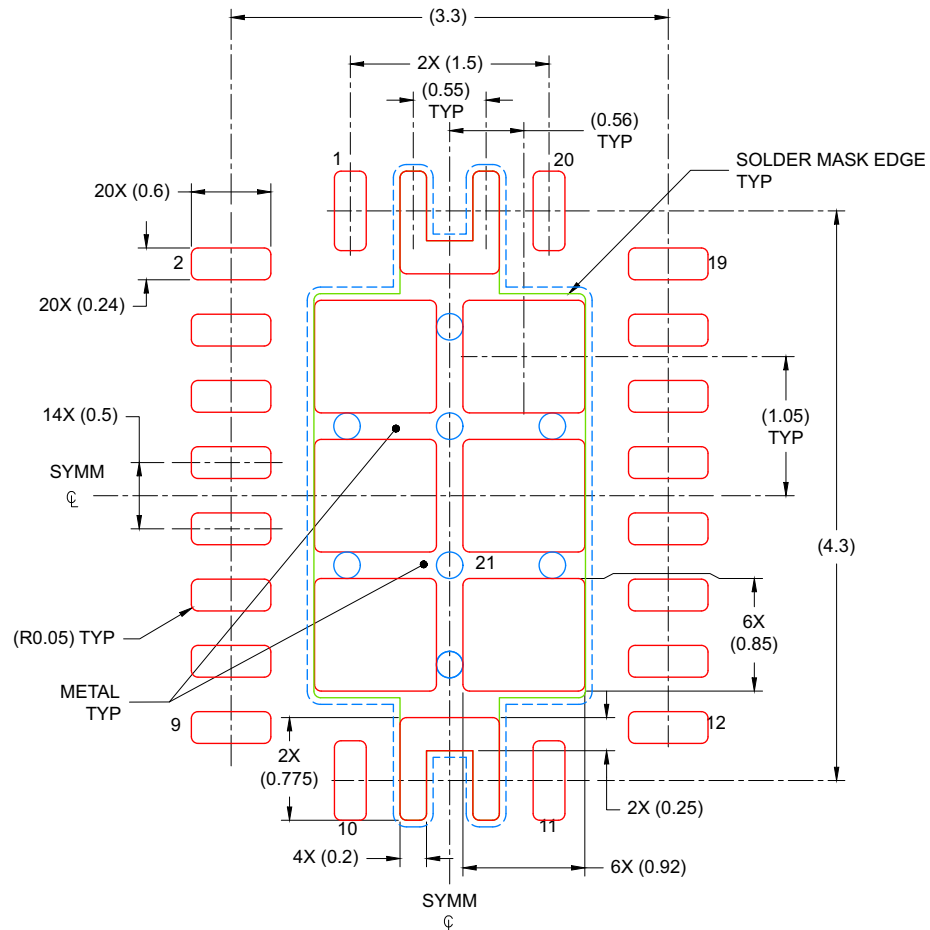
4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/sluea271).
5. Solder mask tolerances between and around signal pads can vary based on board fabrication site.
6. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.

www.ti.com

RHL0020A

EXAMPLE STENCIL DESIGN

PLASTIC QUAD FLATPACK- NO LEAD



**SOLDER PASTE EXAMPLE
BASED ON 0.1mm THICK STENCIL**

EXPOSED PAD
75% PRINTED COVERAGE BY AREA
SCALE: 20X

4219071 / A 06/2017

NOTES: (continued)

7. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations..

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PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
MSP430FR2422IPW16	ACTIVE	TSSOP	PW	16	90	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	FR2422	Samples
MSP430FR2422IPW16R	ACTIVE	TSSOP	PW	16	2000	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	FR2422	Samples
MSP430FR2422IRHLR	ACTIVE	VQFN	RHL	20	3000	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	FR2422	Samples
MSP430FR2422IRHLT	ACTIVE	VQFN	RHL	20	250	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	FR2422	Samples

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSELETE: TI has discontinued the production of the device.

⁽²⁾ **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

⁽³⁾ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

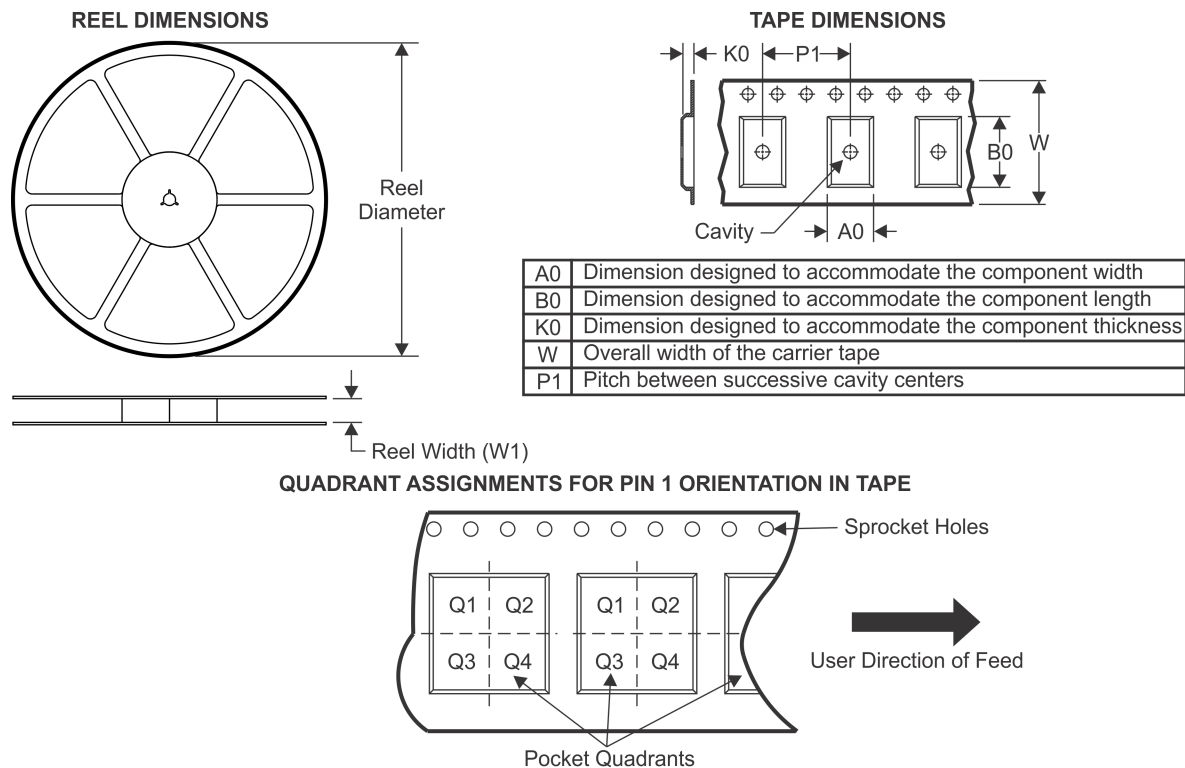
⁽⁵⁾ Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "-" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

⁽⁶⁾ Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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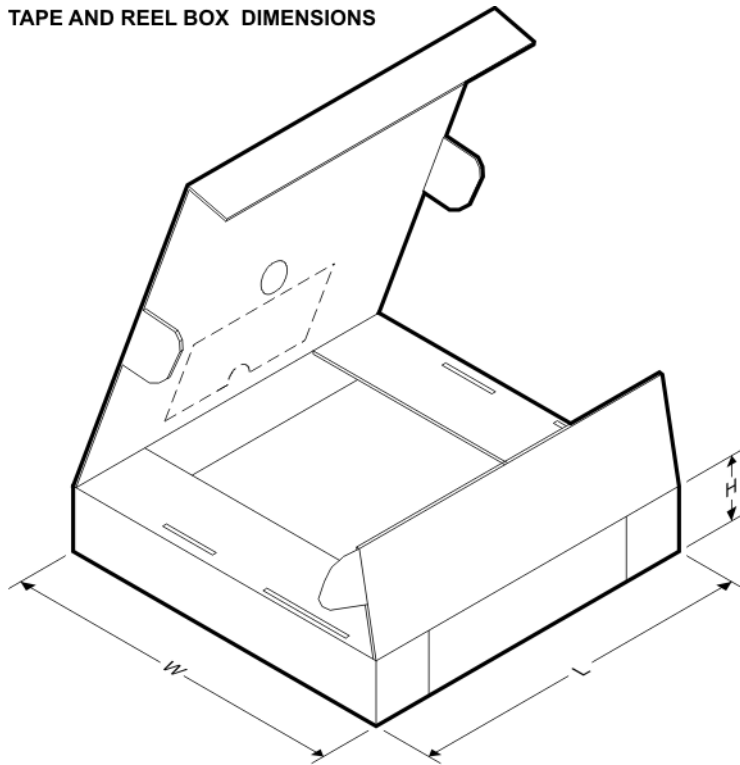
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TAPE AND REEL INFORMATION


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
MSP430FR2422IPW16R	TSSOP	PW	16	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
MSP430FR2422IRHLR	VQFN	RHL	20	3000	330.0	12.4	3.71	4.71	1.1	8.0	12.0	Q1
MSP430FR2422IRHLT	VQFN	RHL	20	250	180.0	12.4	3.71	4.71	1.1	8.0	12.0	Q1

TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
MSP430FR2422IPW16R	TSSOP	PW	16	2000	367.0	367.0	35.0
MSP430FR2422IRHLR	VQFN	RHL	20	3000	367.0	367.0	35.0
MSP430FR2422IRHLT	VQFN	RHL	20	250	210.0	185.0	35.0

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